



---

Managed by Fermi Research Alliance, LLC for the U.S. Department of Energy Office of Science

---

# High Q Developments

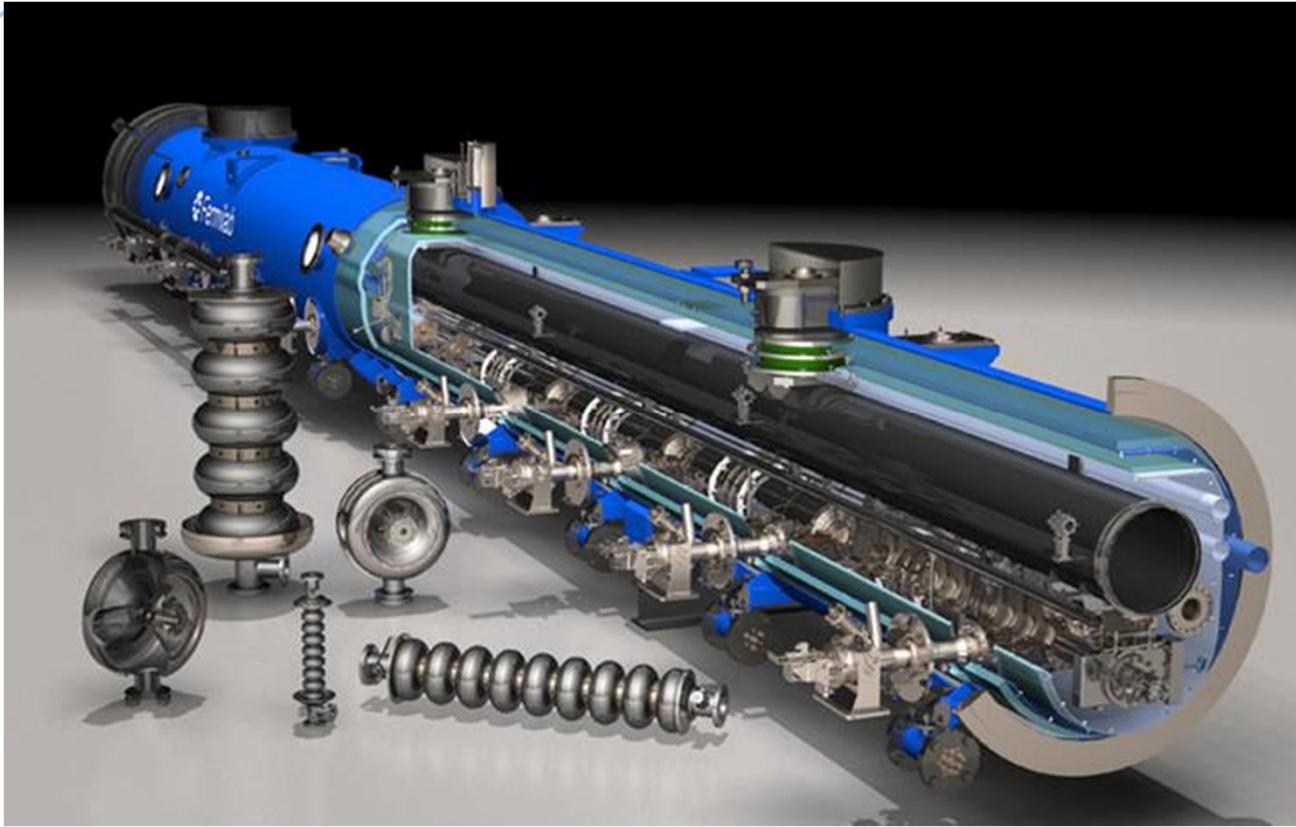
Anna Grassellino  
Fermilab  
IPAC 2015, Richmond, Virginia

# Outline

---

- Two recent breakthroughs have systematically and reproducibly changed the quality factor of niobium SRF cavities:
  1. Nitrogen doping
    - From discovery to cryomodule ready/transfer to industry ready technology (LCLS-2)
    - Why does it work? What is known and yet unknown (samples characterization, cavity measurements, theoretical models...)
  2. Efficient Magnetic Flux Expulsion via fast cooling
    - Discovery and progress in understanding with bare cavities
    - Practical implementation of lessons learned in cryomodules

# Superconducting RF cavities



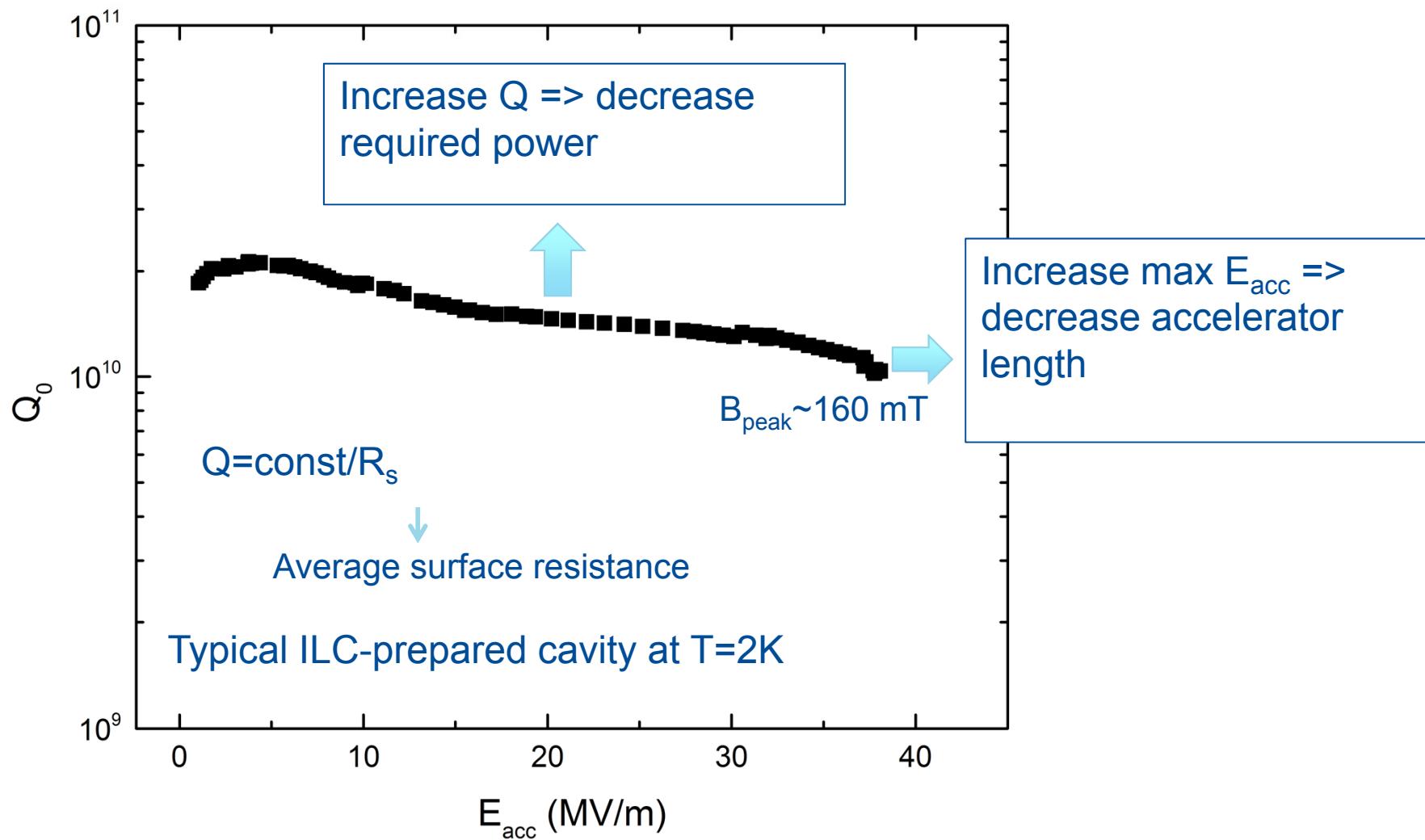
- Niobium is the material of choice (superconducting below 9.2K)
- Depending on different machines/applications:
  - Fundamental mode  $f = 50 \text{ MHz} - 10 \text{ GHz}$
  - Operating temperature  $T = 1.8\text{K}$  to  $4.2\text{K}$
  - Achievable accelerating gradients  $\sim 50 \text{ MV/m}$

# SRF cavities – advantages

---

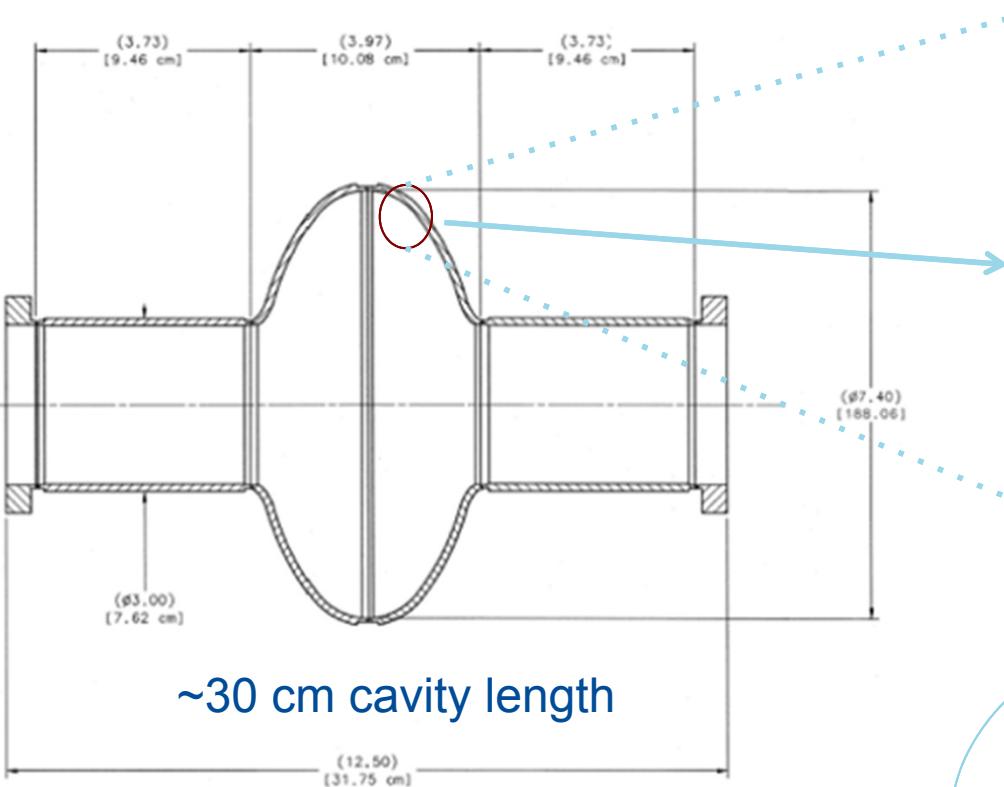
- Wall dissipation (proportional to surface resistance  $R_s$ ) is reduced by many orders of magnitude over a normal conducting copper cavity
- Among highest quality factors Q in nature
  - $Q > 10^{11}$  achieved,  $Q = 2 \times 10^{10}$  – routine
- Affordable continuous wave and long pulse gradients
  - Field=acceleration can be ON all the time
- Larger aperture gives better beam quality

# SRF cavities figures of merit: efficiency ( $Q$ ) and quench field

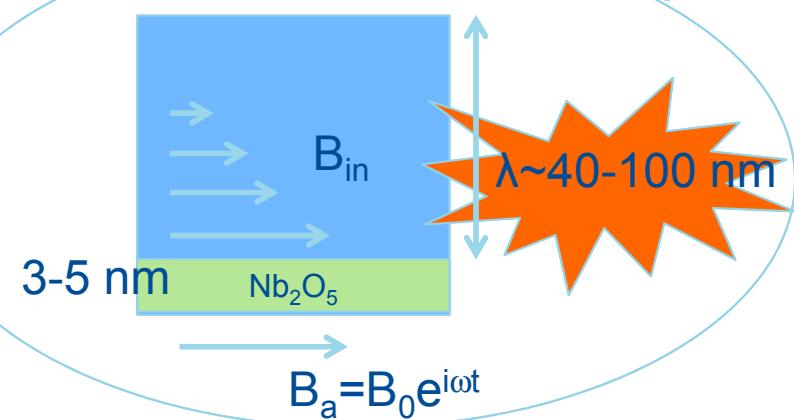
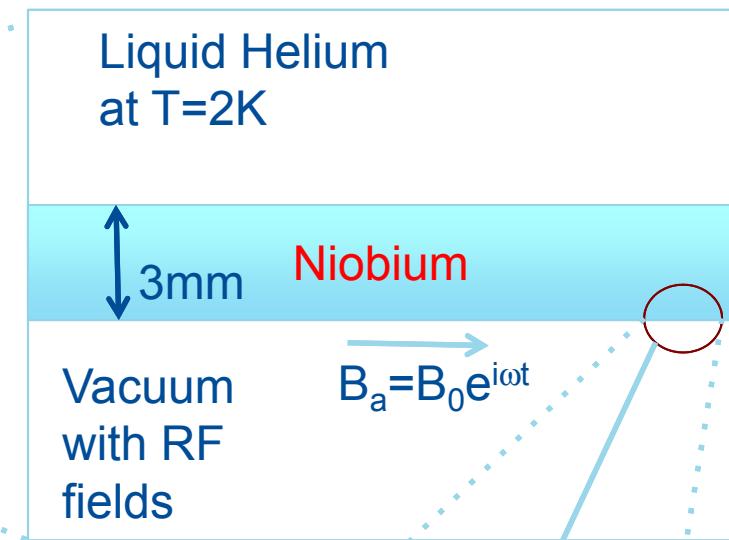


# What matters for SRF performance?

## Relevant scale is the nanoscopic

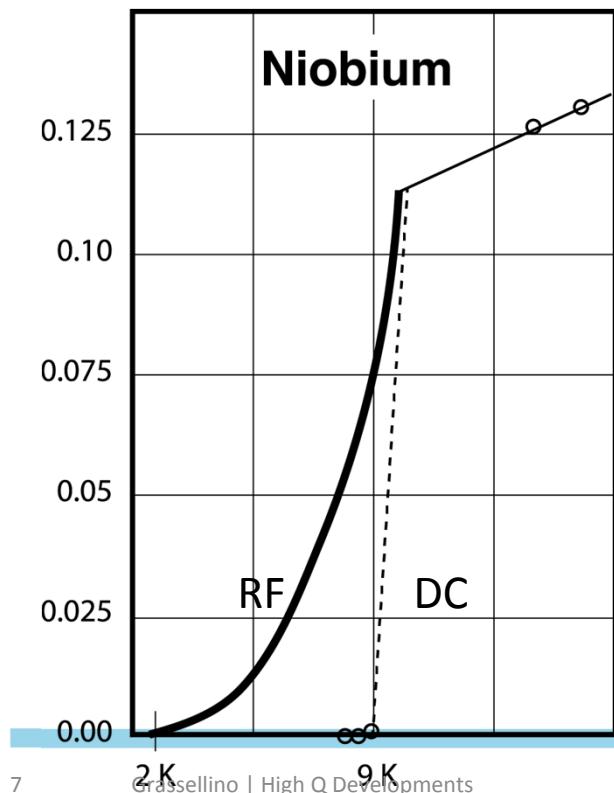
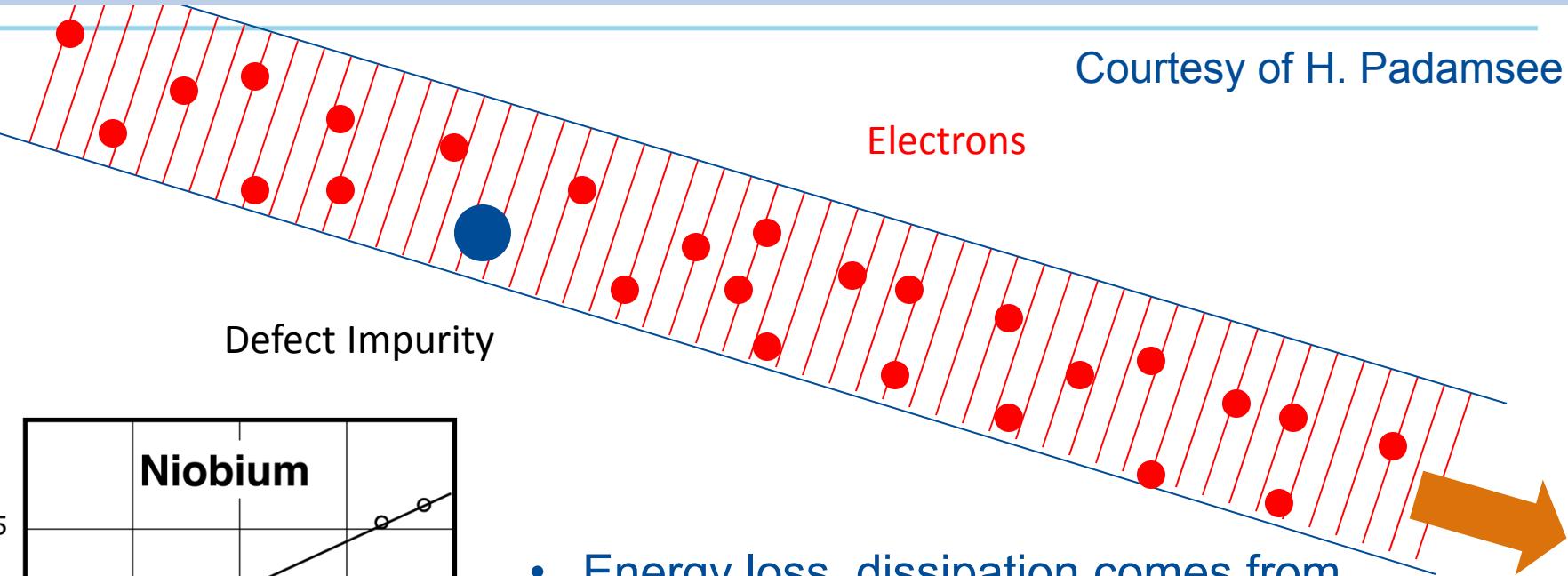


Inner surface nanostructure within ~2-100 nm completely determines RF losses in the cavity



# Superconductivity: DC case

Courtesy of H. Padamsee



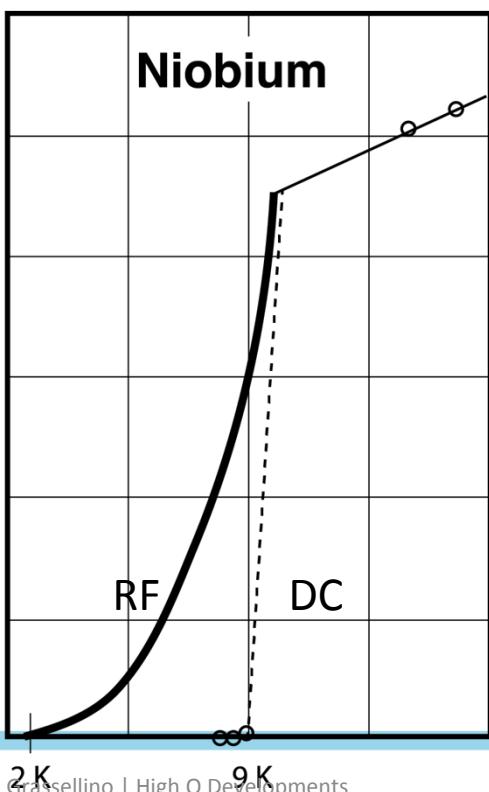
- Energy loss, dissipation comes from scattering of electrons with defects or **Current** impurities
- In normal conducting state electrons scatter
- In superconducting state, cooper pairs form and move 'with no friction'

# Superconductivity RF case- Small Non-Zero Resistance

Defect  
Impurity

Courtesy of H. Padamsee

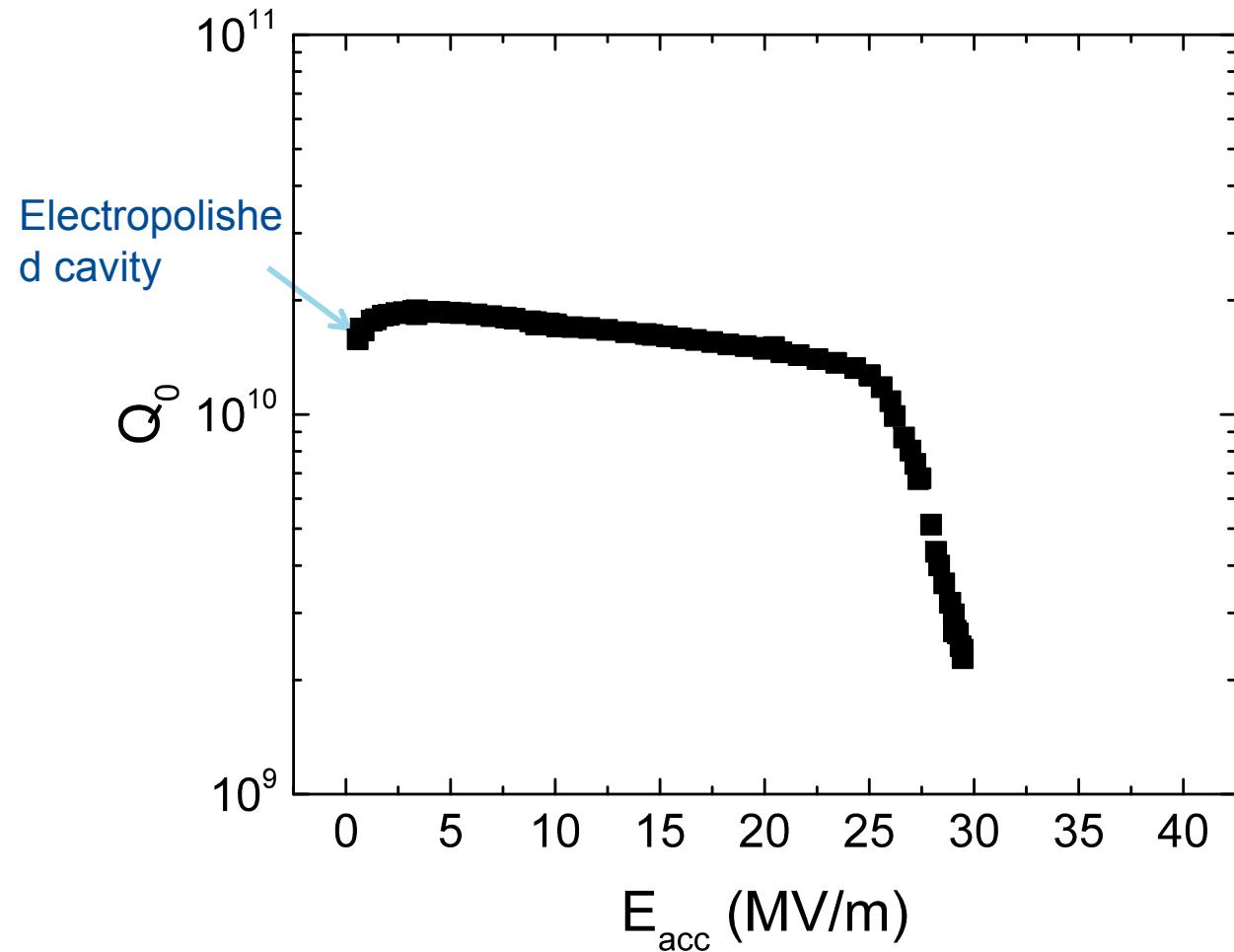
Electrons



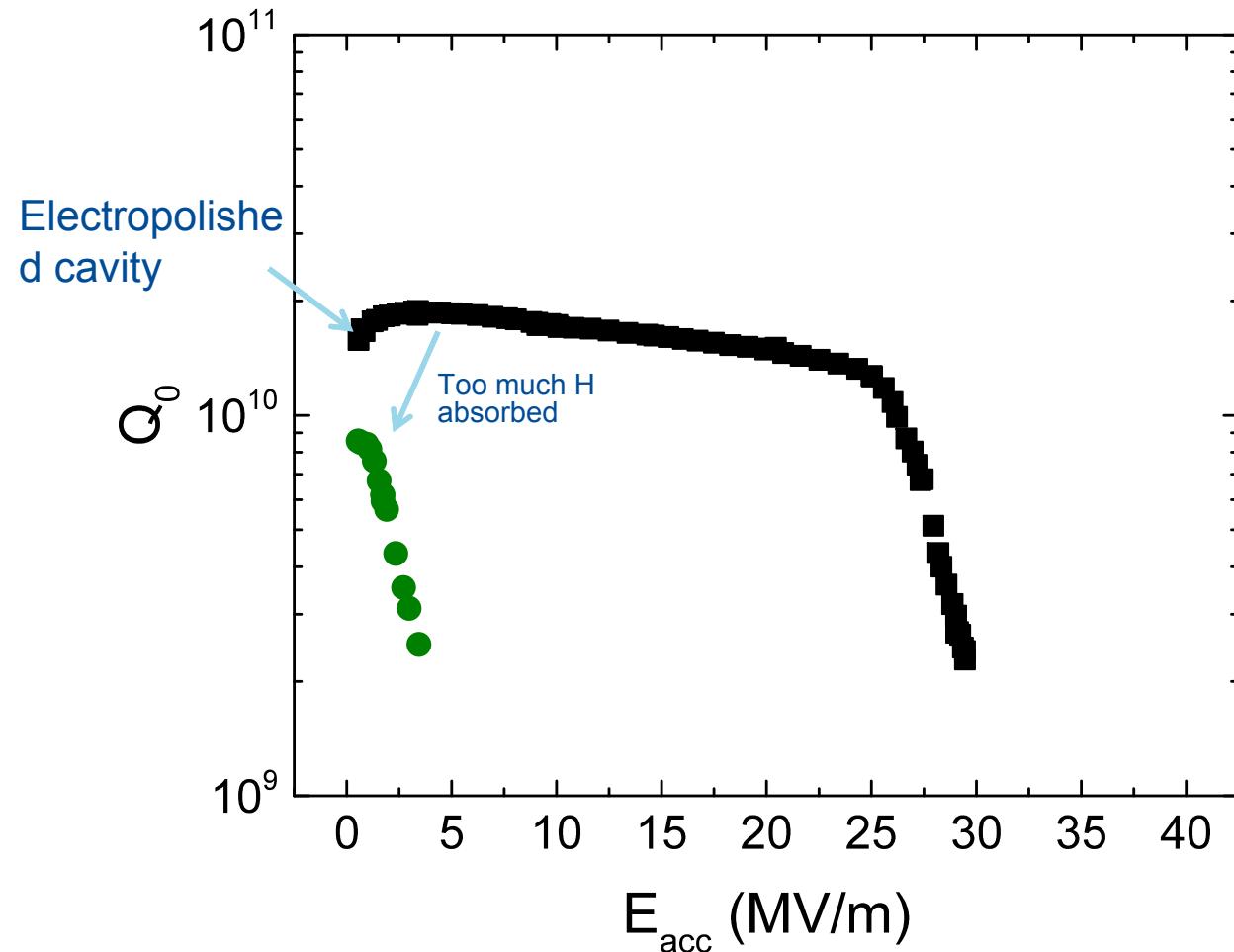
- Purple: unpaired electrons
- Red : Cooper pairs
- Unpaired electrons can scatter and cause RF resistance and loss in efficiency (lower Q)



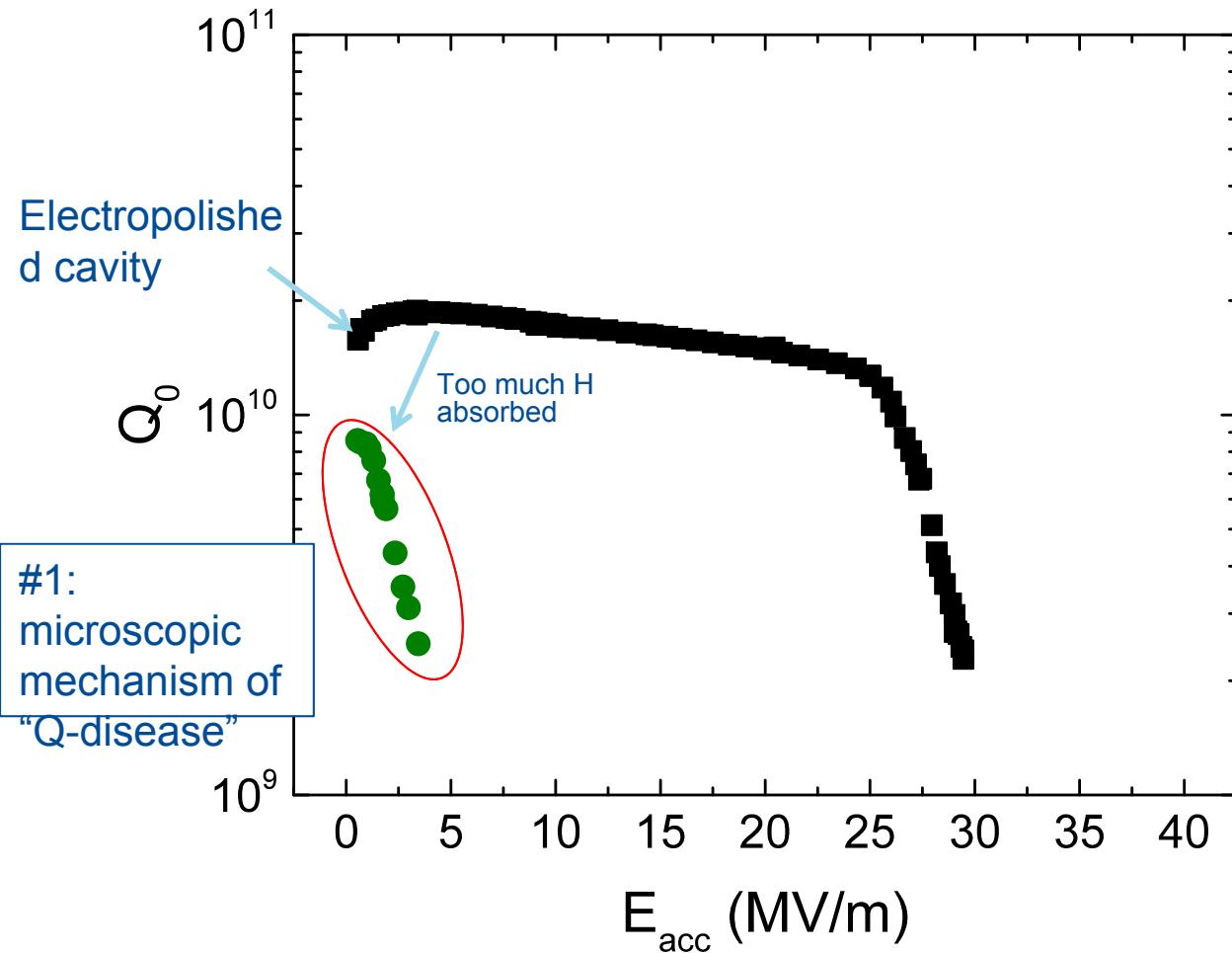
# SRF advancements are driven by fundamental understanding of the underlying physics of cavity surface



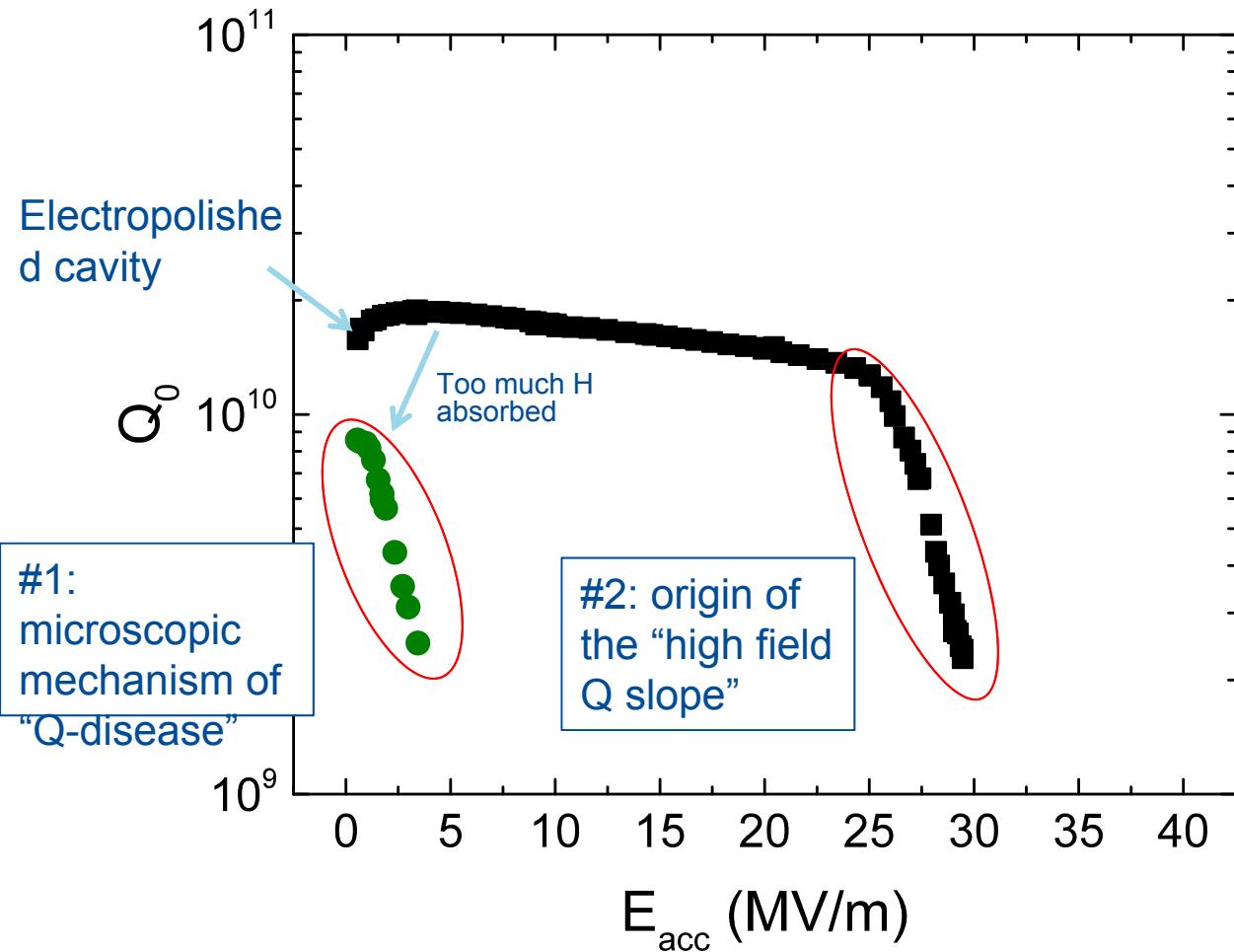
# SRF advancements are driven by fundamental understanding of the underlying physics of cavity surface



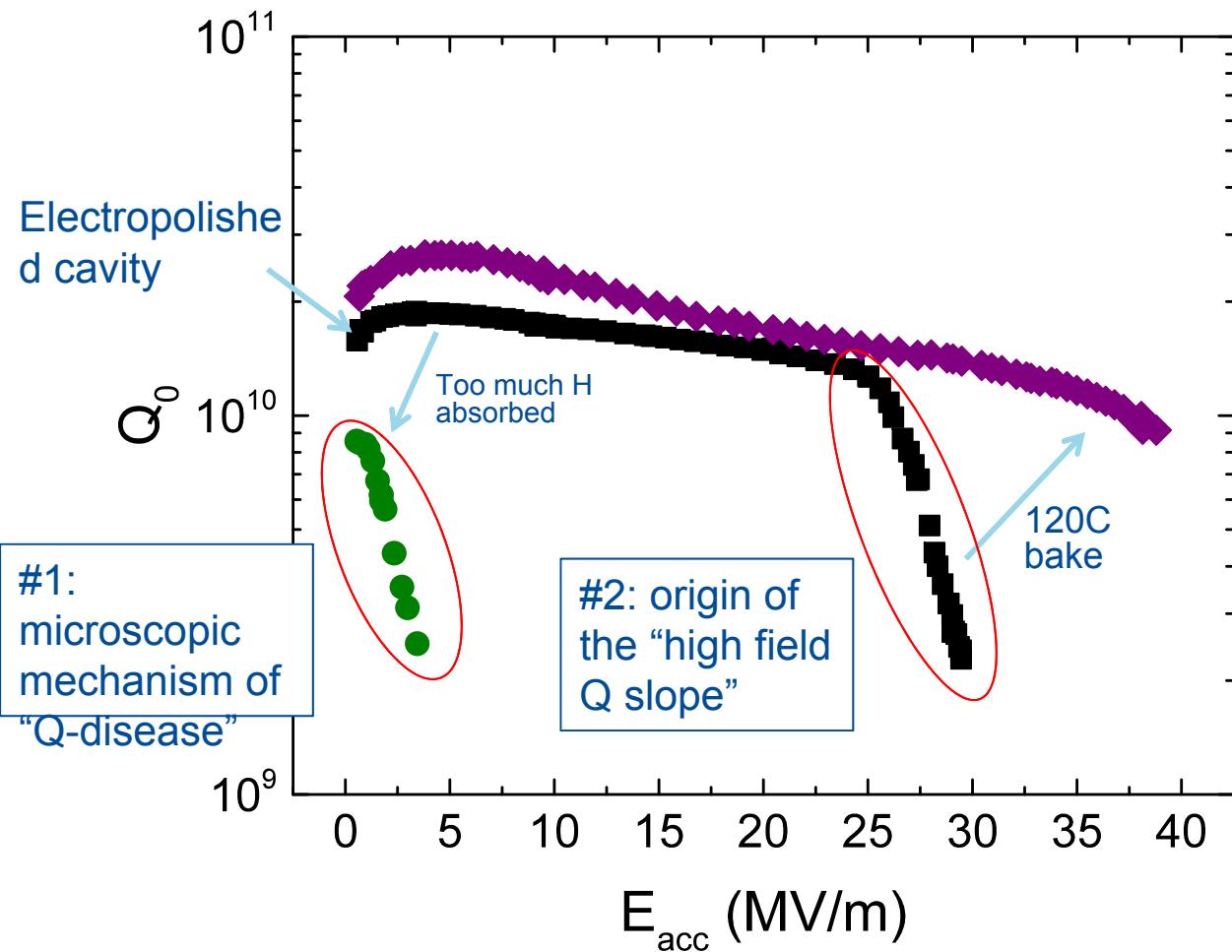
# SRF advancements are driven by fundamental understanding of the underlying physics of cavity surface



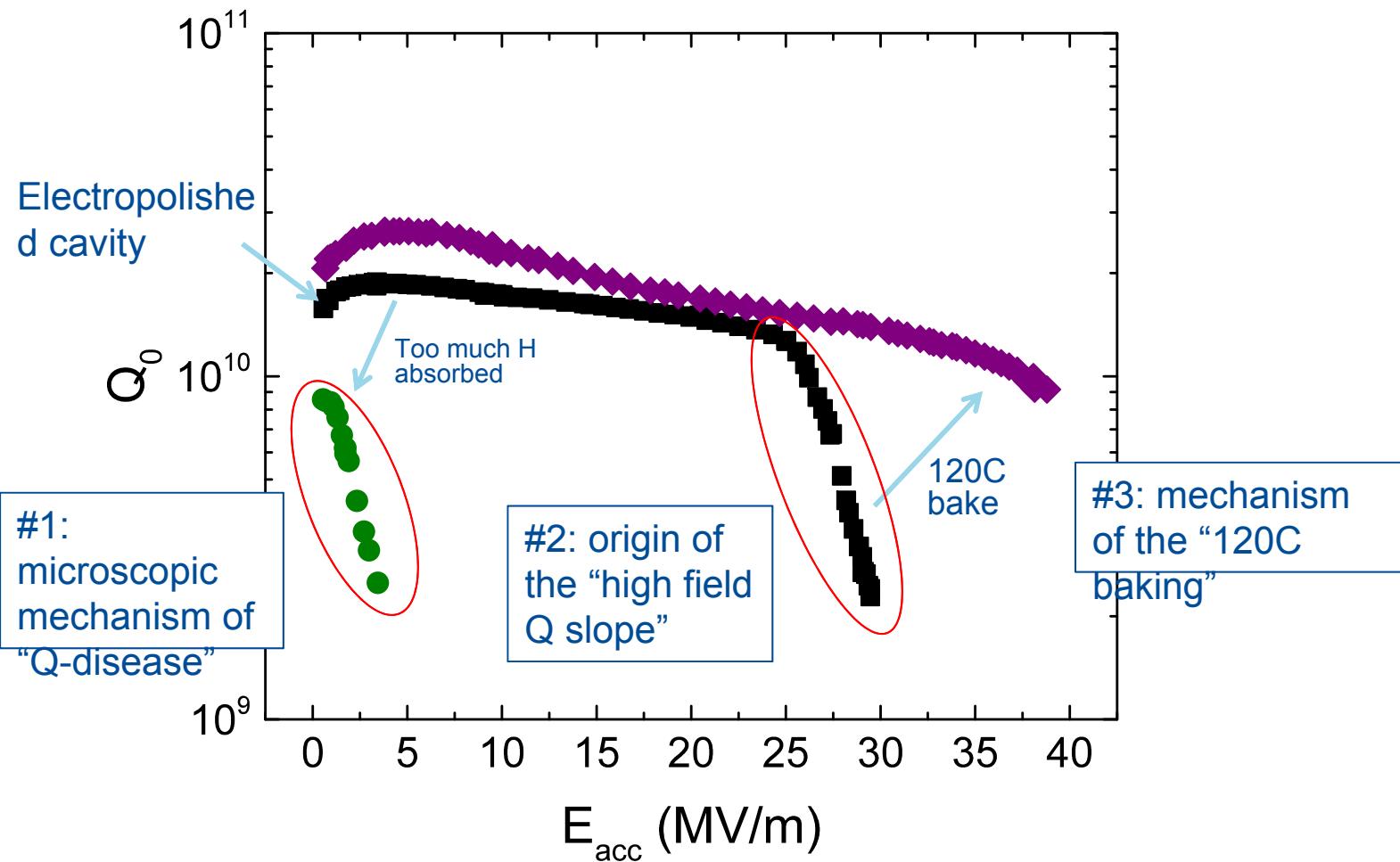
# SRF advancements are driven by fundamental understanding of the underlying physics of cavity surface



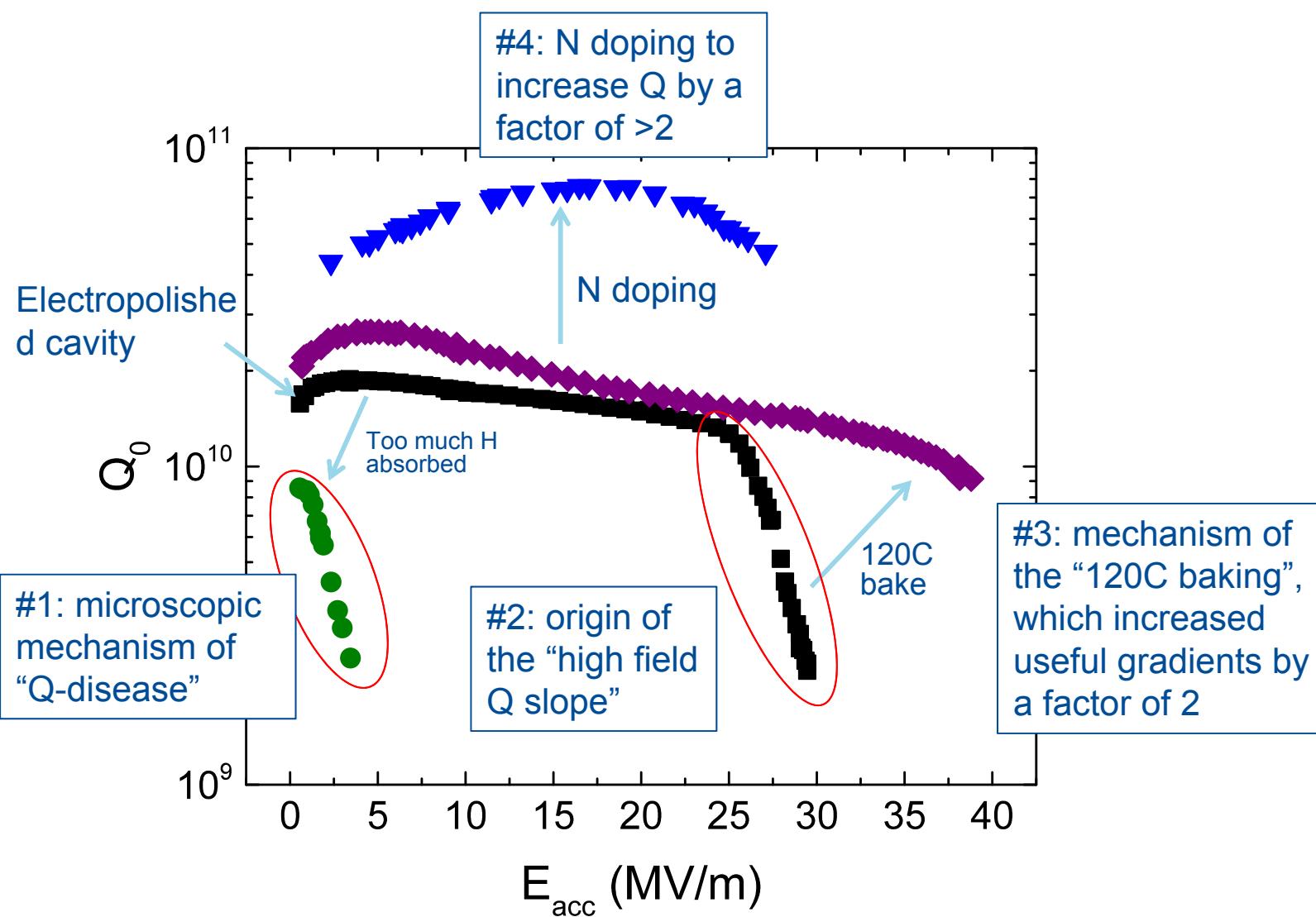
# SRF advancements are driven by fundamental understanding of the underlying physics of cavity surface



# SRF advancements are driven by fundamental understanding of the underlying physics of cavity surface



# SRF advancements are driven by fundamental understanding of the underlying physics of cavity surface

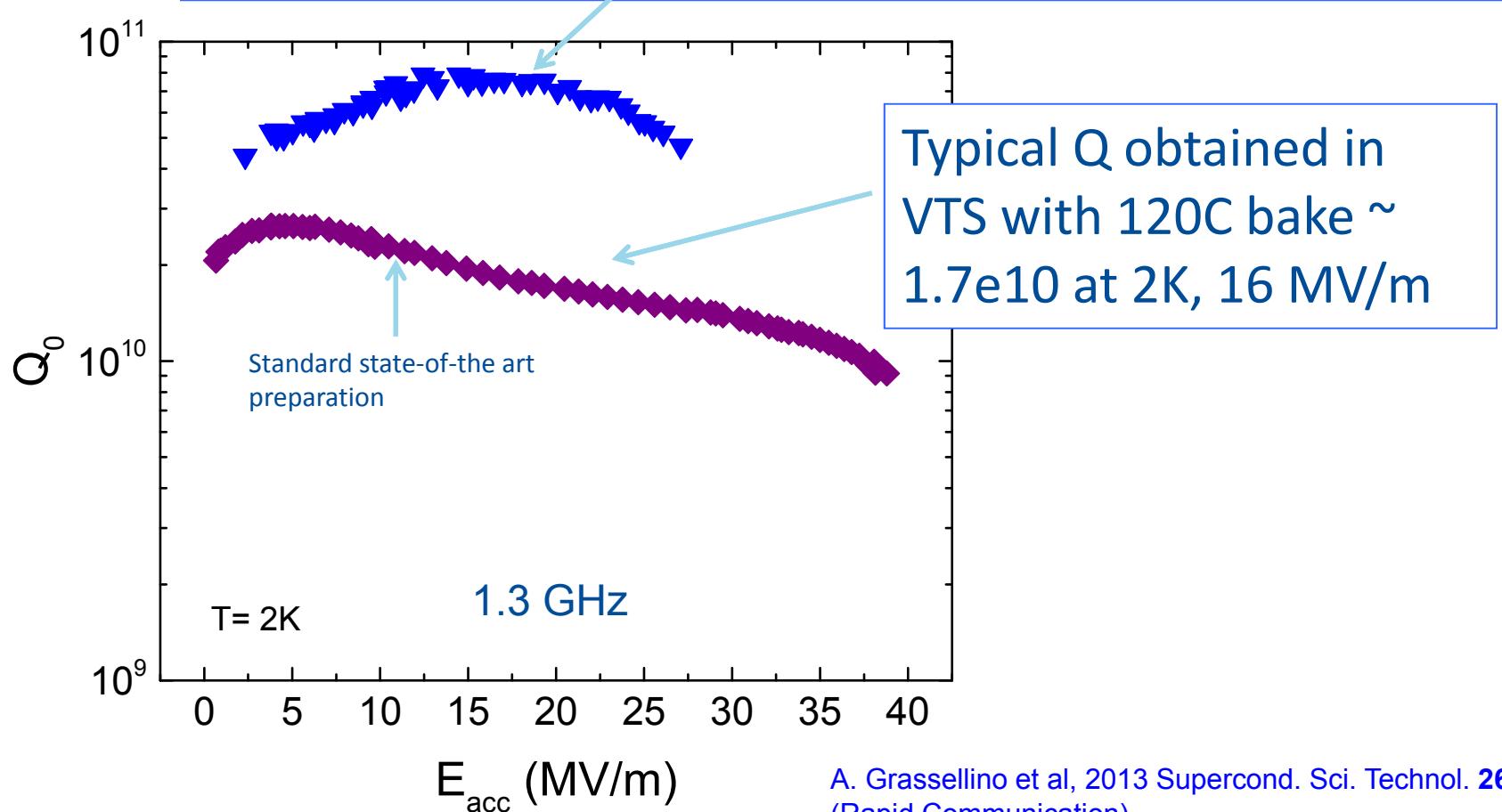


---

*N doping:  
results for LCLS-2, progress in understanding*

# Nitrogen Doping: a breakthrough in Q

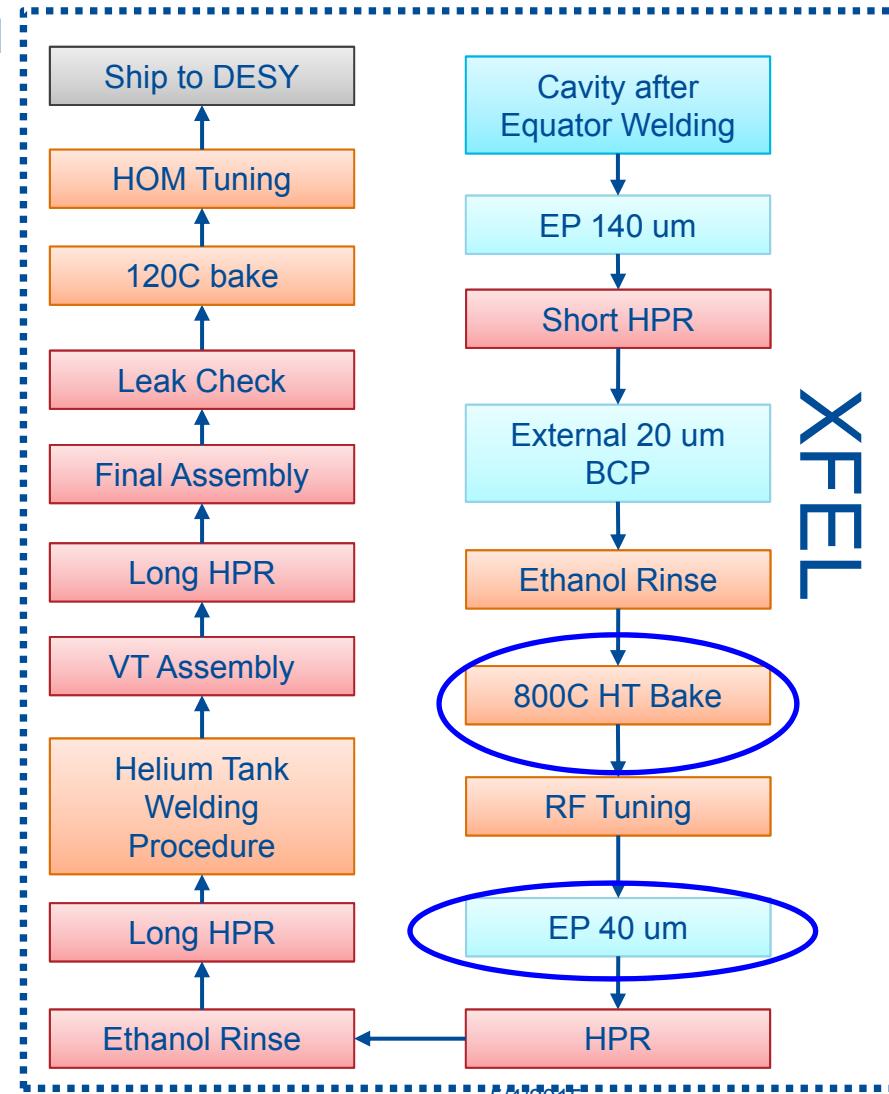
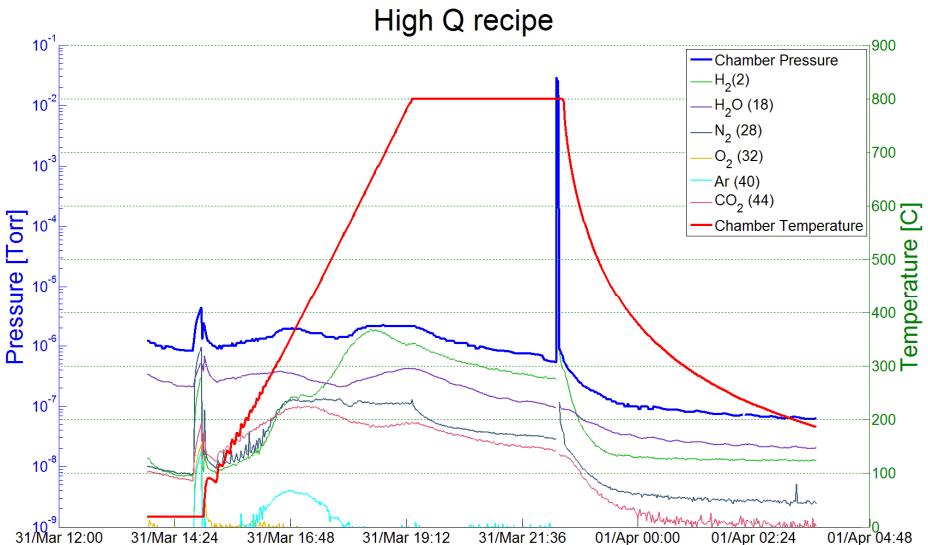
Record after nitrogen doping – up to 4 times higher Q! Average values obtained on nine cell Q(2K, 16MV/m)~ 3.5e10



# Doping Treatment: small variation from standard protocol, large difference in performance

Example from a doping process developed for LCLS-2:

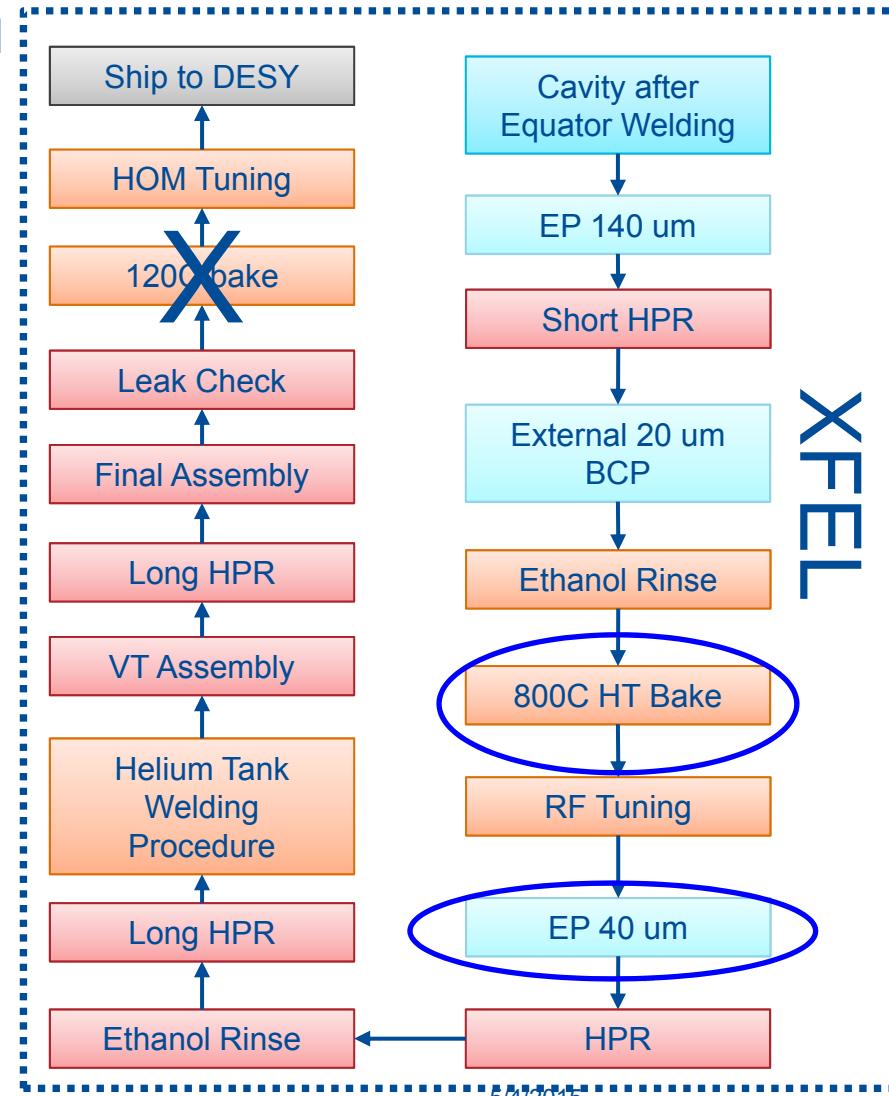
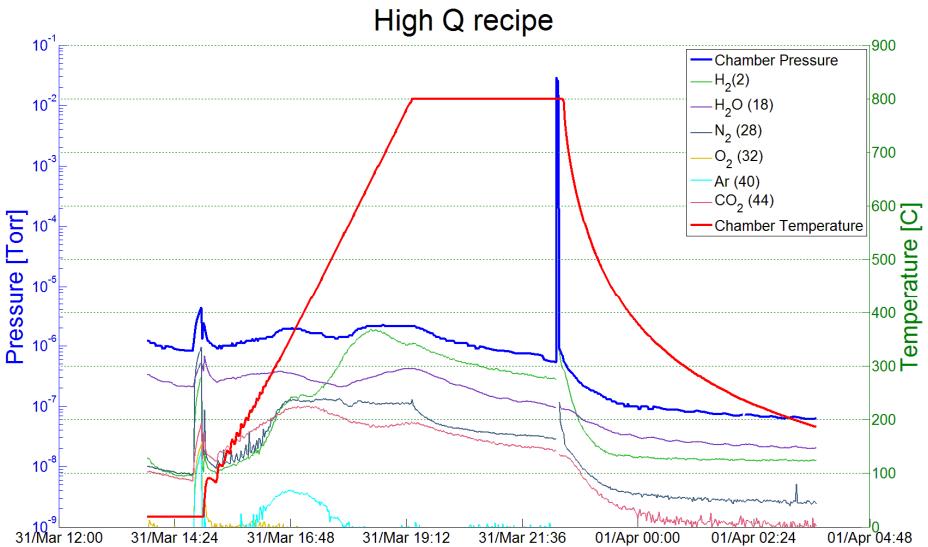
- Bulk EP
- 800 C anneal for 3 hours in vacuum
- 2 minutes @ 800C nitrogen diffusion
- 800 C for 6 minutes in vacuum
- Vacuum cooling
- 5 microns EP



# Doping Treatment: small variation from standard protocol, large difference in performance

Example from a doping process developed for LCLS-2:

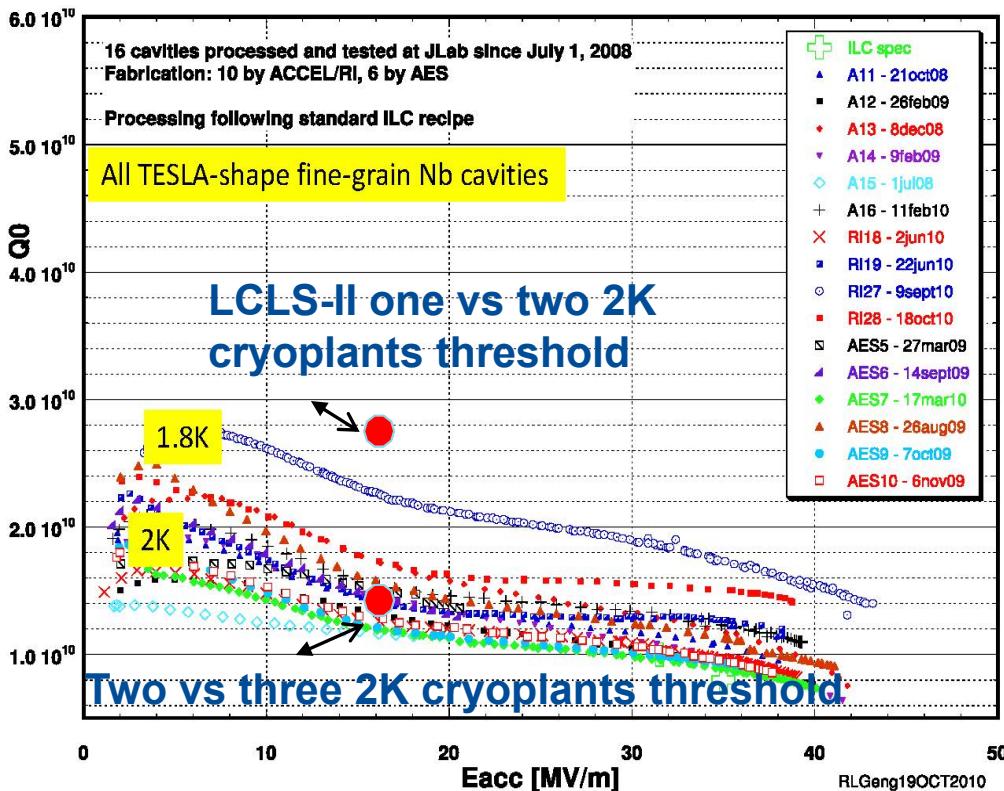
- Bulk EP
- 800 C anneal for 3 hours in vacuum
- 2 minutes @ 800C nitrogen diffusion
- 800 C for 6 minutes in vacuum
- Vacuum cooling
- 5 microns EP



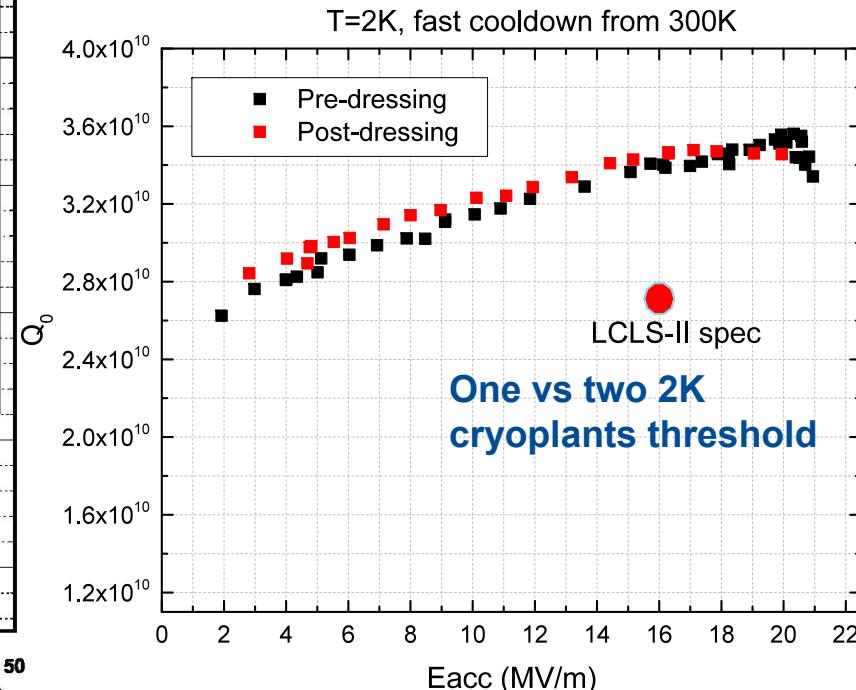
# The importance of a high Q technology – the case of the CW machine LCLS-2

Example of 120C baked (standard ILC/XFEL technology)

Would possibly require > 2 full cryoplants



Example of N doped Dressed cavity for LCLS-2  
Below the one cryopant threshold



- N doping technology allows significantly lower refrigeration costs (capital, operating)
- Larger margin and possibility for an energy upgrade for same refrigeration cost

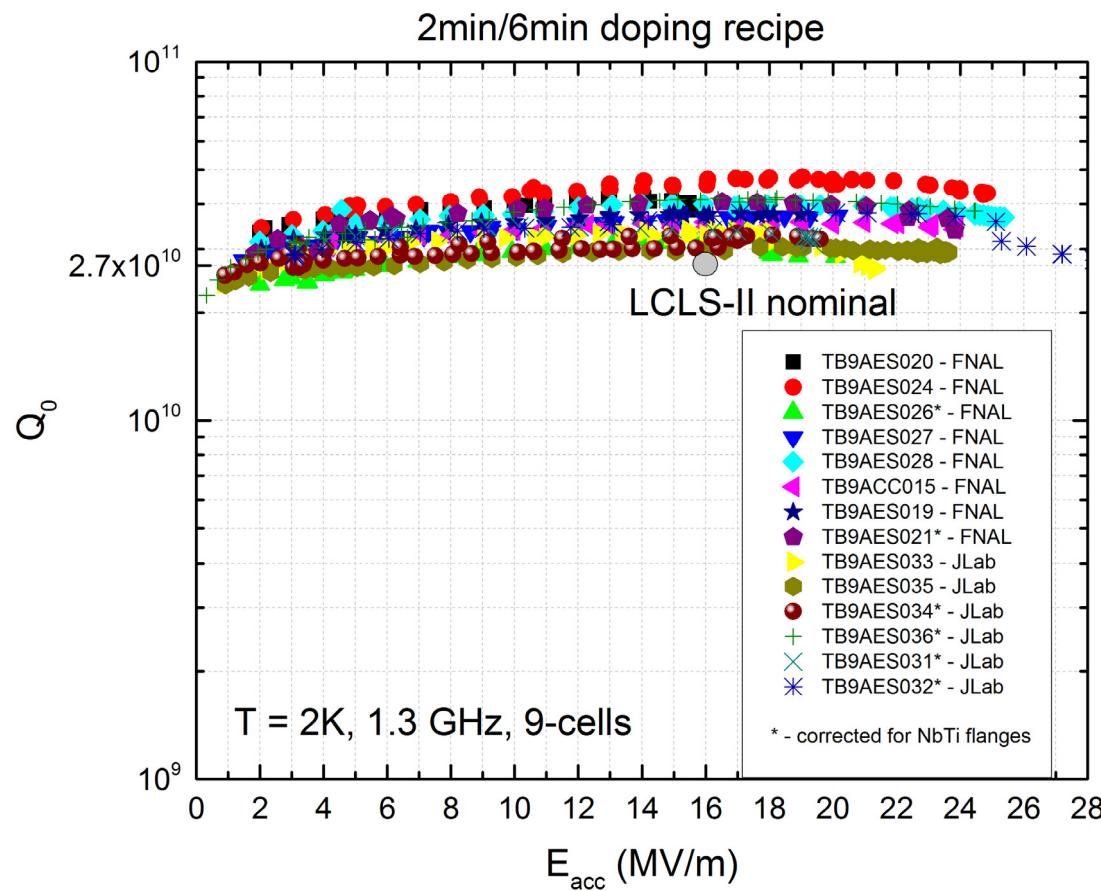
# The High Q Collaboration for LCLS-II

---

- FNAL, Cornell, Jlab and SLAC together with one goal: bring the N doping technology from single cell R&D to nine cell production ready technology
- Technology transferred to FNAL to Cornell and Jlab; now is being transferred to industry, that will employ it in production stage for LCLS-II
- Target Q :  $2.7 \times 10^{10}$  at 2K, 16 MV/m (1.3 GHz) – almost twice the state of the art (XFEL)
- High Q collaboration team leads:
  - SLAC – M. Ross (coordinator)
  - Jlab – C. Reece
  - Cornell – M. Liepe
  - FNAL – A.Grassellino

A. Crawford et al, WEPRI062, IPAC14

# From single cell R&D to cryomodule ready technology: the two LCLS-II prototype cryomodules (FNAL and Jlab)



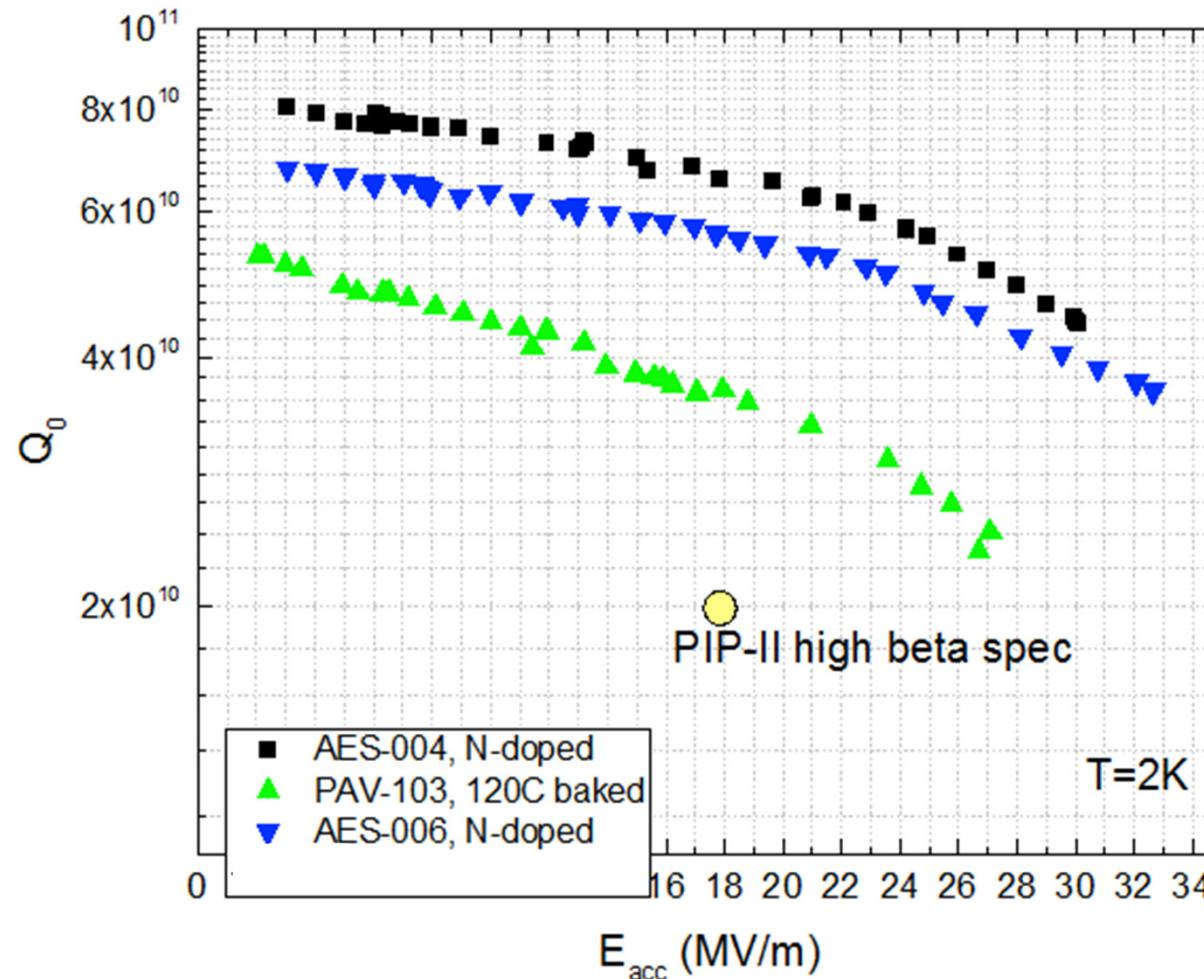
$\langle Q \rangle = 3.6 \times 10^10$   
 $\langle E_{max} \rangle = 22.2 \text{ MV/m}$   
 $E_{max} \text{ median} = 22.8 \text{ MV/m}$

It is the highest average Q ever demonstrated in vertical test for  
1.3 GHz nine cells at 2K, 16 MV/m in the history of SRF  
(larger than a factor of two the state of the art)

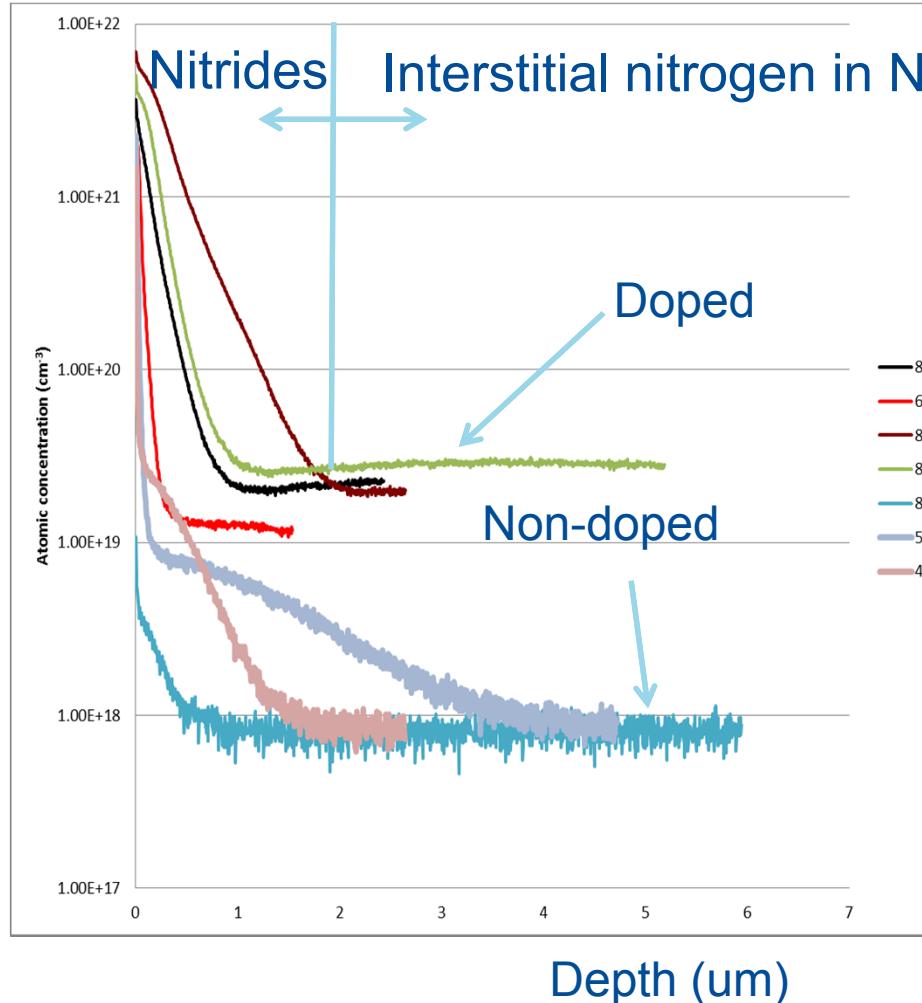
# N doping applied to 650 MHz cavities at FNAL

## Q~ 7e10 at 2K, 17 MV/m – record at this frequency!

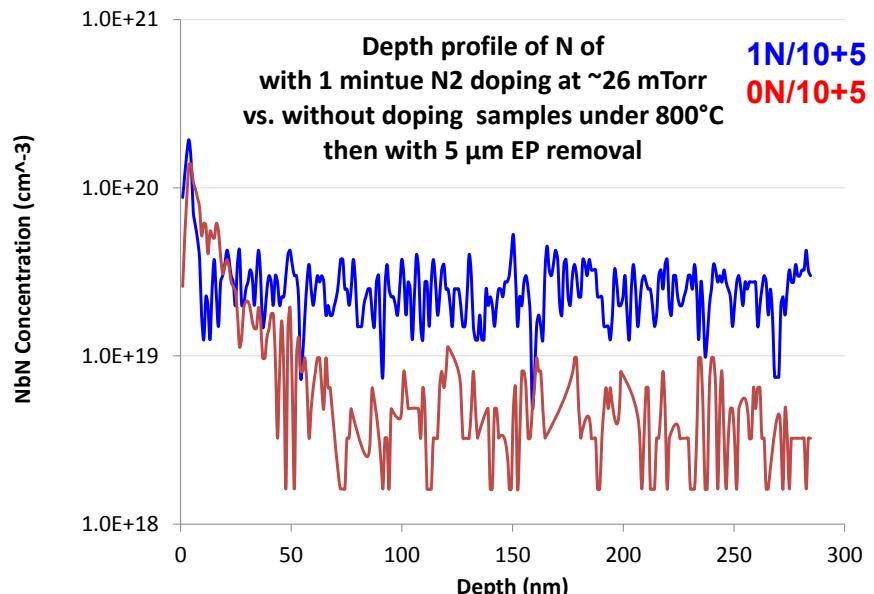
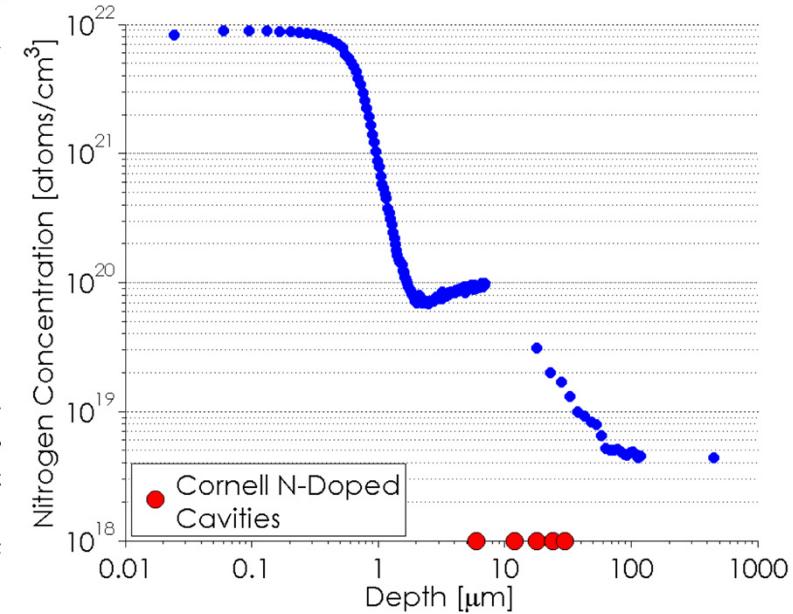
Applying N doping to 650 MHz ( $\beta=0.9$ ) leads to double Q compared to 120C bake (standard surface treatment ILC/XFEL)



# What does the N treatment do? N doping profiles via SIMS

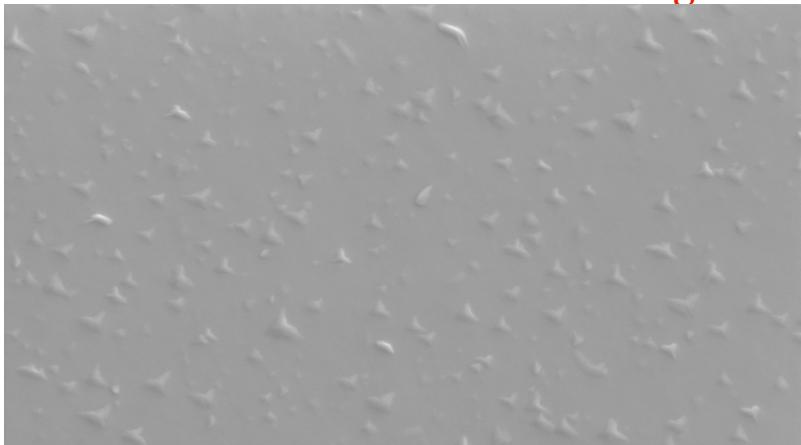


A. Romanenko, talk at LINAC 2014, Geneva  
And D. Gonnella et al, LINAC 2014, Geneva  
C. Reece et al, WEPWI026



# Surface Nitrides (post bake, pre-EP) – imaged by SEM

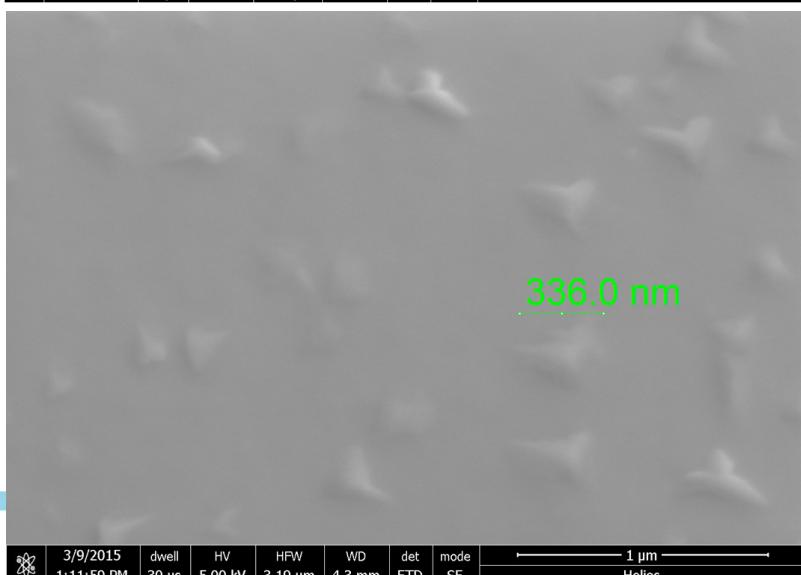
Flat Nb sample baked at 800C°  
for **2 min with N<sub>2</sub>** + 6 min annealing



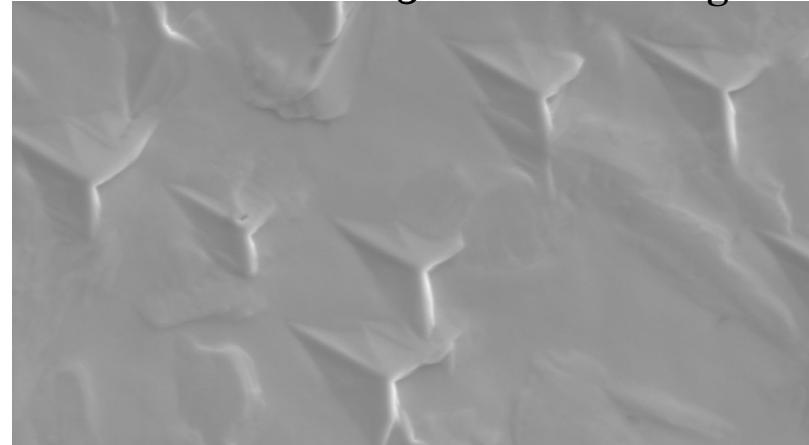
**Bad (poorly SC) nitride phases that need to be removed via EP**

3/9/2015	dwell	HV	HFW	WD	det	mode	3 μm
1:16:09 PM	30 μs	5.00 kV	10.4 μm	4.3 mm	ETD	SE	Helios

336.0 nm

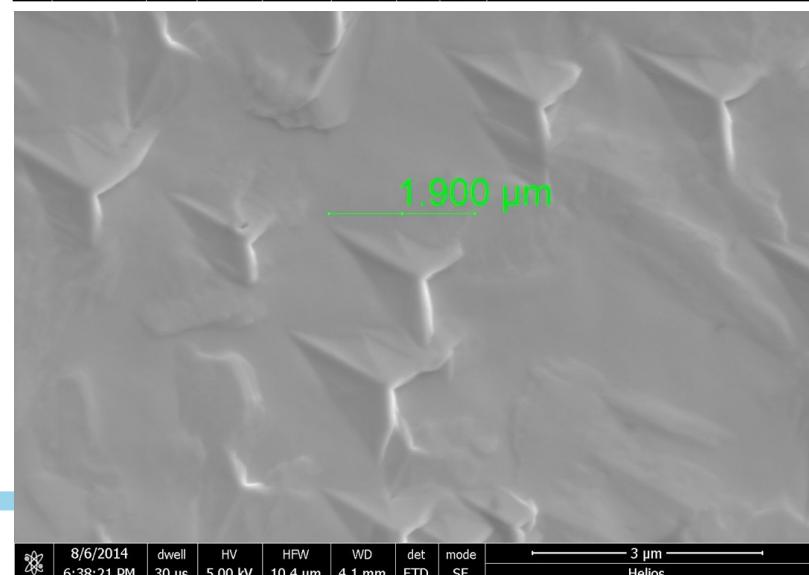


Flat Nb sample baked at 800C° for  
**20 min with N<sub>2</sub>** + 30 min annealing



8/6/2014	dwell	HV	HFW	WD	det	mode	3 μm
6:38:21 PM	30 μs	5.00 kV	10.4 μm	4.1 mm	ETD	SE	Helios

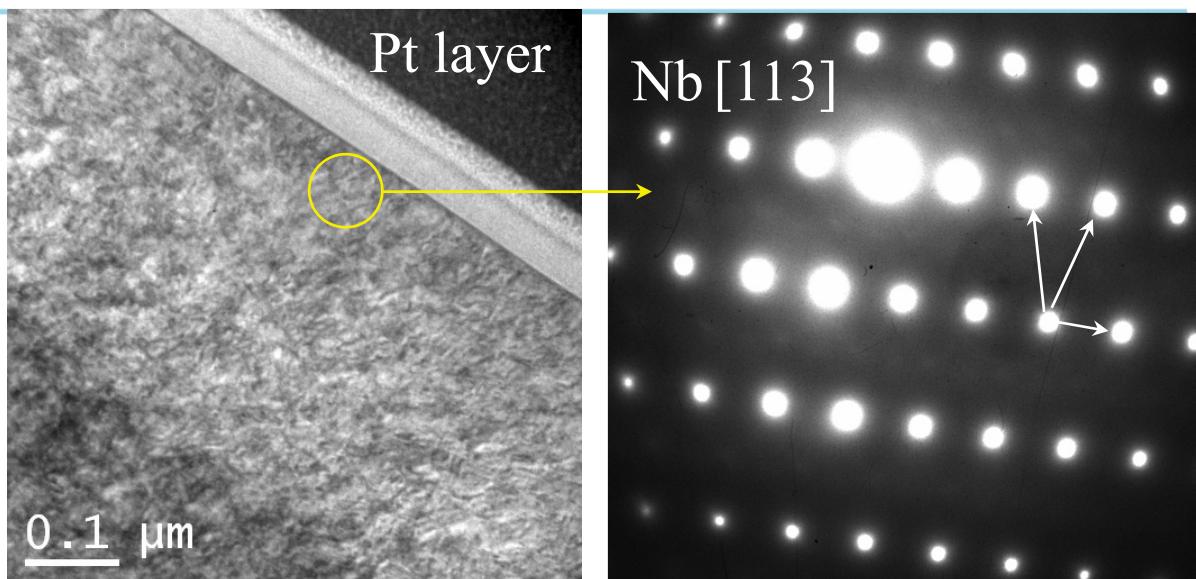
1.900 μm



3/9/2015	dwell	HV	HFW	WD	det	mode	3 μm
1:11:59 PM	30 μs	5.00 kV	3.19 μm	4.3 mm	ETD	SE	Helios

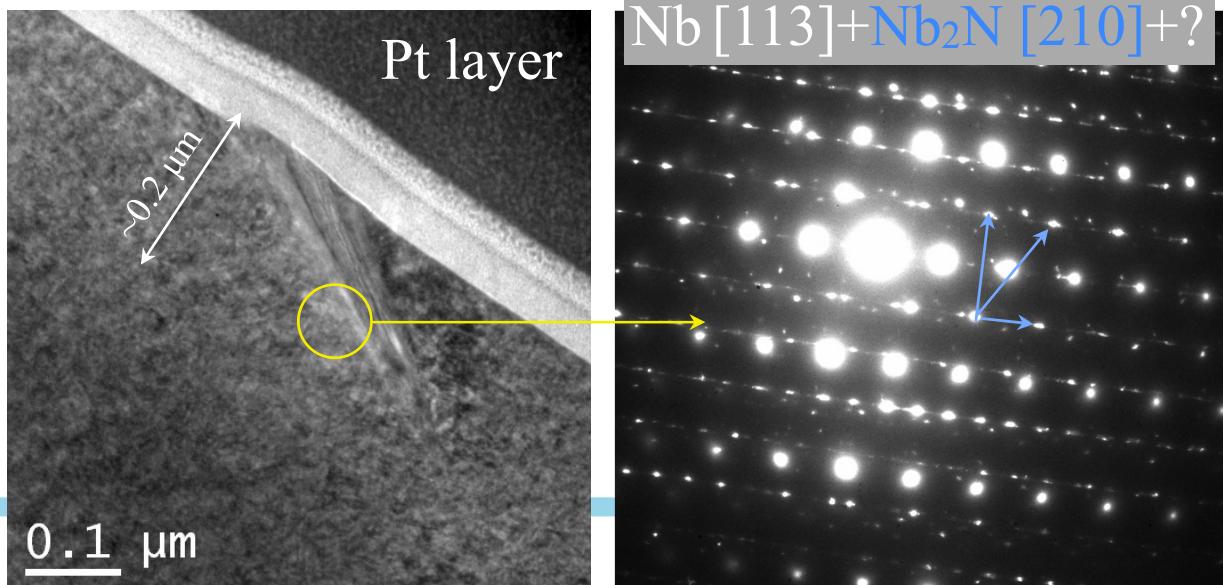
## Room T TEM on post gas bake, pre-EP surface (2/6 recipe)

a)  $\mu\text{m}$ -sized areas of “uniform” contrast in near-surface show only Nb reflections



Courtesy of Y. Trenhikina, FNAL

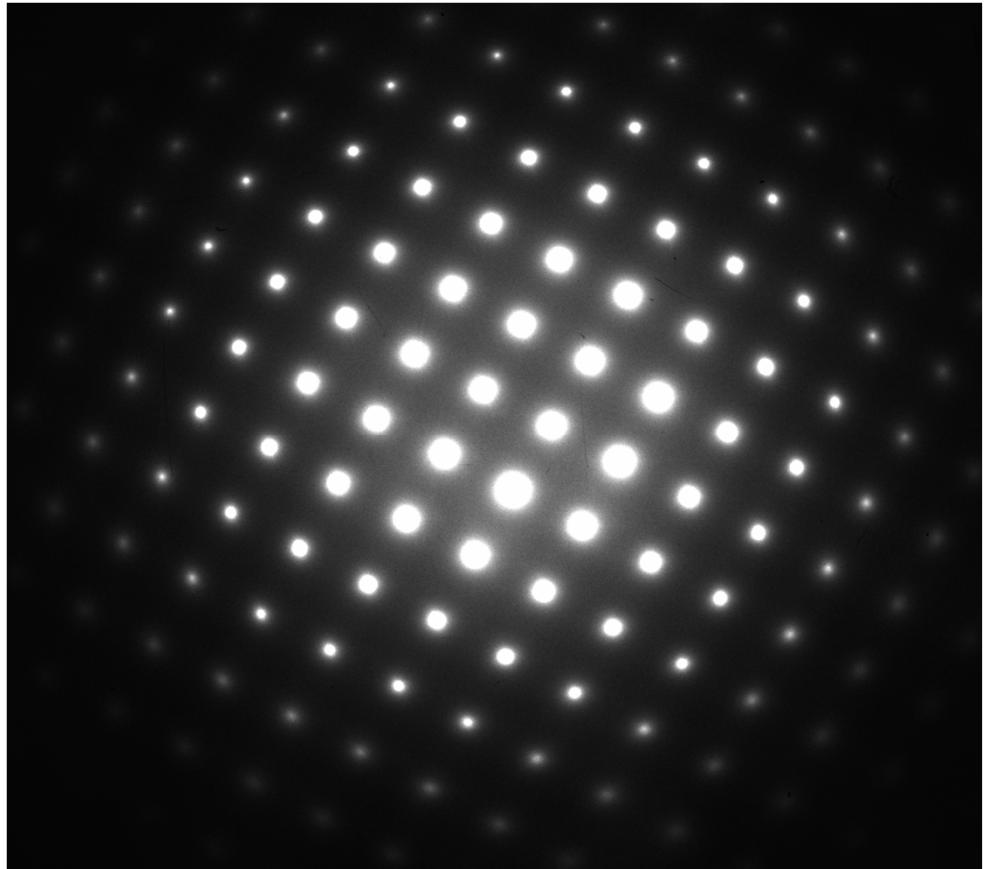
b) few Nb nitrides-features (Nb<sub>2</sub>N reflections) in Nb near-surface. Nitride “teeth” go  $\sim 0.2 \mu\text{m}$  deep



# Room T TEM on N doped surface AFTER EP

---

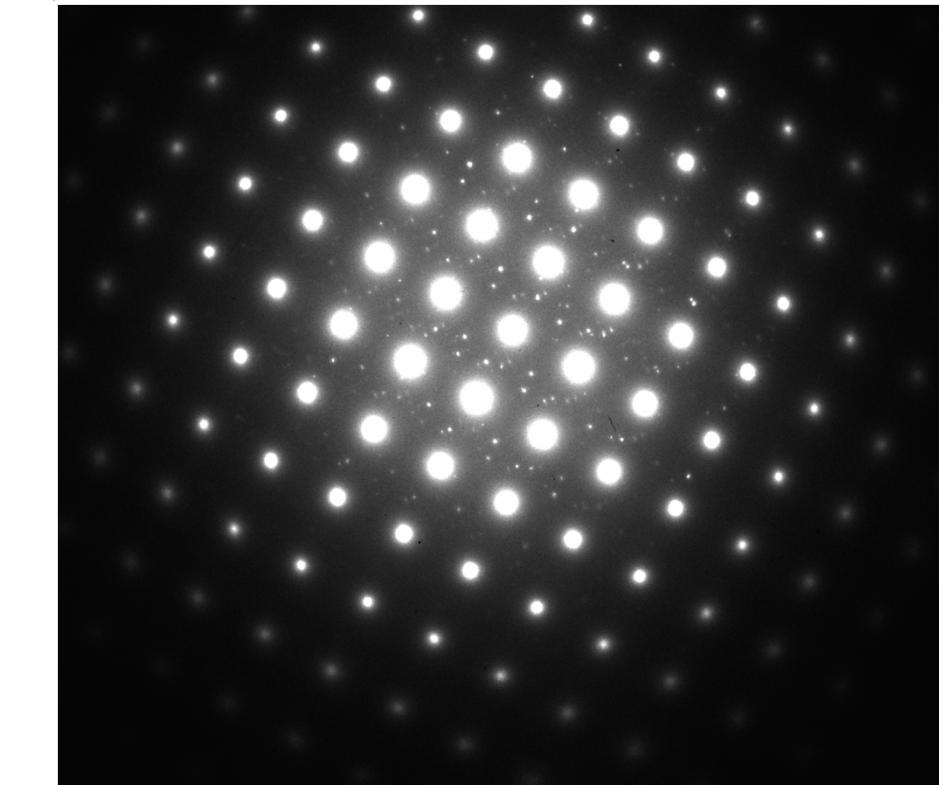
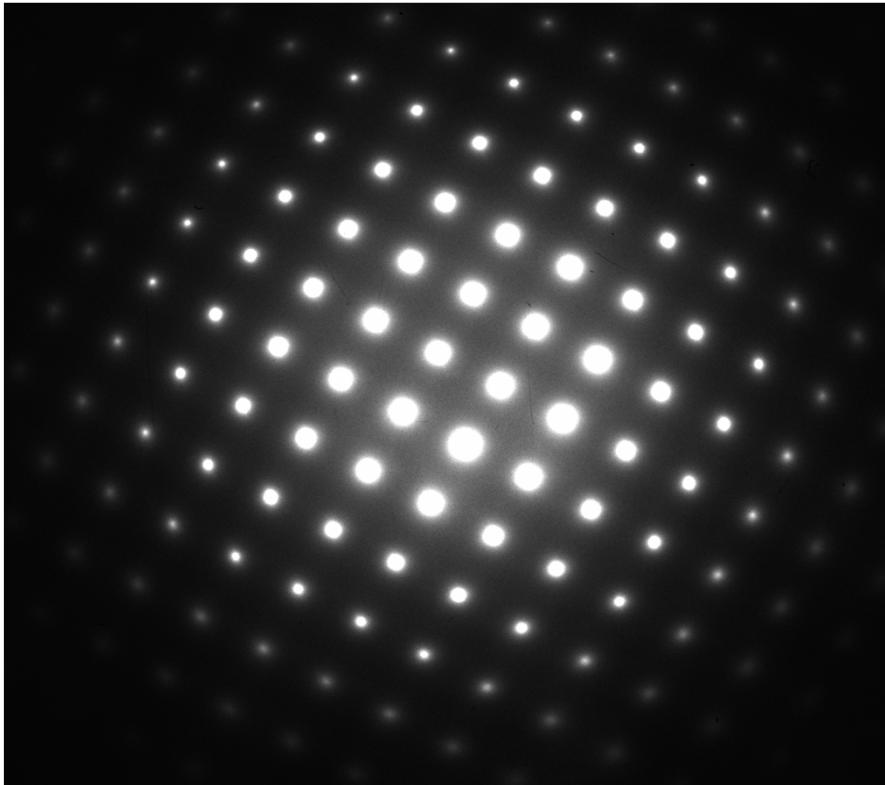
- Preliminary: no visible Nb nitrides-teeth in near-surface show only Nb reflections
- Confirms that root of improvement is from nitrogen as interstitial in the lattice



# Cryogenic TEM on N doped surface AFTER EP

ROOM T

90K

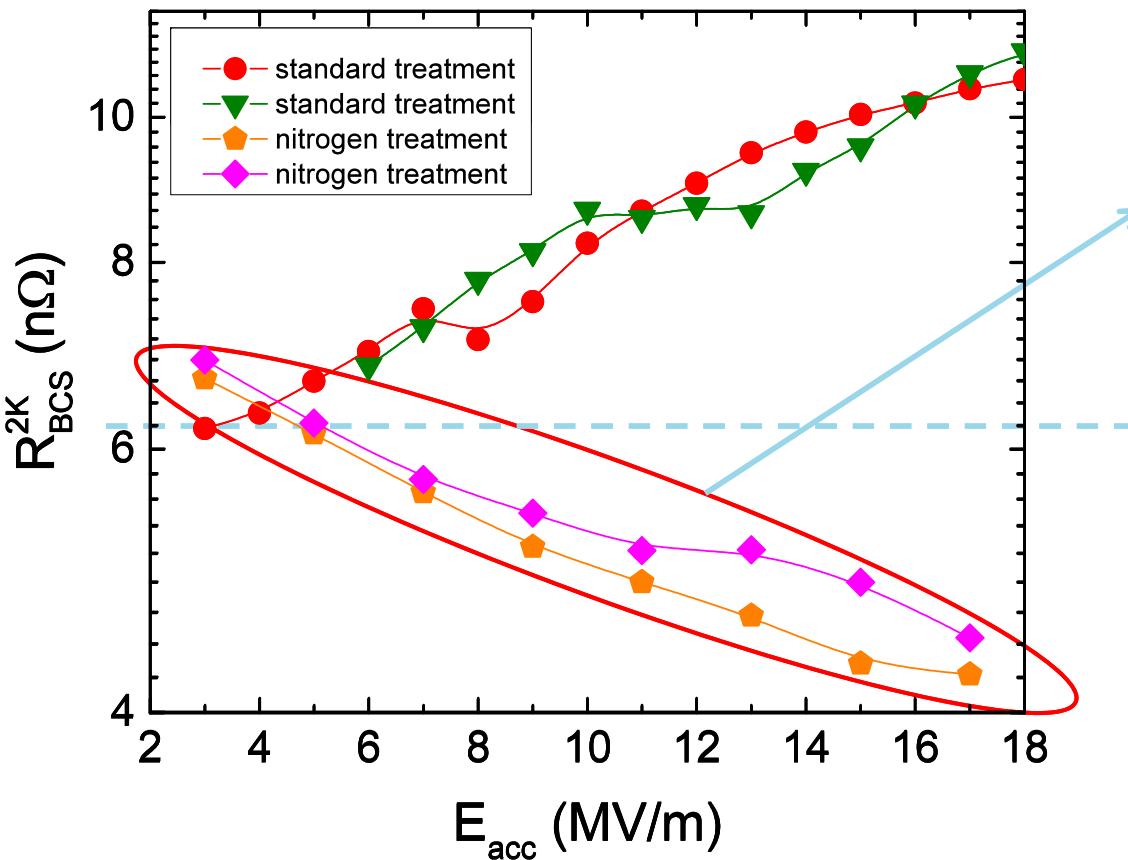


Preliminary: large near-surface area is affected by Nb nanohydride precipitation!  
But different than typical: closely spaced, very small/thin Nb hydrides.

Nanohydrides in standardly treated samples: Trenikhina et. al. J. of Appl. Phys., 117, 154507 (2015).



# Physics – perceived BCS limit has been overcome



Anti-Q-slope emerges  
from the BCS surface  
resistance decreasing  
with field

This is what BCS theory  
predicted to be the  
lowest possible surface  
resistance

A. Grassellino et al, 2013 *Supercond. Sci. Technol.* **26** 102001 (Rapid Communication)

A. Romanenko and A. Grassellino, *Appl. Phys. Lett.* **102**, 252603 (2013)

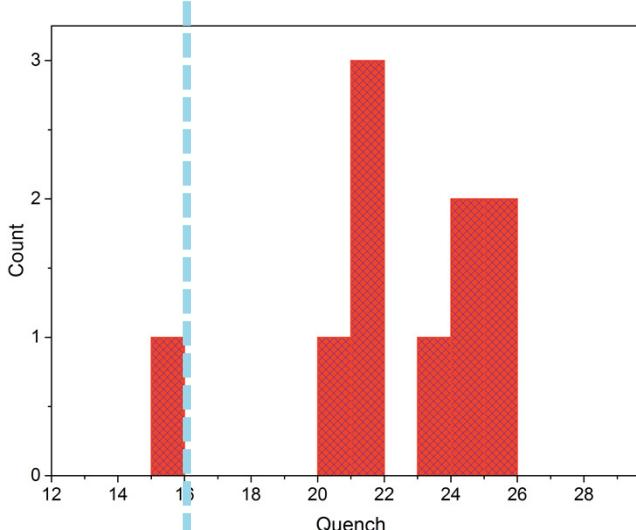
# Models for explaining N doping $R_{BCS}(B)$

---

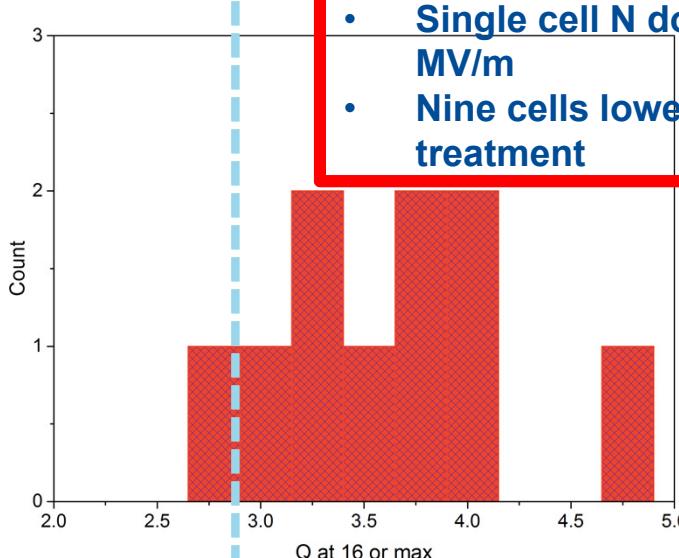
- B.P. Xiao, C. Reece, M. J. Kelley from JLab and College of William and Mary
  - Momentum of Cooper pairs leads to an inverted field dependence of  $R_{BCS}$ ?
  - [B.P. Xiao et al, Physica C **490** (2013) 26-31]
- A. Gurevich from ODU
  - Time-dependent density of states leads to the effect?
  - [A. Gurevich, Phys. Rev. Lett. **113**, 087001 (2014)]

# Open questions: nature of premature quench in N doped

16 MV/m



2.7e10



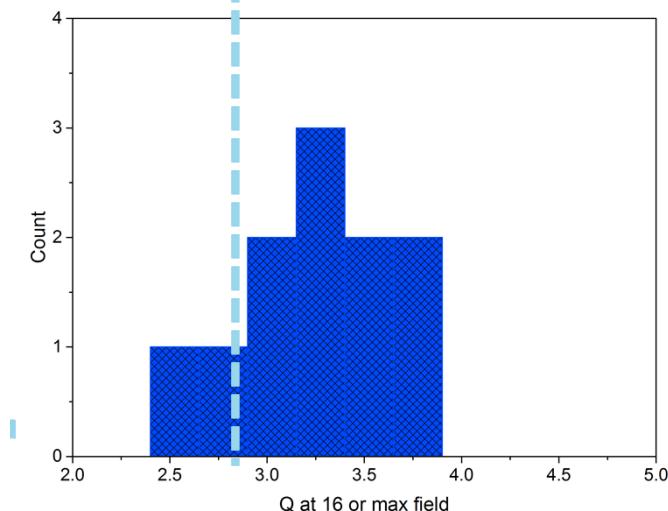
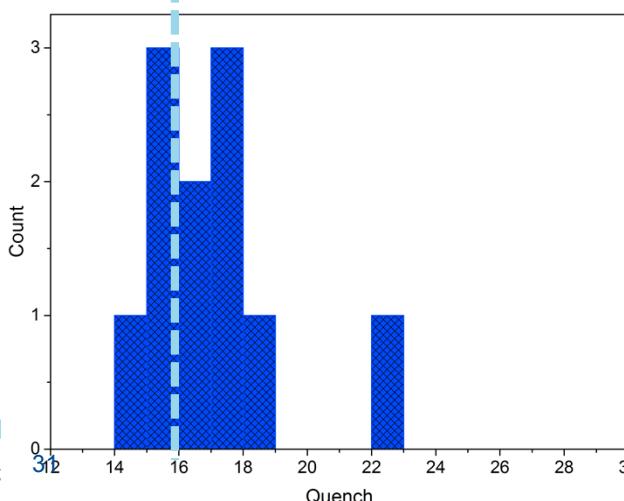
- Heavier doping levels result in premature quench
- Single cell N doped demonstrated up to 39 MV/m
- Nine cells lower than single cell for same treatment

Recipe 2/6  
“light doping”

$$\langle Q \rangle = 3.6 \text{e}10$$

$$\langle E_{\max} \rangle = 22.2 \text{ MV/m}$$

$$E_{\max} \text{ median} = 22.8 \text{ MV/m}$$



Recipe 20/30  
“heavy doping”

$$\langle Q \rangle = 3.24 \text{e}10$$

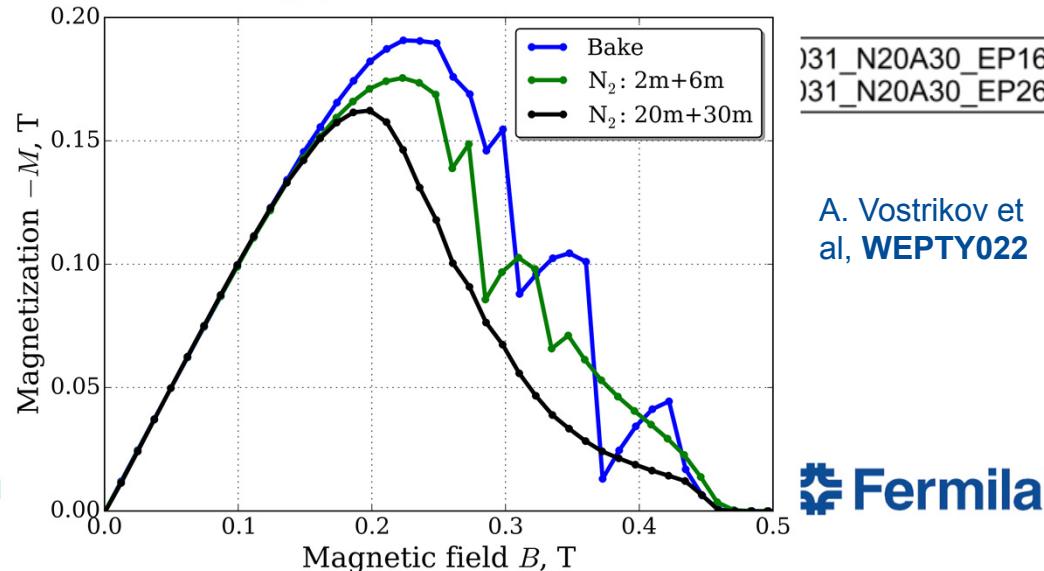
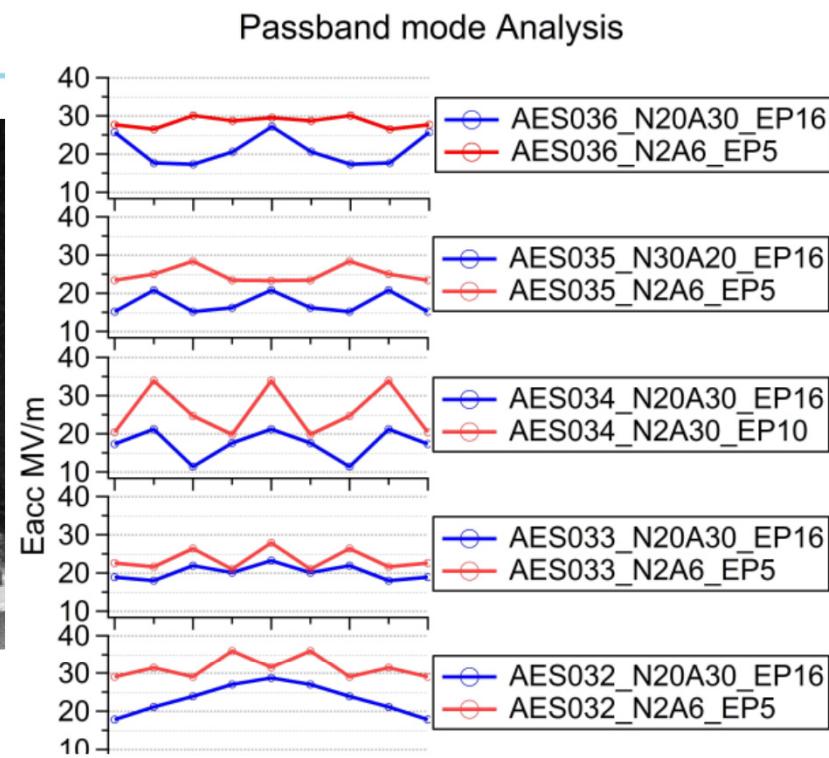
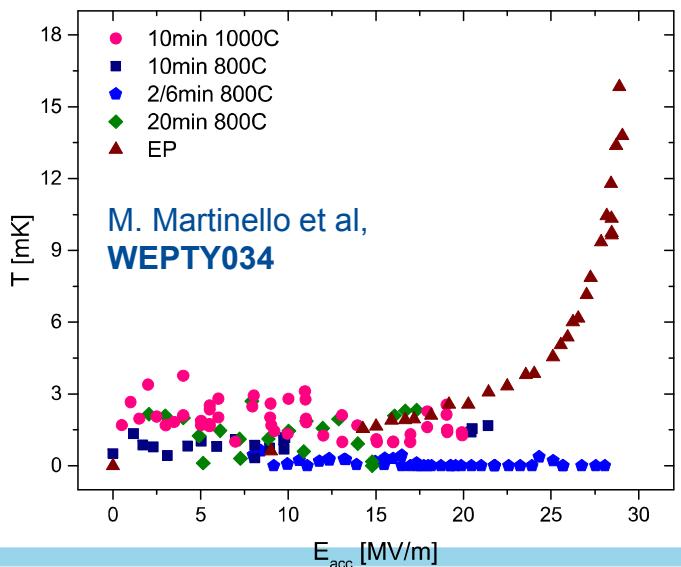
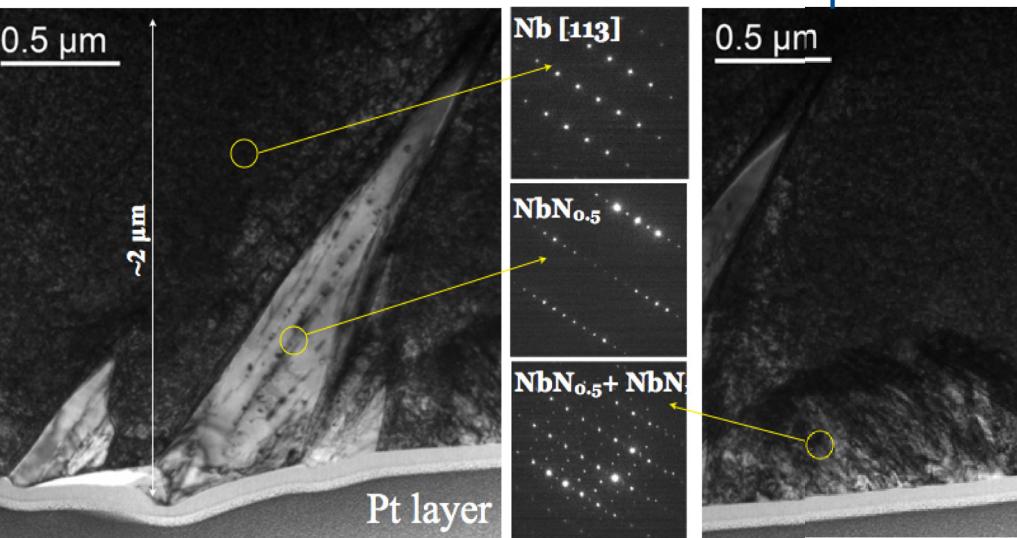
$$\langle E_{\max} \rangle = 16.3 \text{ MV/m}$$

$$E_{\max} \text{ median} = 16.5 \text{ MV/m}$$

# New insights on quench in N doped cavities

A. D. Palczewski et al,  
WEPWI019

Nitride teeth...residual nanonitrides post EP?

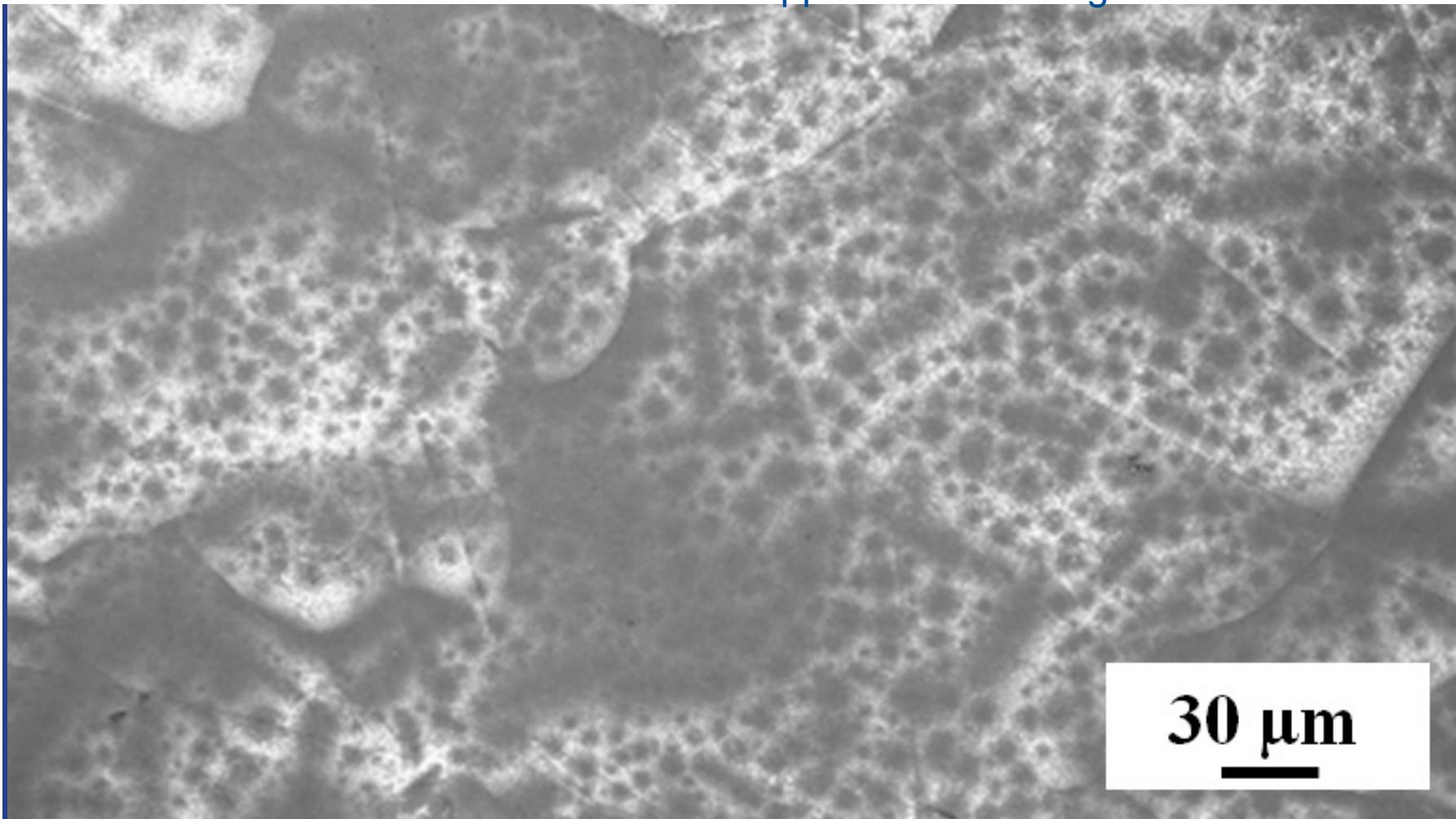


---

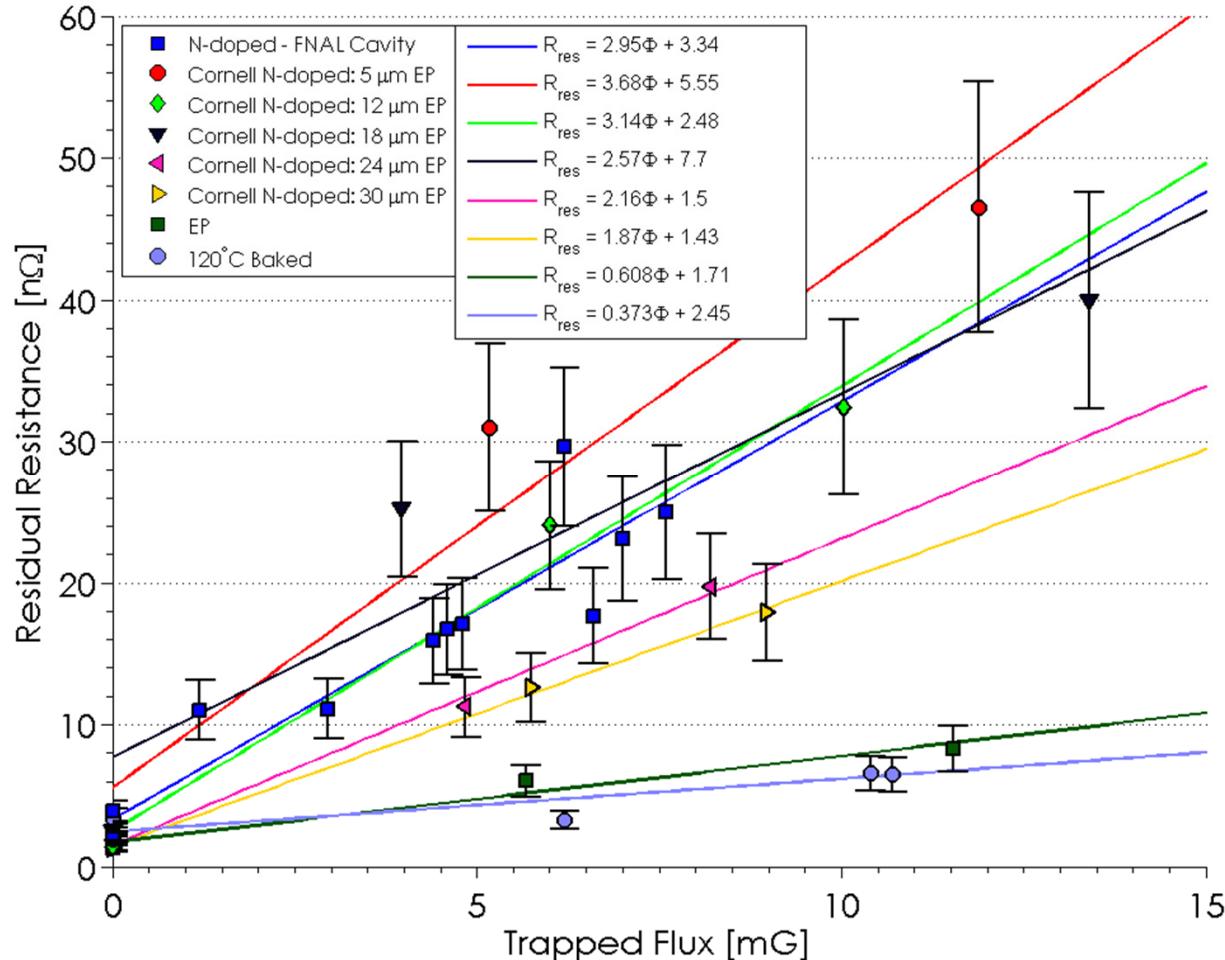
## *Efficient magnetic flux expulsion via fast cooling*

# Magnetic flux lines can be trapped and cause large RF losses

Trapped vortices imaged via Bitter Decoration

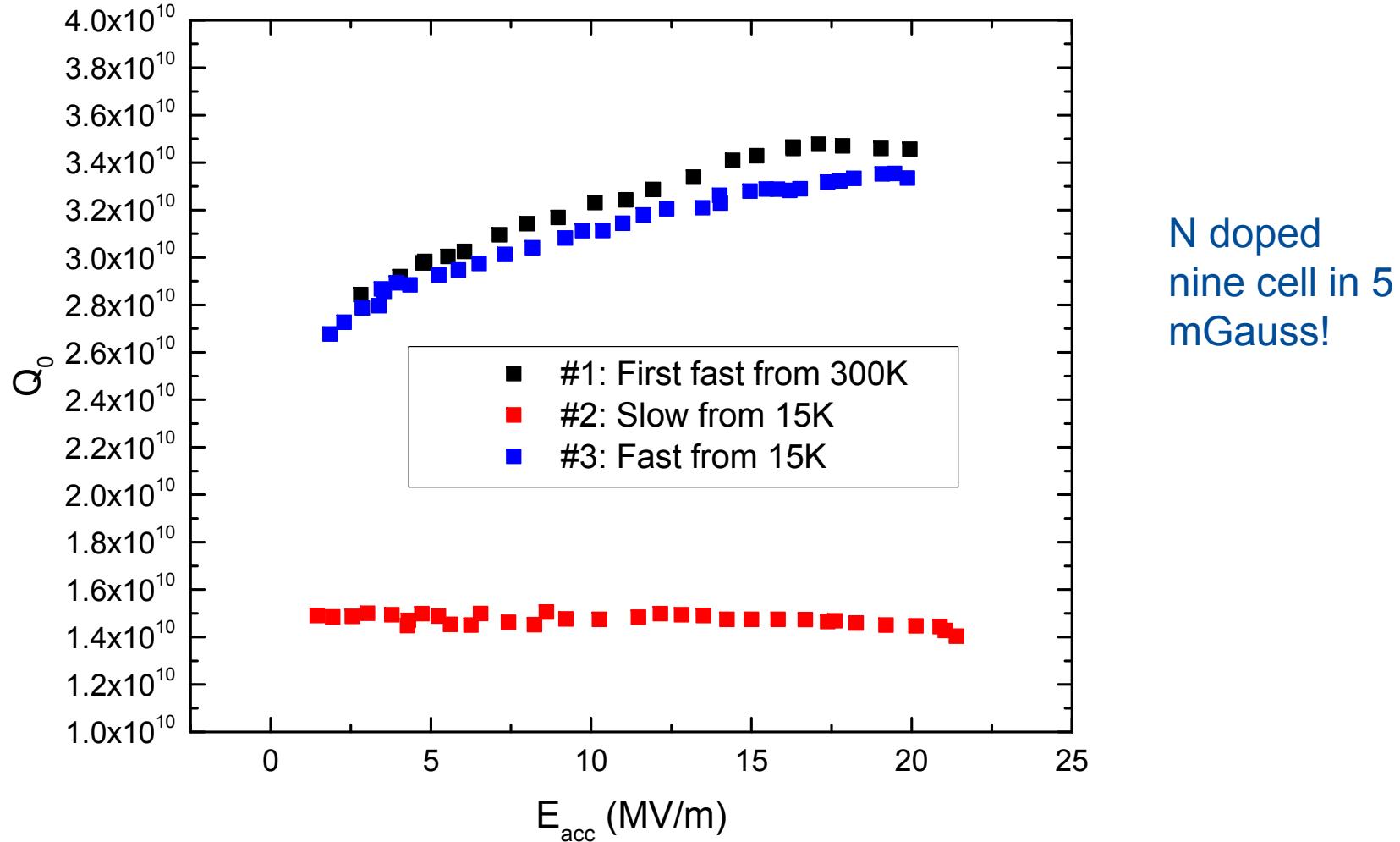


# Enhanced sensitivity to magnetic field of N doped



D. Gonnella and M. Liepe. Cool Down and Flux Trapping Studies on SRF Cavities. Proceedings of LINAC 14, Geneva, Switzerland. MOPP017.

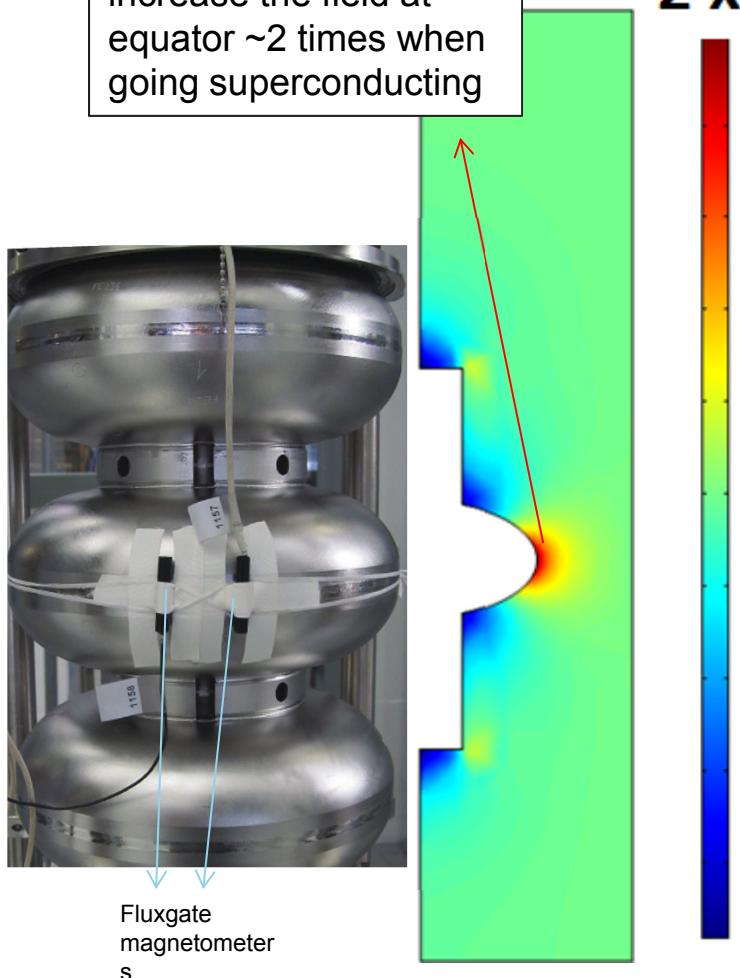
# At FNAL, discovered that slow cooldown can kill high Q



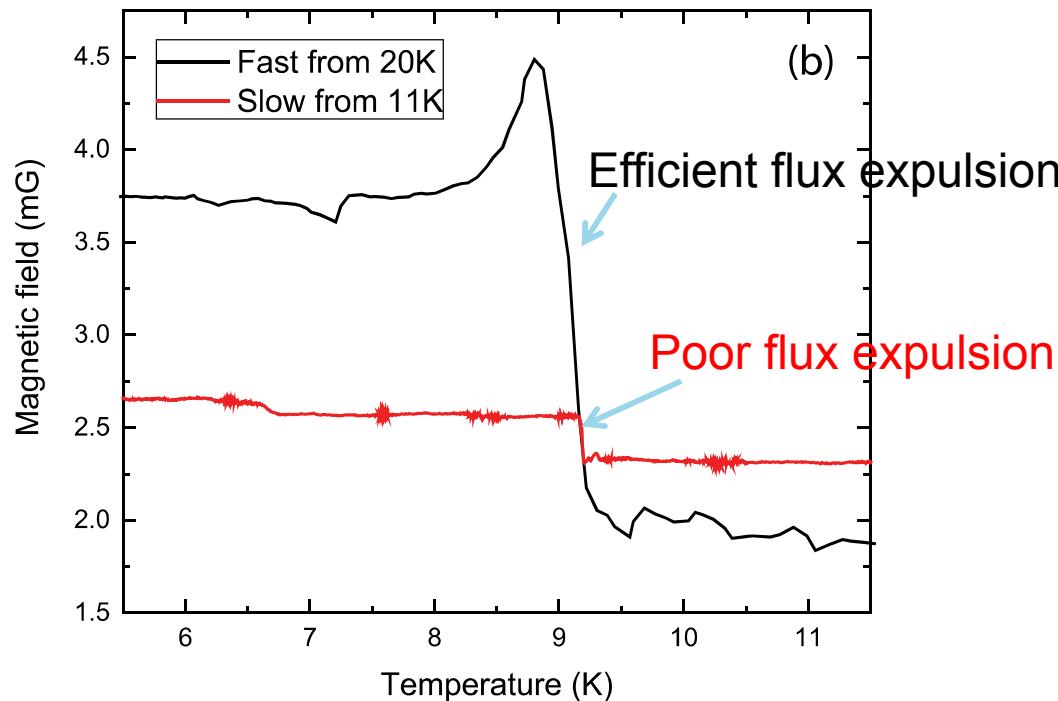
A. Romanenko, A. Grassellino, O. Melnychuk, D. A. Sergatskov, J. Appl. Phys. **115**, 184903 (2014)

# Magnetic probes revealed the new physics

Full expulsion of the magnetic field should increase the field at equator ~2 times when going superconducting

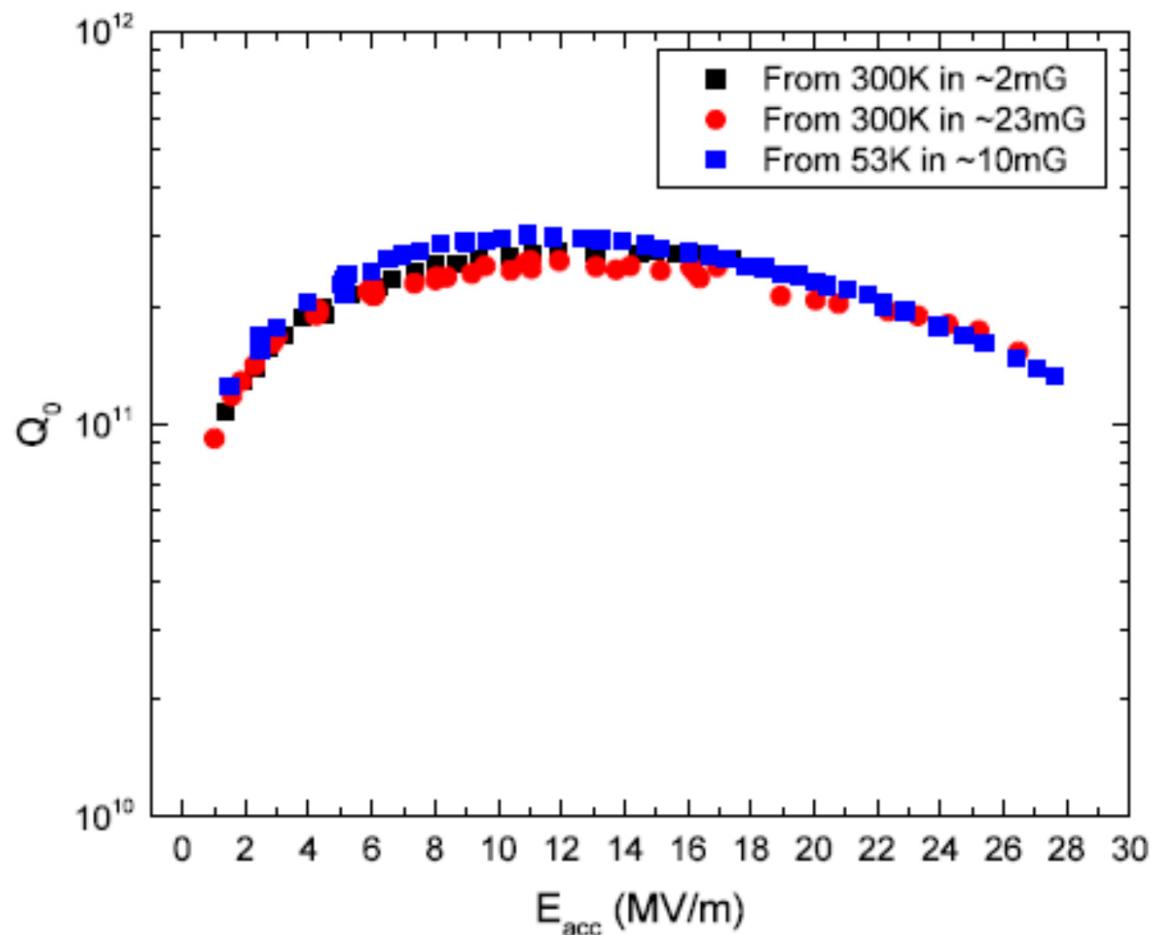


**2 x H** It turns out the expulsion efficiency can be controlled by the cooldown procedure through  $T_c=9.2K$  (fast/slow, uniform or not)



Same Meissner behavior for EP, EP+120C, N doping, fine/single grain, cooling is what matters

# Record Q up to the highest fields combining N doping and efficient flux expulsion

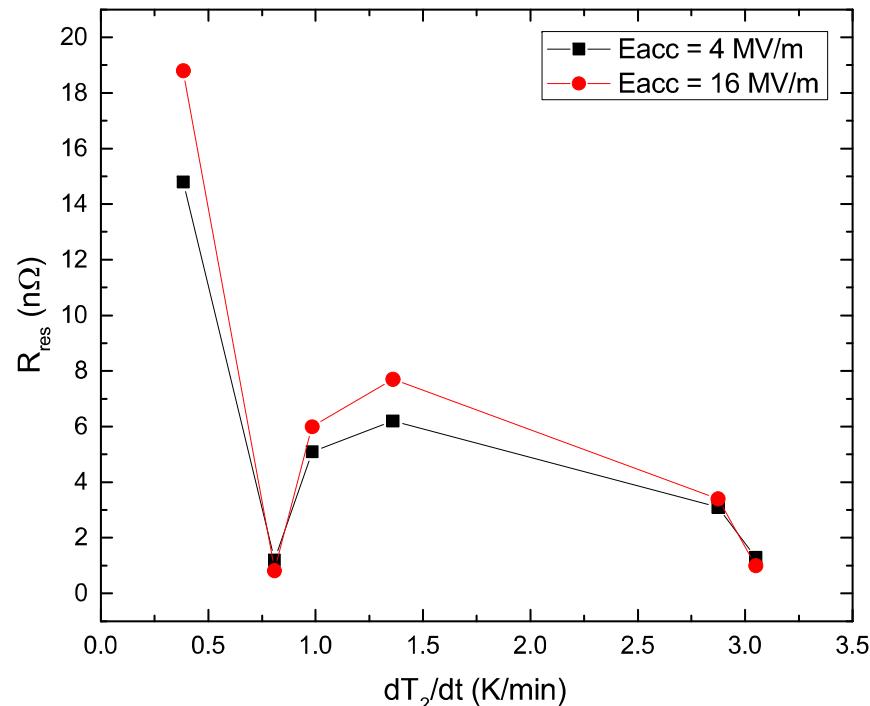
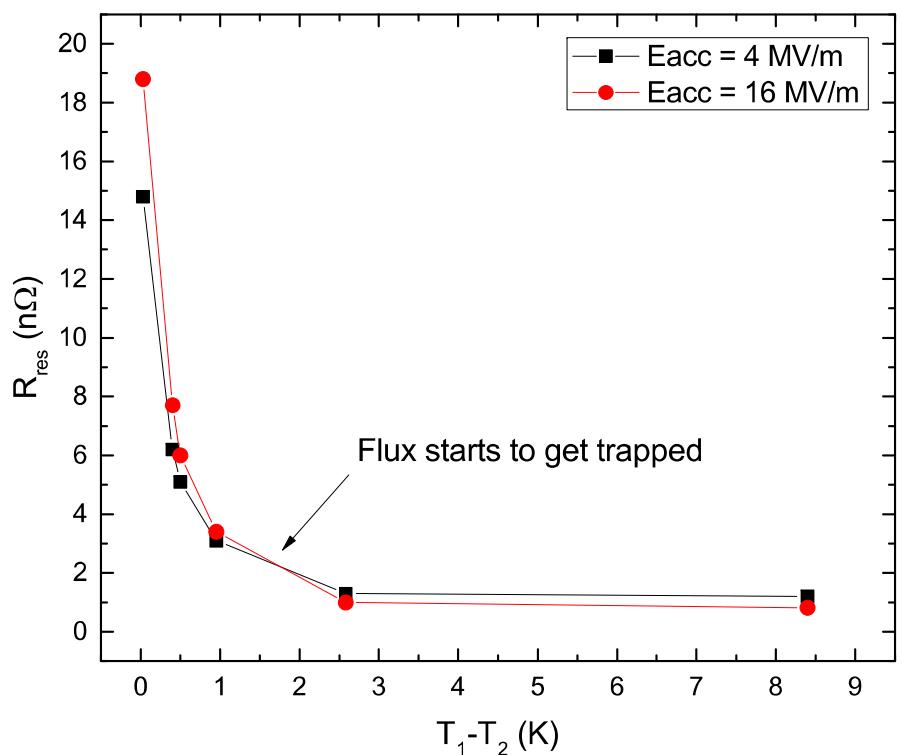


- High thermal gradient provides depinning force allowing efficient magnetic field expulsion
- Ultra-high  $Q_0$  even in 190mG

A. Romanenko, A. Grassellino et al. J. Appl. Phys. 115, 184903 (2014)

A. Romanenko, A. Grassellino et al. Appl. Phys. Lett. 105, 234103 (2014)

# It's a matter of thermogradient along the cell (at the phase front) – and geometry of the problem has an effect, too...

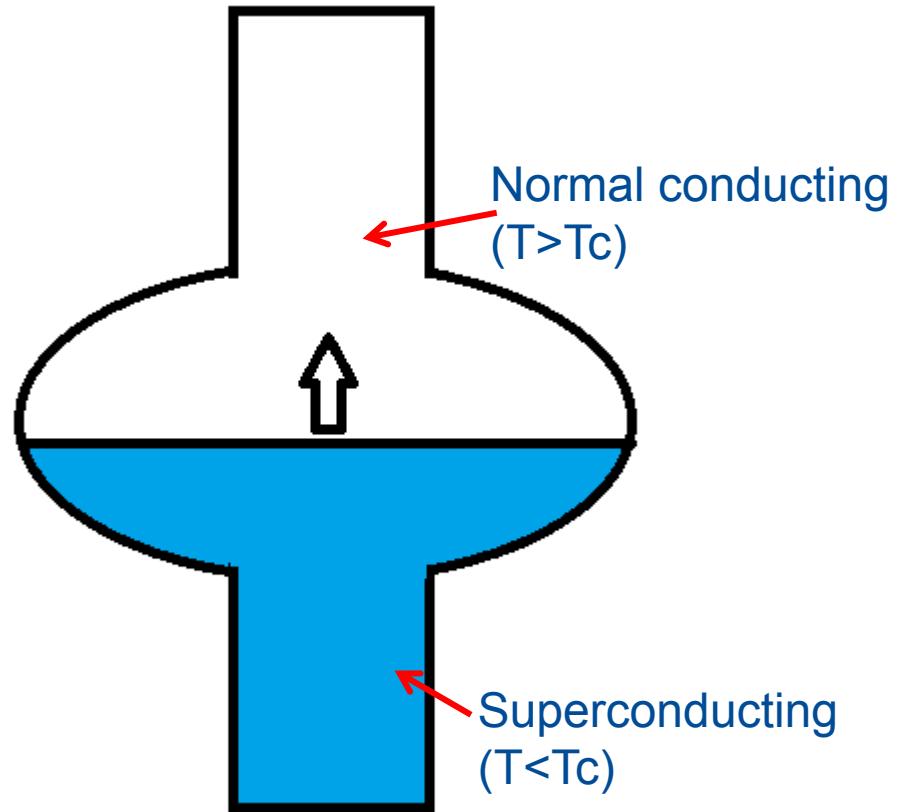


A. Romanenko, A. Grassellino, A. Crawford, D. A. Sergatskov, Appl. Phys. Lett. 105, 234103 (2014)

M. Martinello et al, [arXiv:1502.07291](https://arxiv.org/abs/1502.07291)

# Details of superconductivity nucleation matter

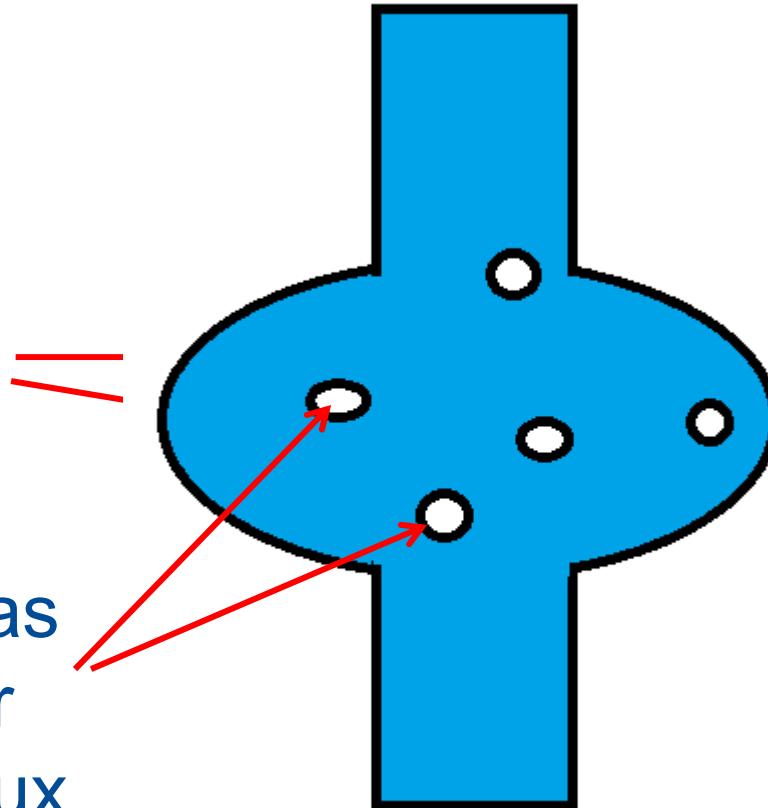
Fast cooldown – well-defined superconducting/normal boundary is moving from bottom to the top => no energy barrier for flux to be expelled



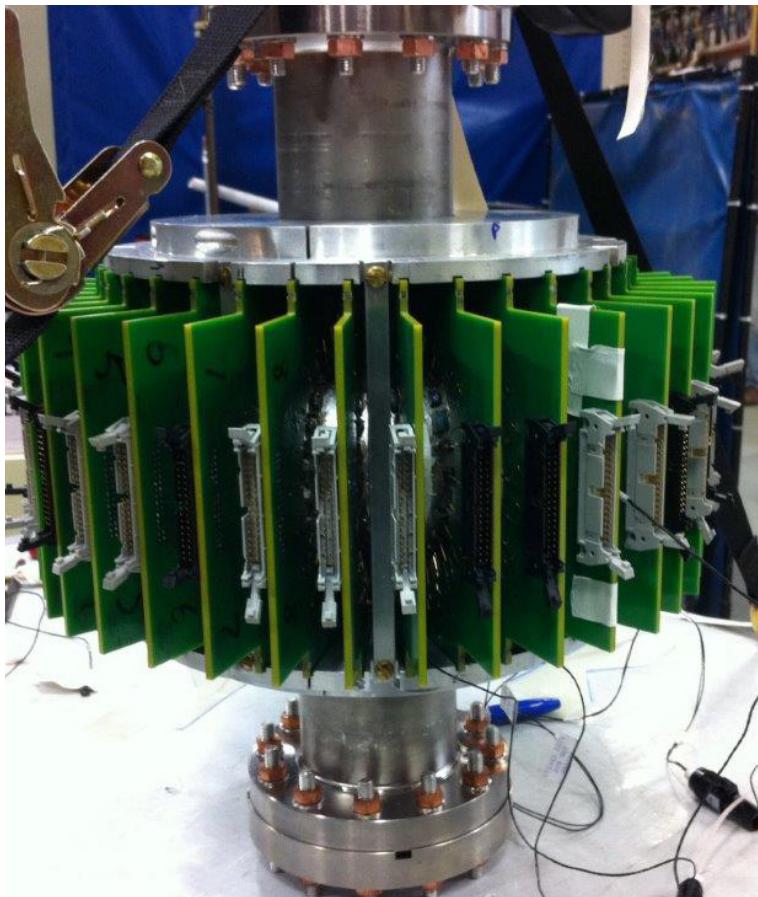
# Details of superconductivity nucleation matter

Slow uniform cooldown –  
superconductivity is nucleated at  
multiple spots which reach  $T < T_c$

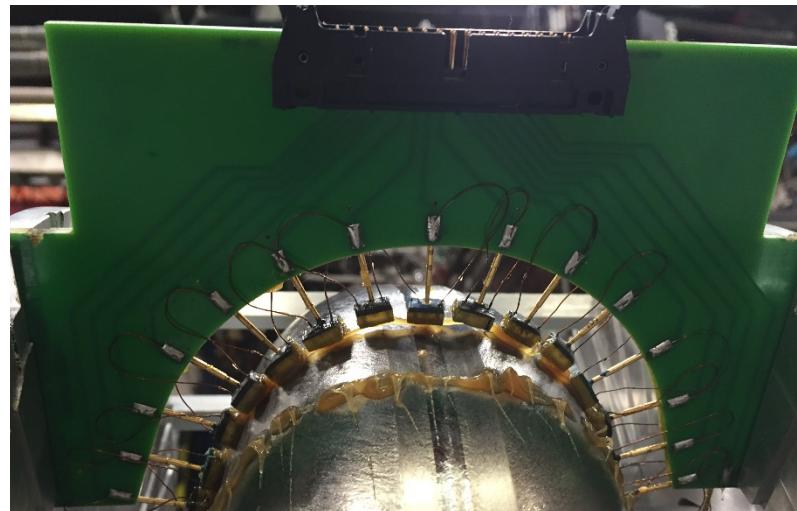
Flux surrounded by  
superconducting areas  
has an energy barrier  
for escape=> more flux  
trapping is possible



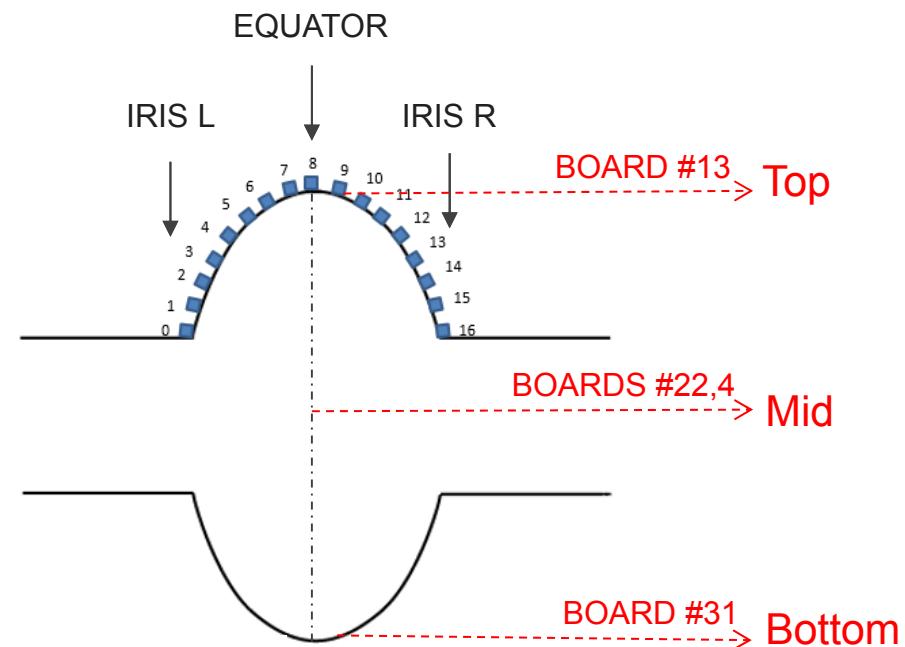
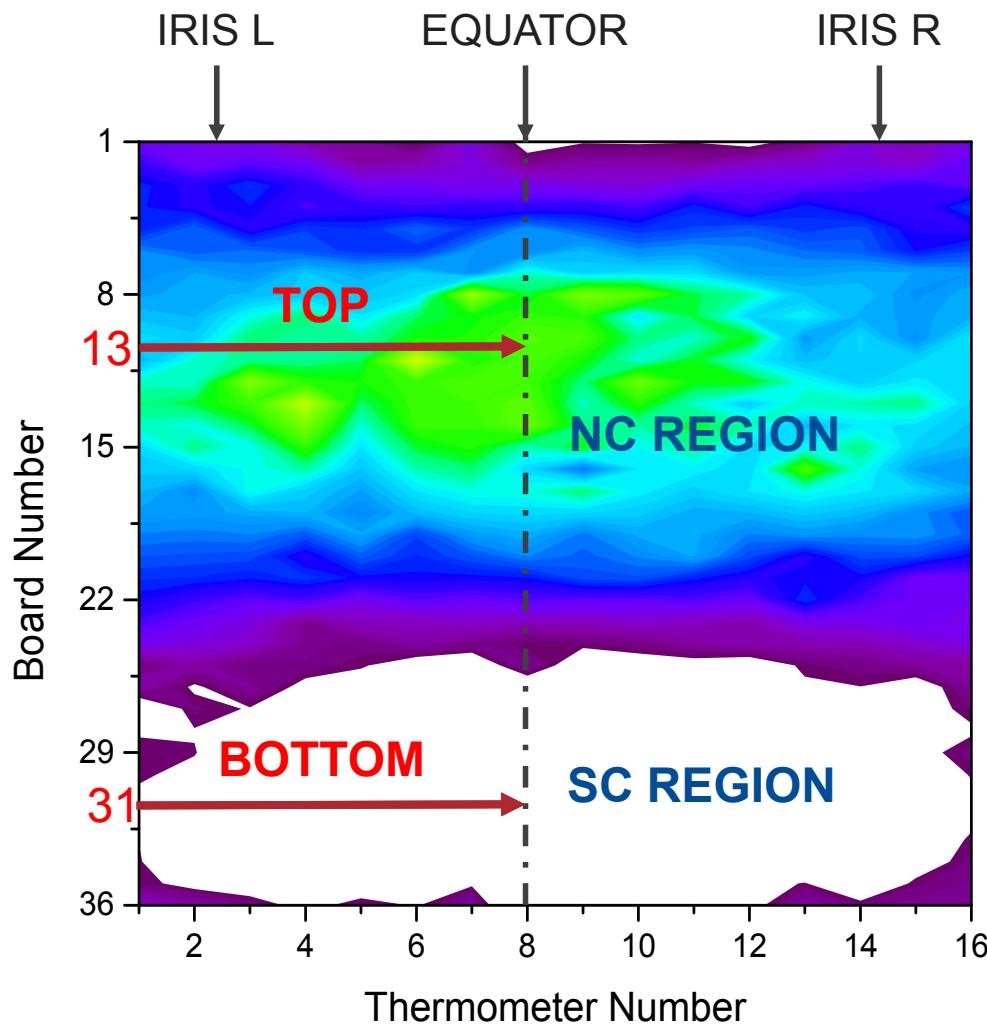
# T-map apparatus



- Cornell-based T-map system
- 36 boards with 16 thermometers each



**576 thermometers  
all around the cavity**



# Fast Cool-down T-map

Starting T: 250K

# Fast Cool-down From 250K

Board Number

1

8

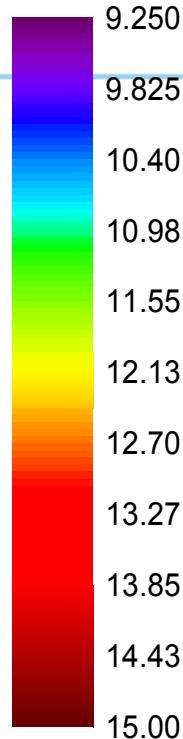
15

22

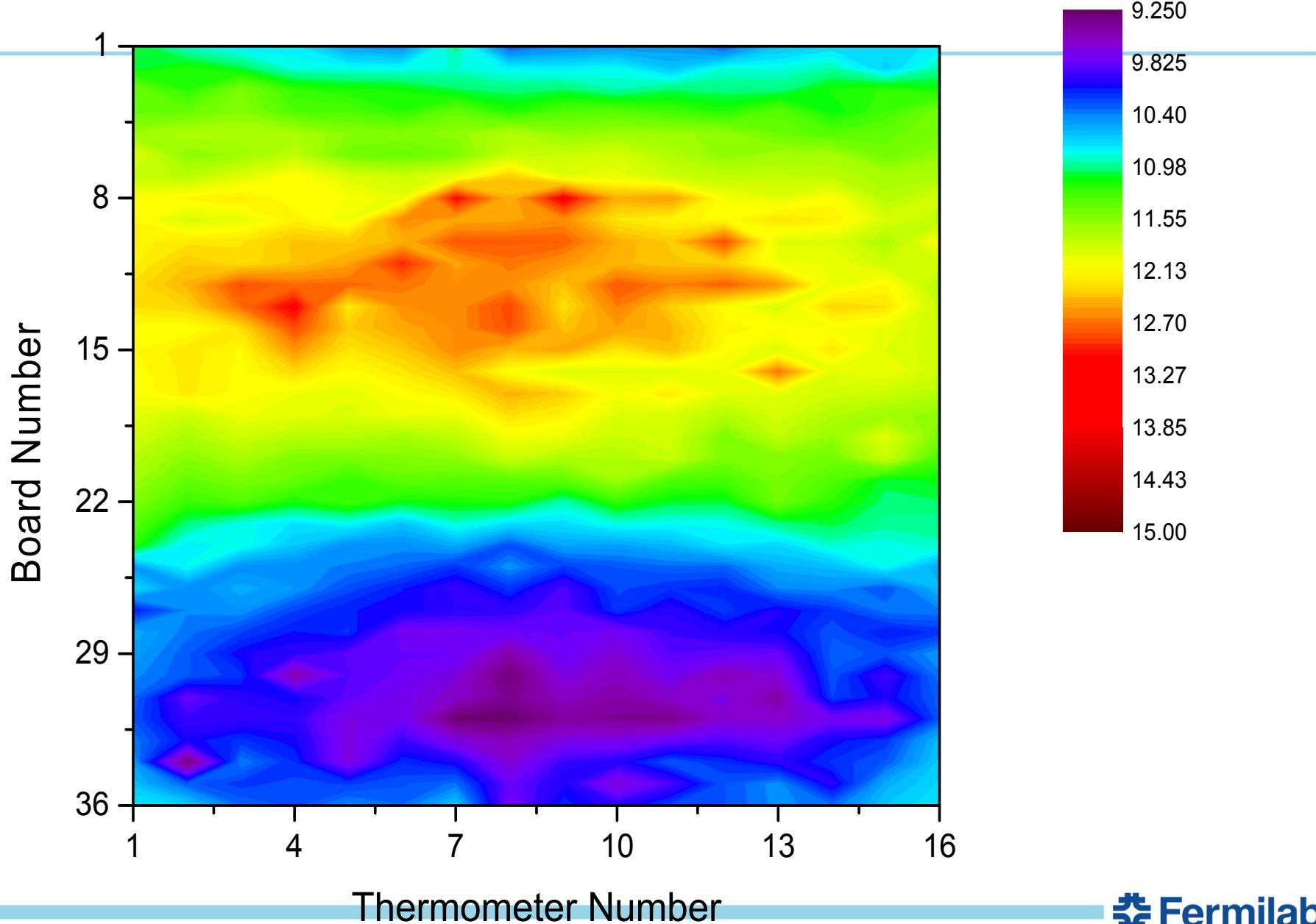
29

36

Thermometer Number



# Fast Cool-down From 250K



# Fast Cool-down From 250K

Board Number

1

8

15

22

29

36

1

4

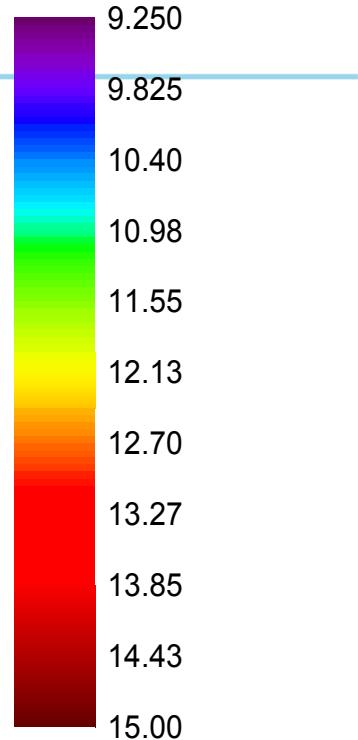
7

10

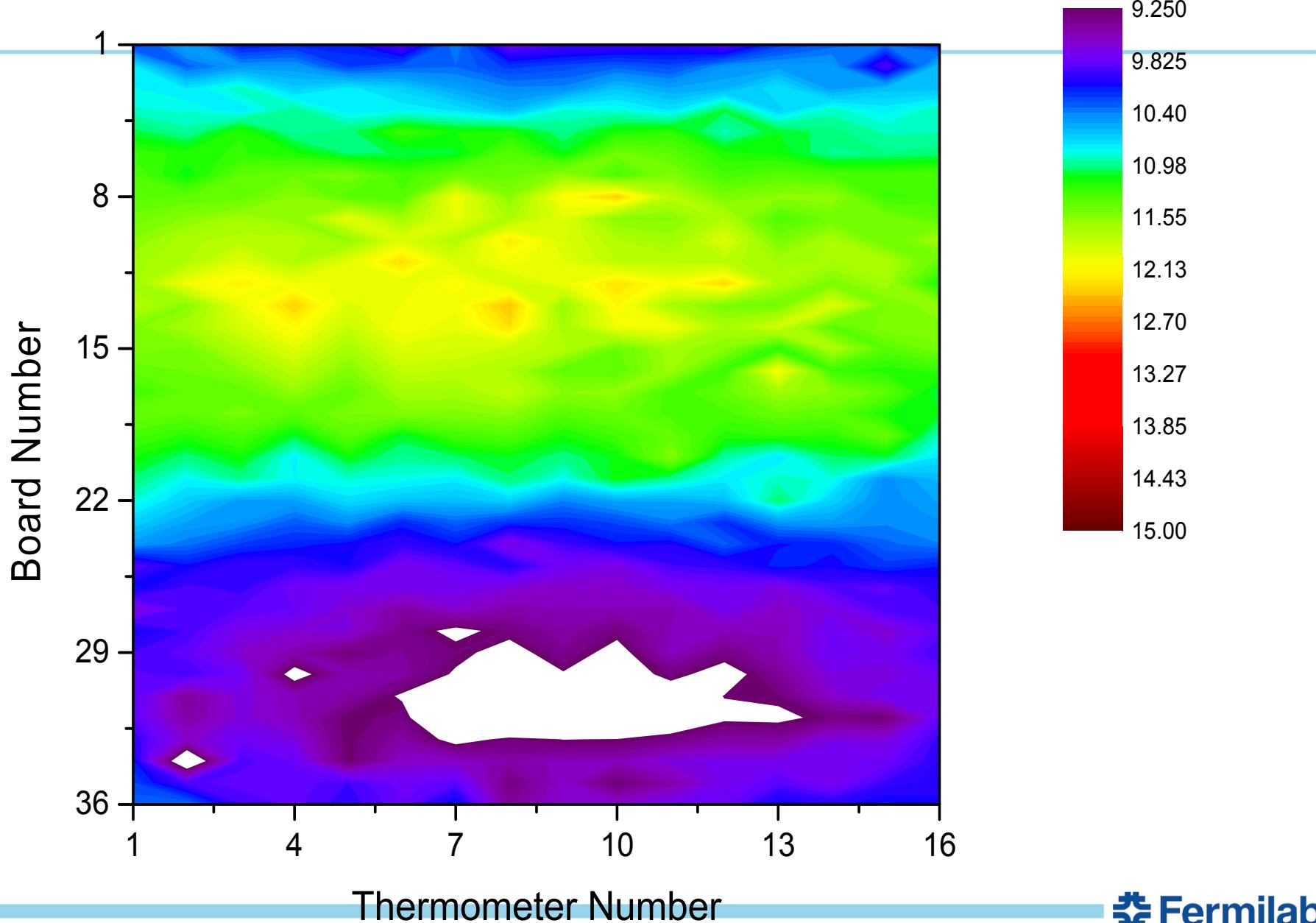
13

16

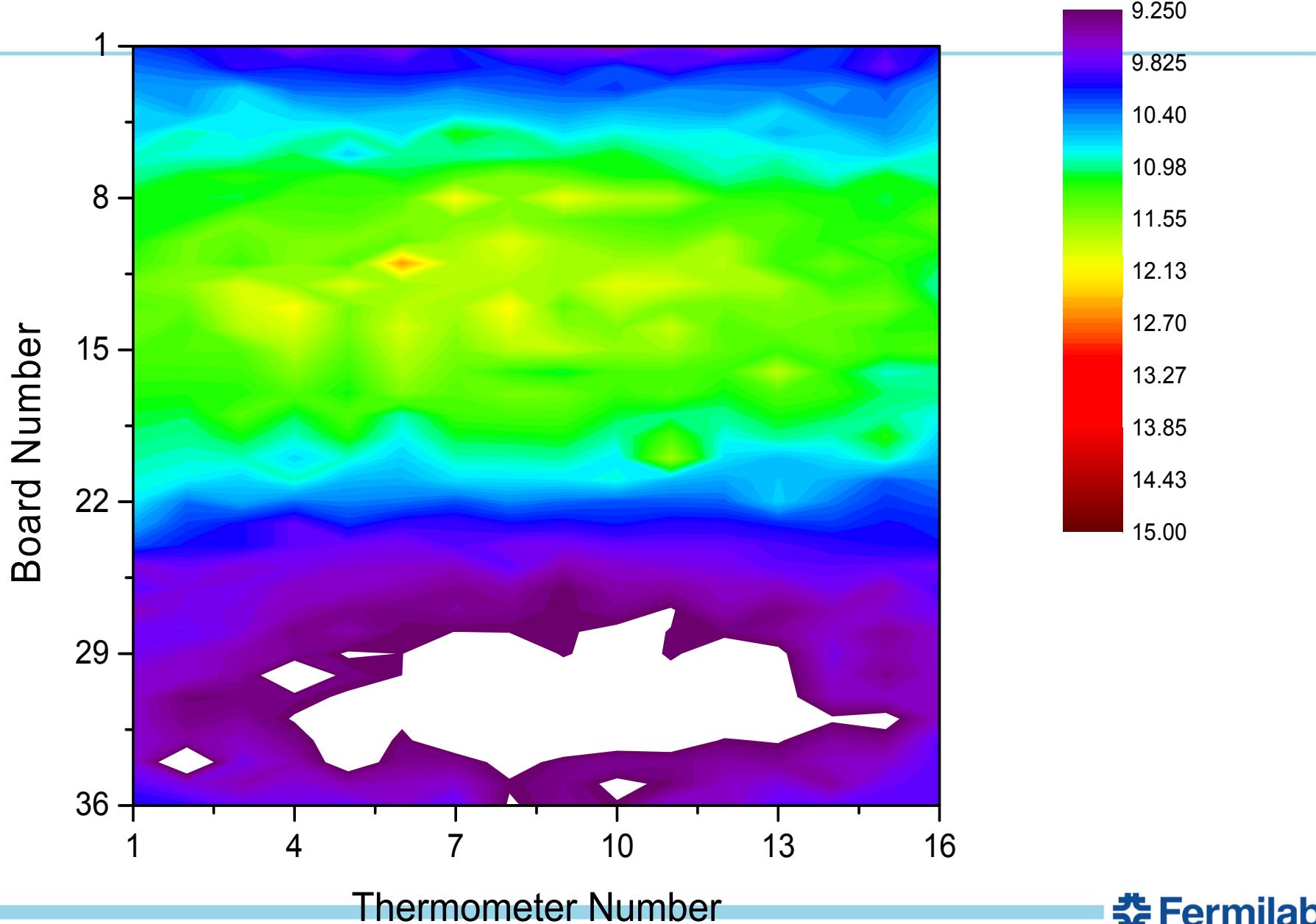
Thermometer Number



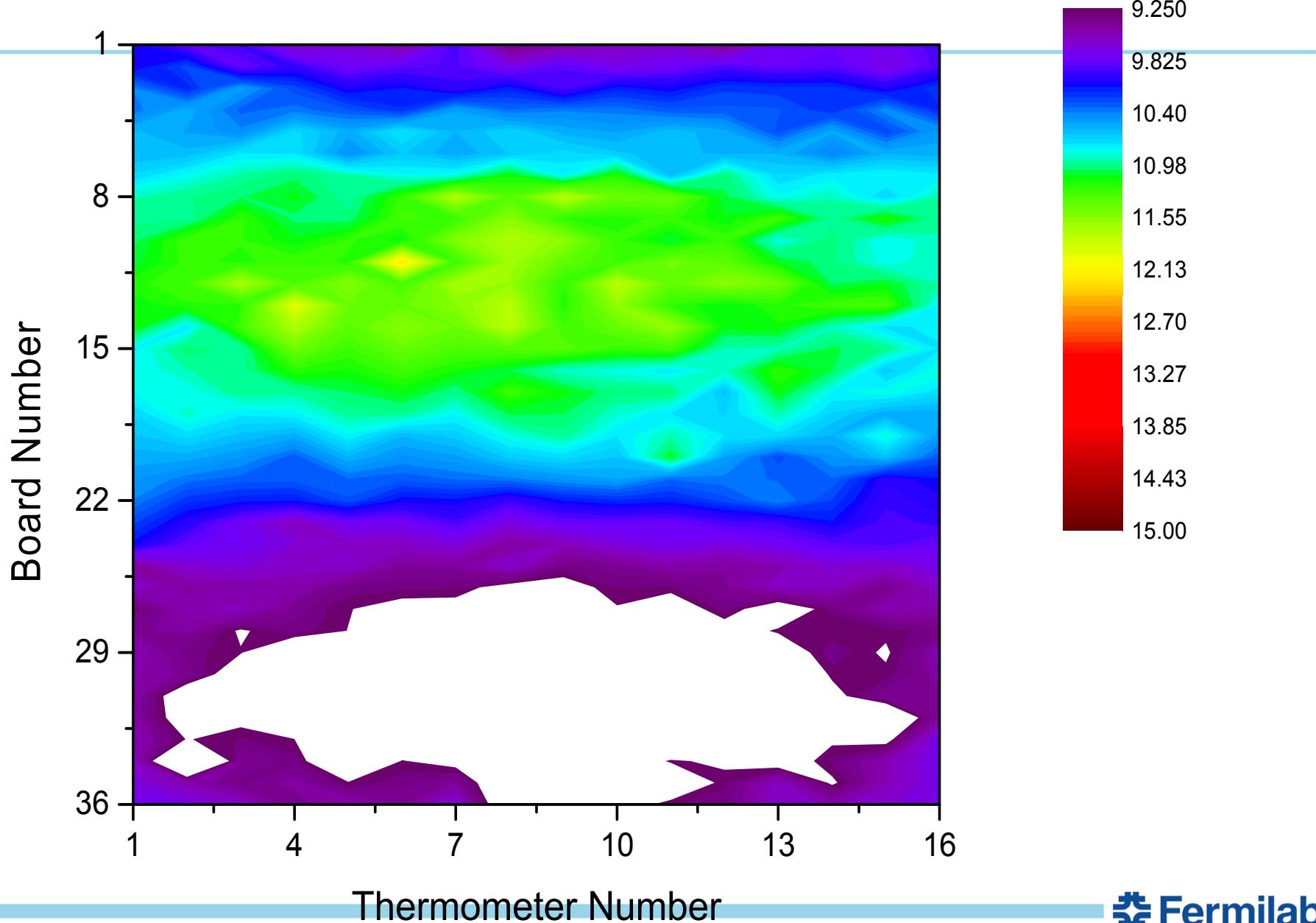
# Fast Cool-down From 250K



# Fast Cool-down From 250K



# Fast Cool-down From 250K



# Fast Cool-down From 250K

Board Number

1

8

15

22

29

36

2

4

6

8

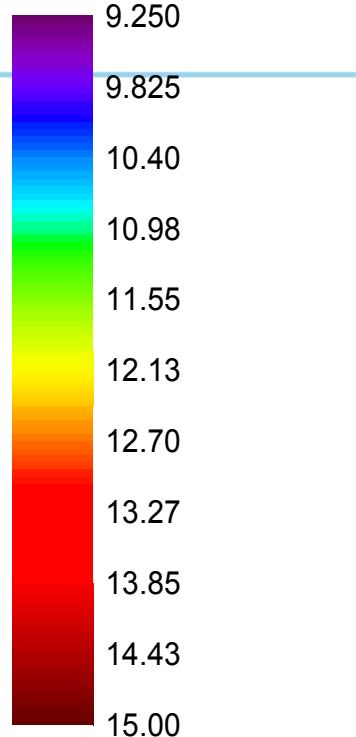
10

12

14

16

Thermometer Number



# Fast Cool-down From 250K

Board Number

1

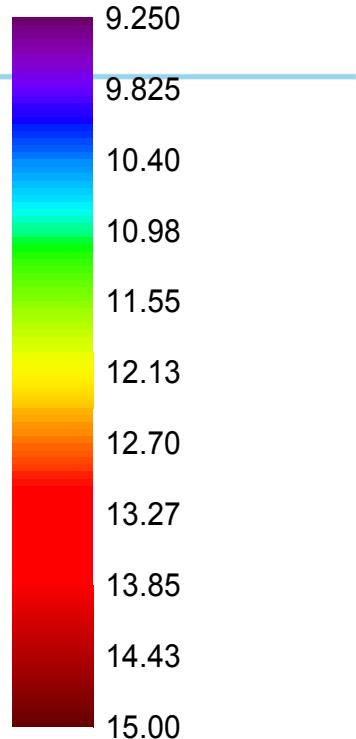
8

15

22

29

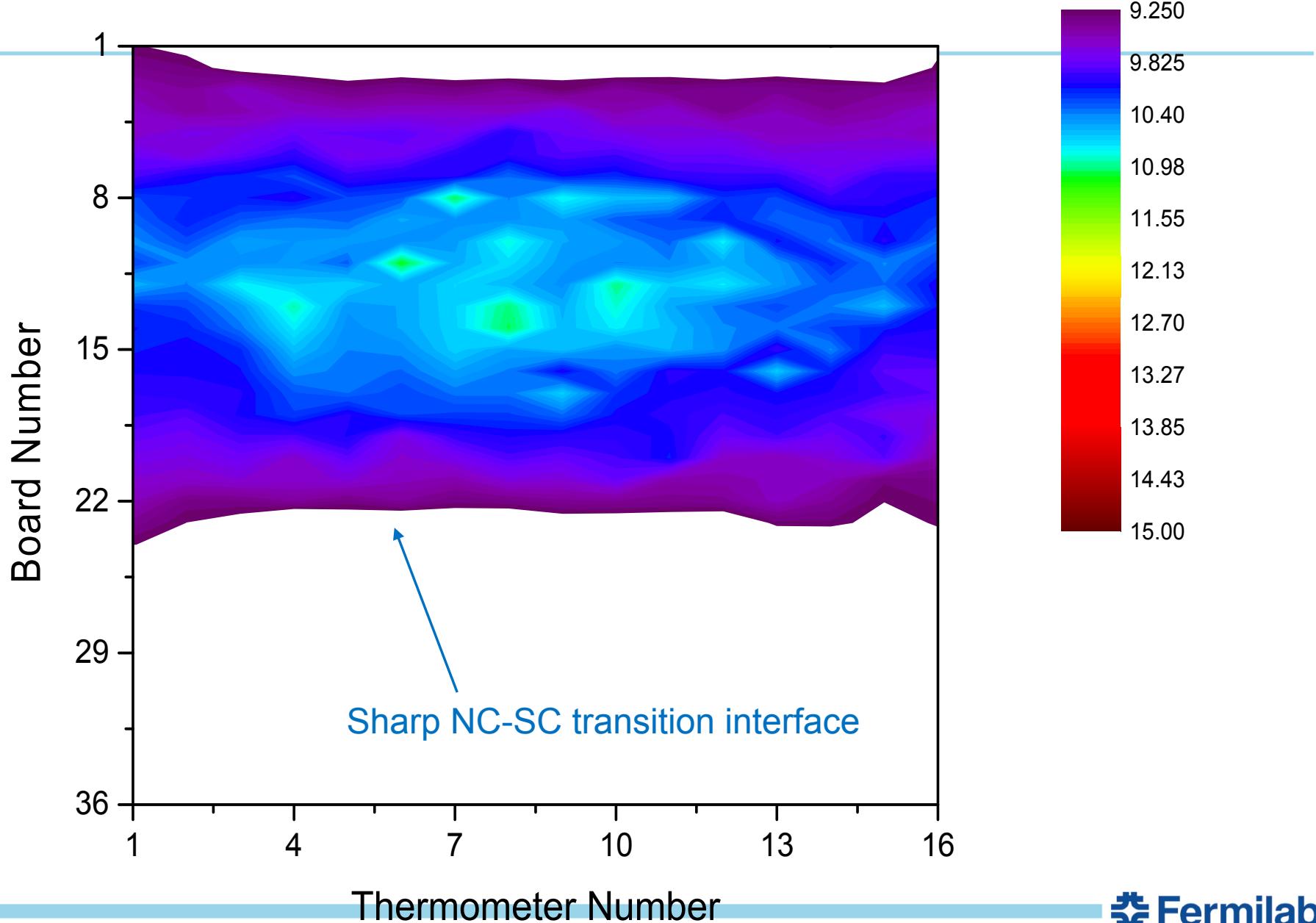
36



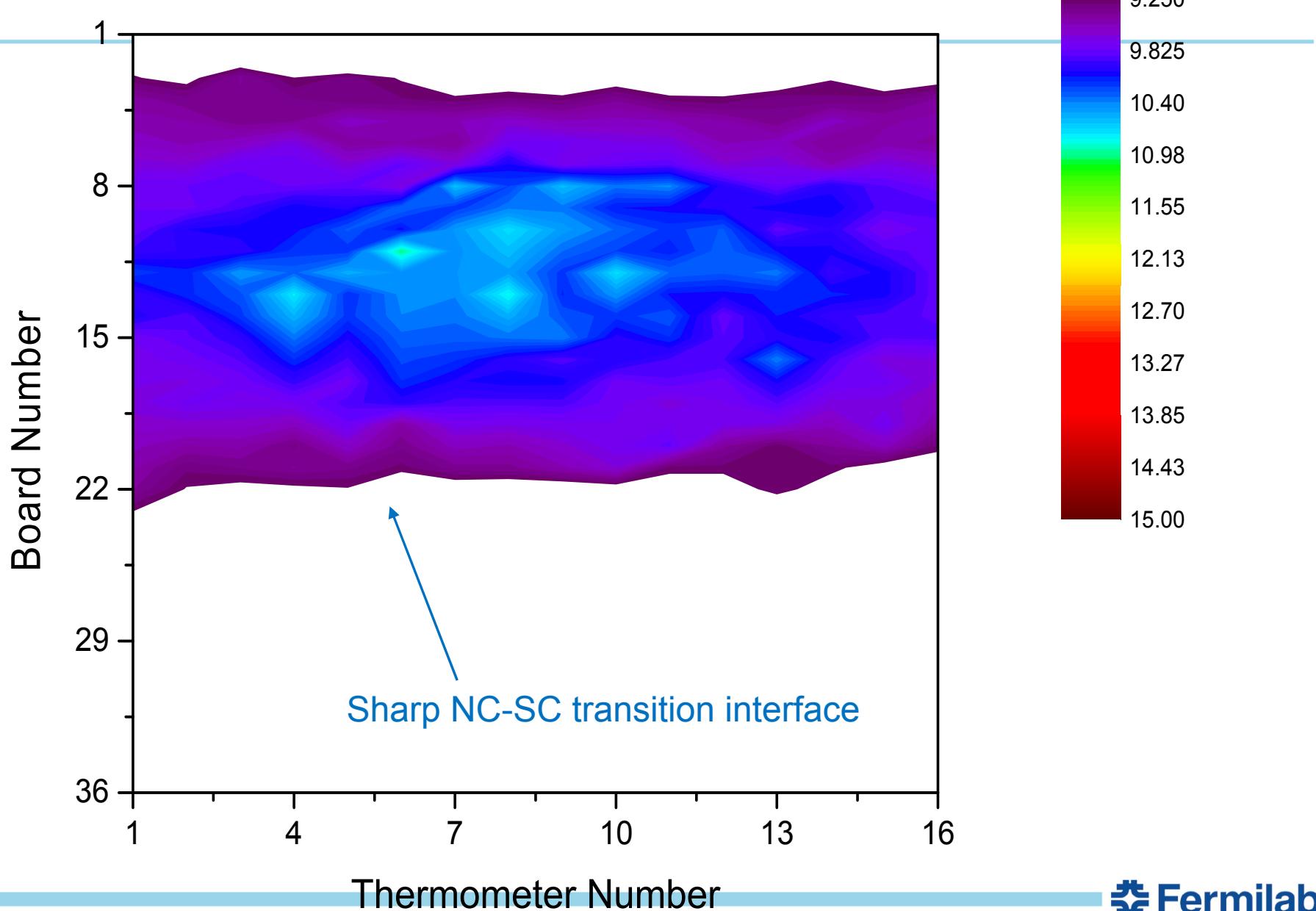
Thermometer Number

Sharp NC-SC transition interface

# Fast Cool-down From 250K



# Fast Cool-down From 250K



# Fast Cool-down From 250K

Board Number

1

8

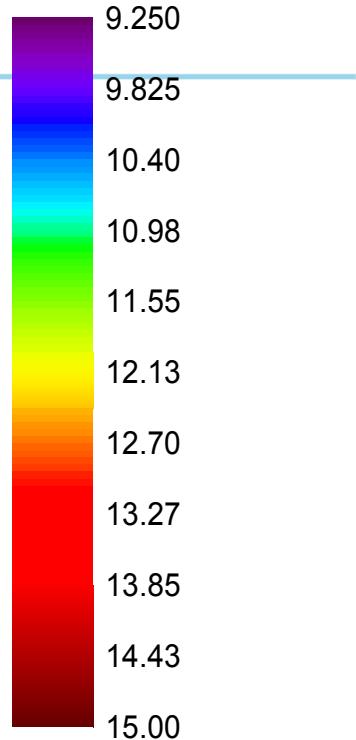
15

22

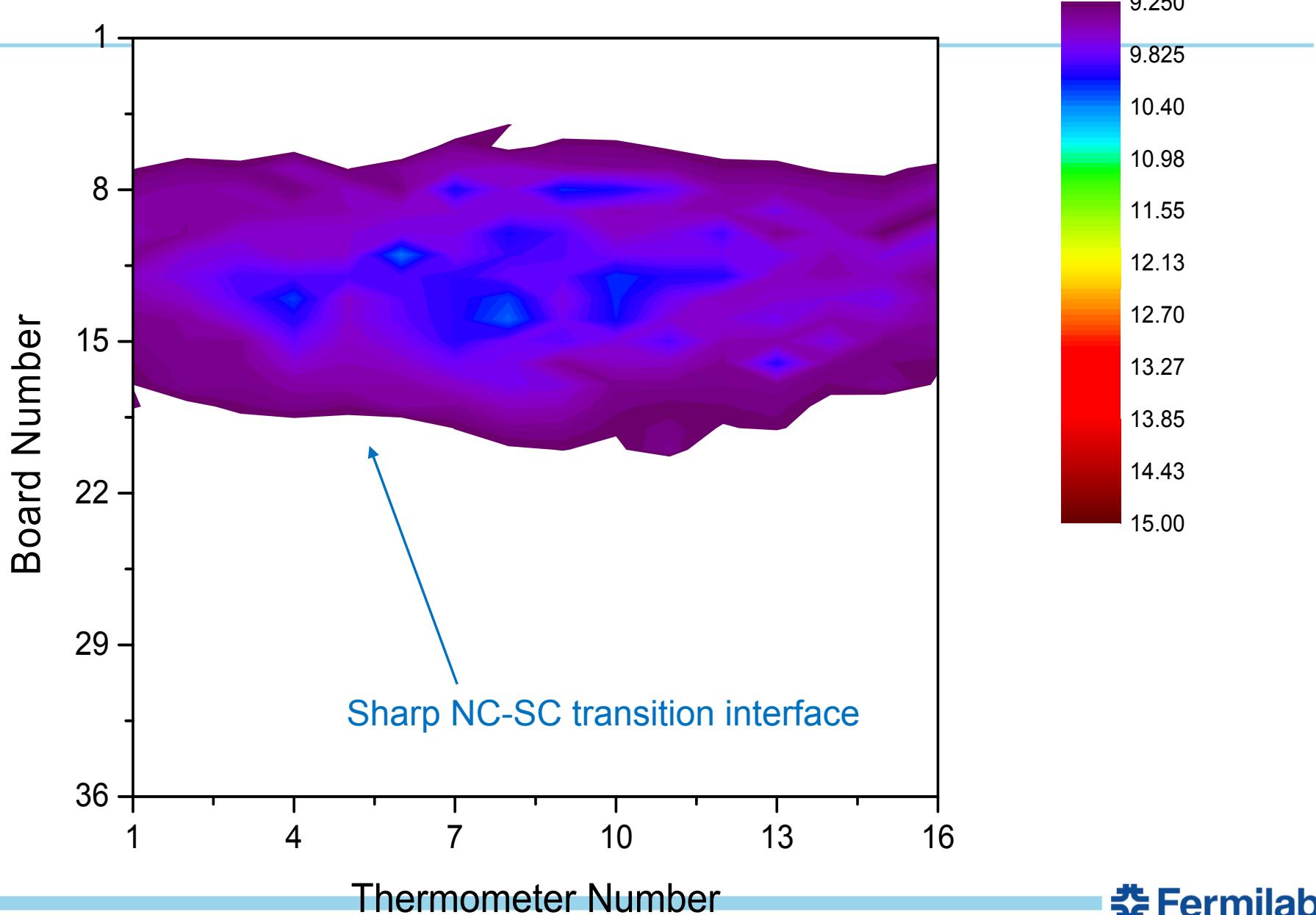
29

36

Thermometer Number



# Fast Cool-down From 250K



# Fast Cool-down From 250K

Board Number

1

8

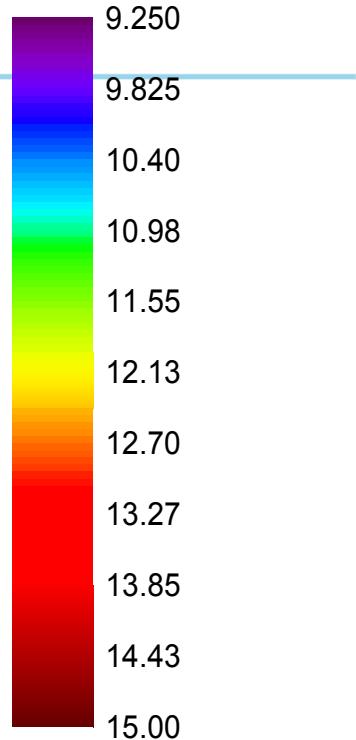
15

22

29

36

Thermometer Number



Sharp NC-SC transition interface

# Fast Cool-down From 250K

Board Number

1

8

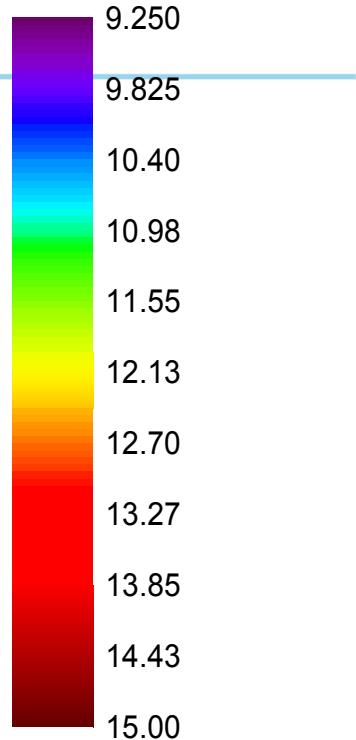
15

22

29

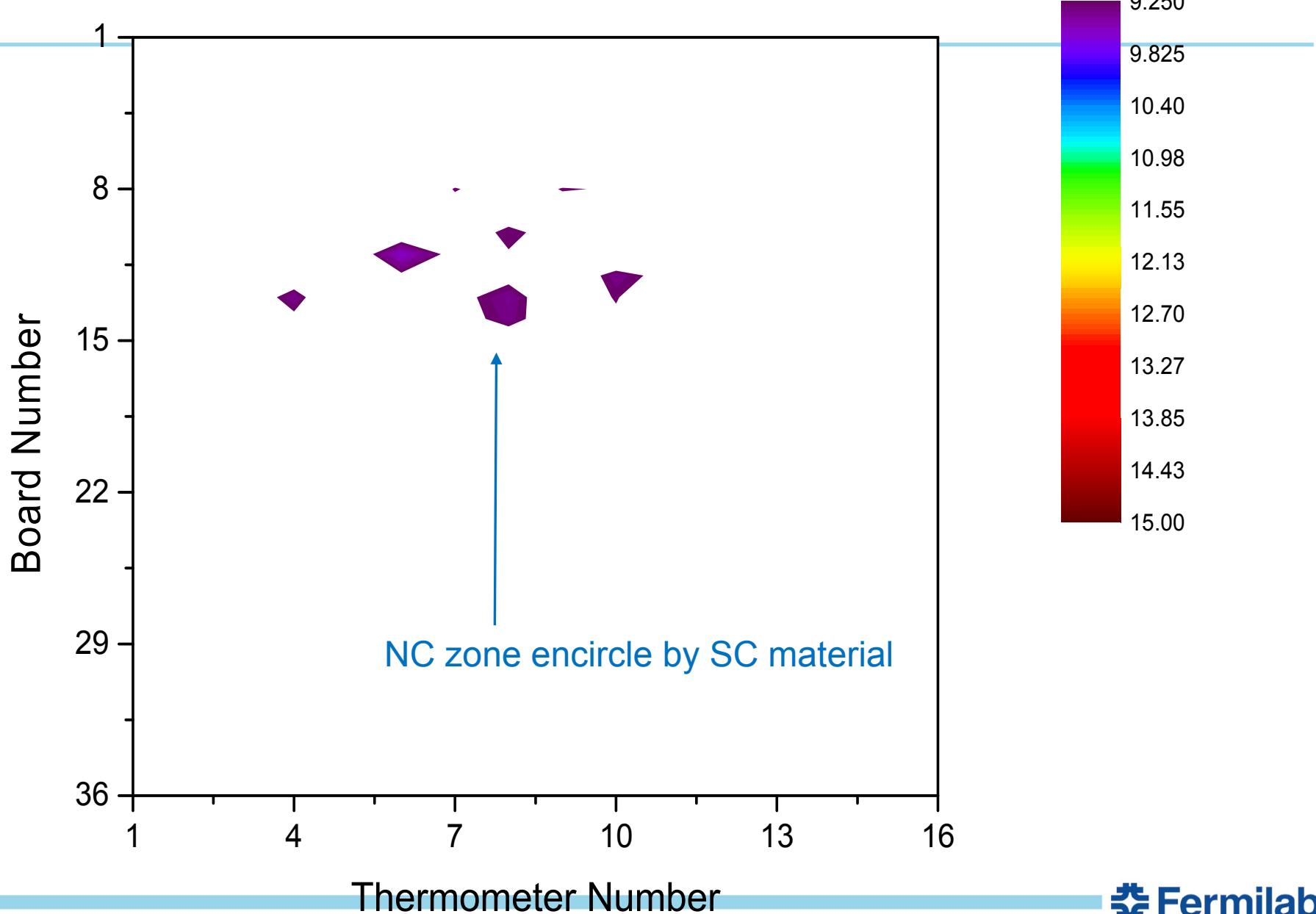
36

Thermometer Number



NC zones encircle by SC material

# Fast Cool-down From 250K



# Fast Cool-down From 250K

Board Number

1

8

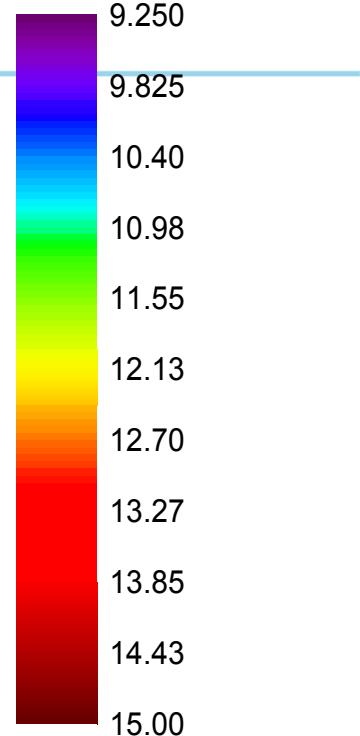
15

22

29

36

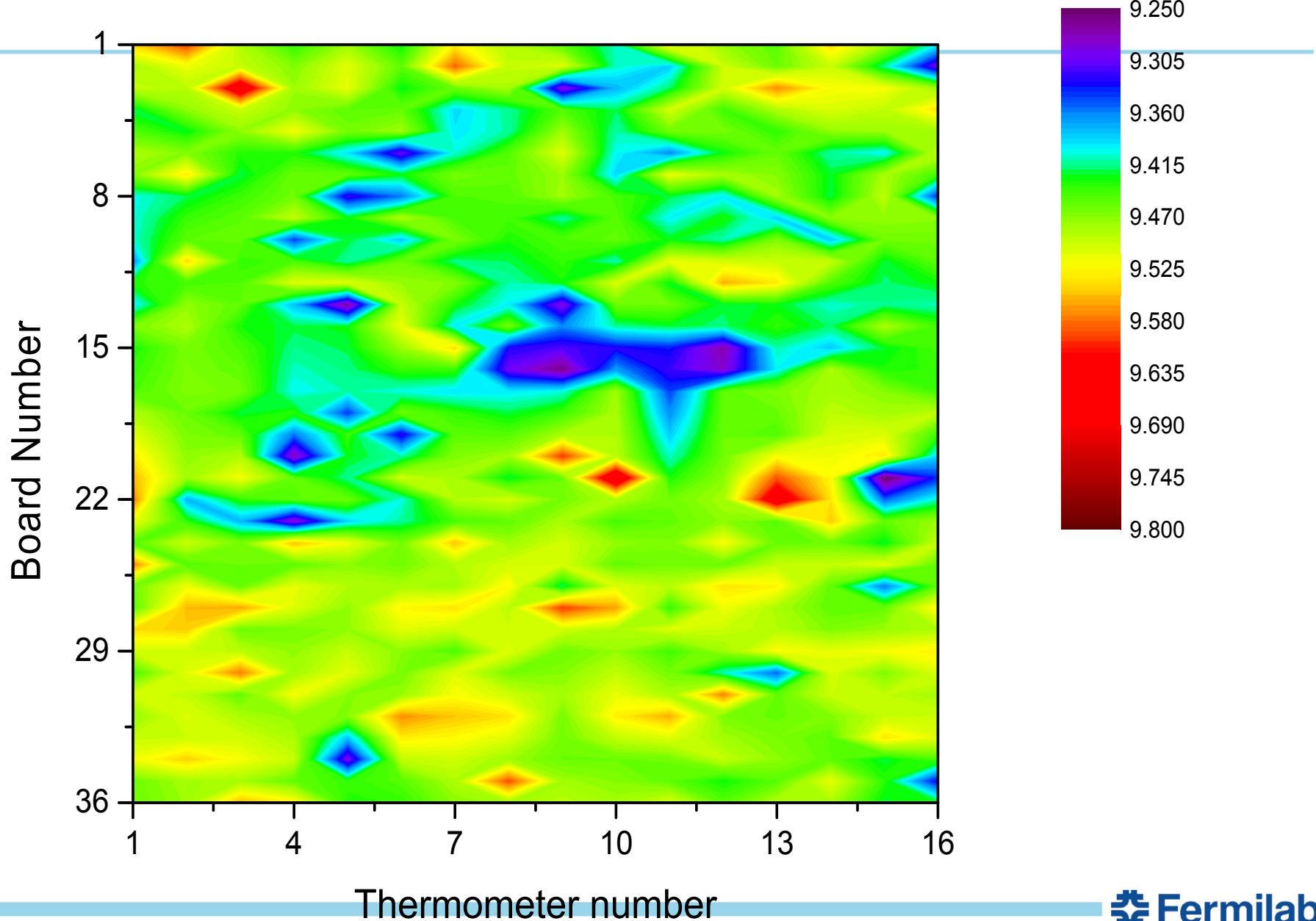
Thermometer Number



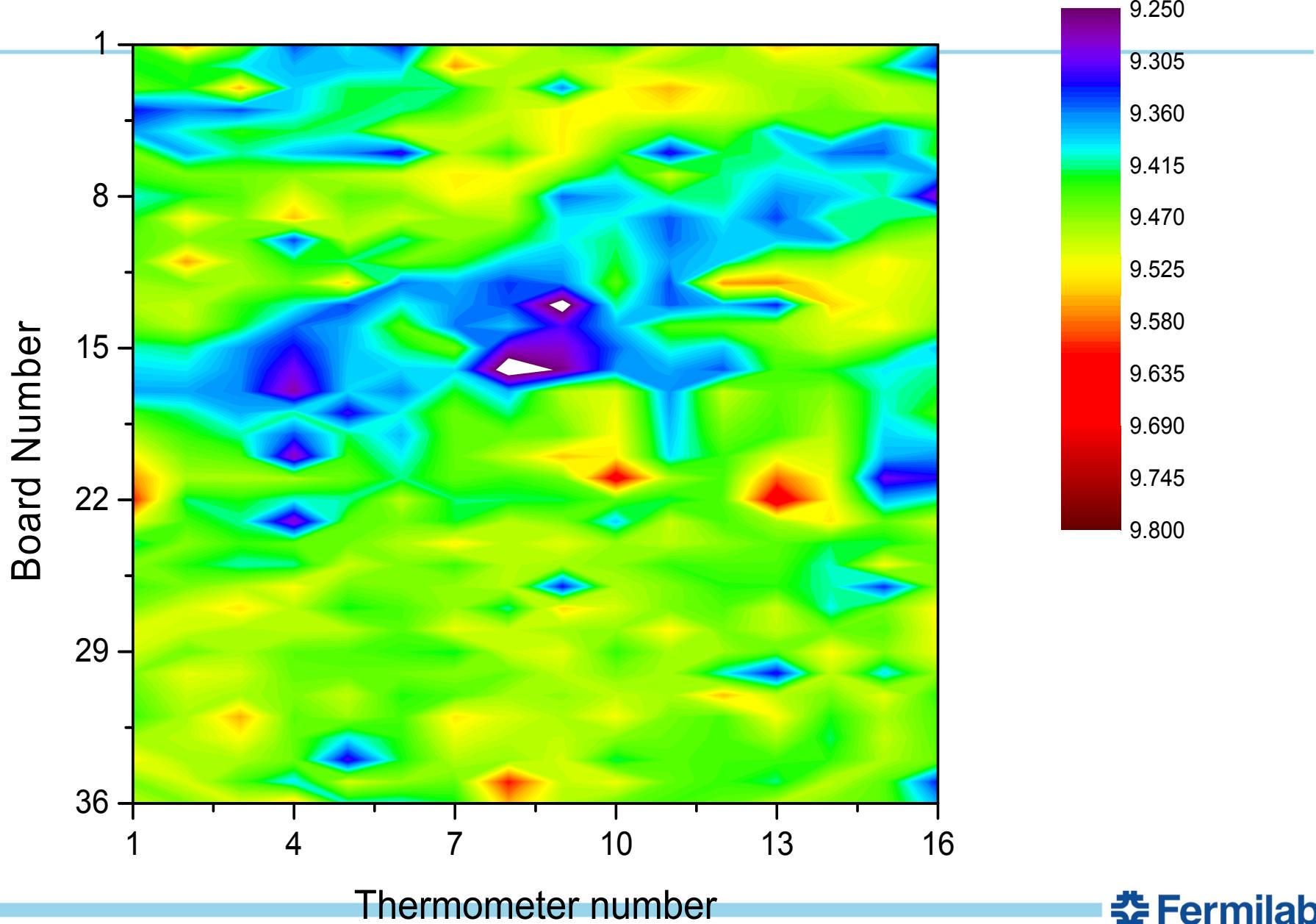
# Slow Cool-down T-map

Starting T: 12K

# Slow Cool-down From 12K

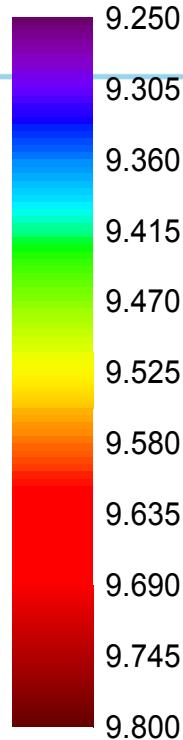
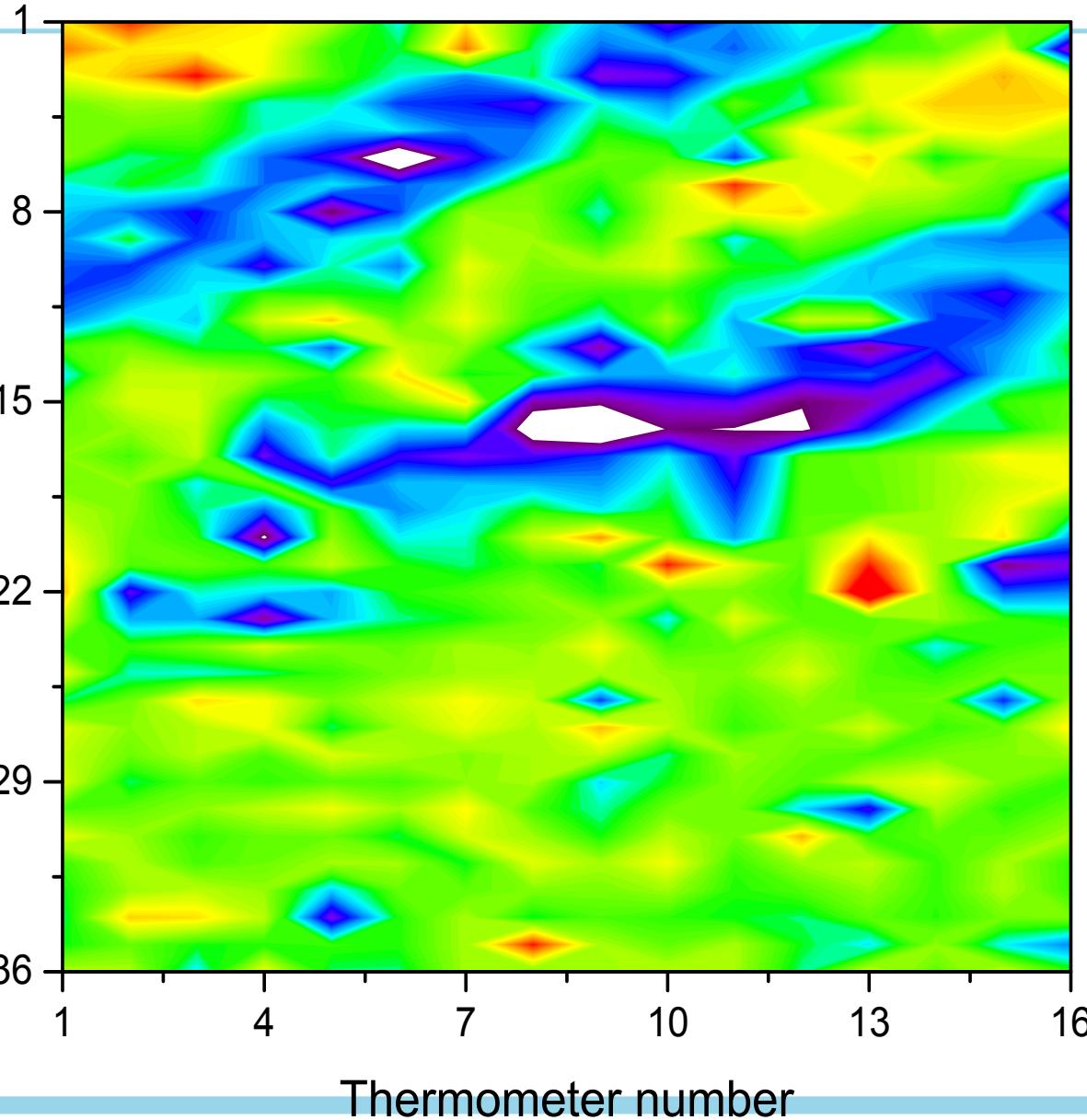


# Slow Cool-down From 12K



# Slow Cool-down From 12K

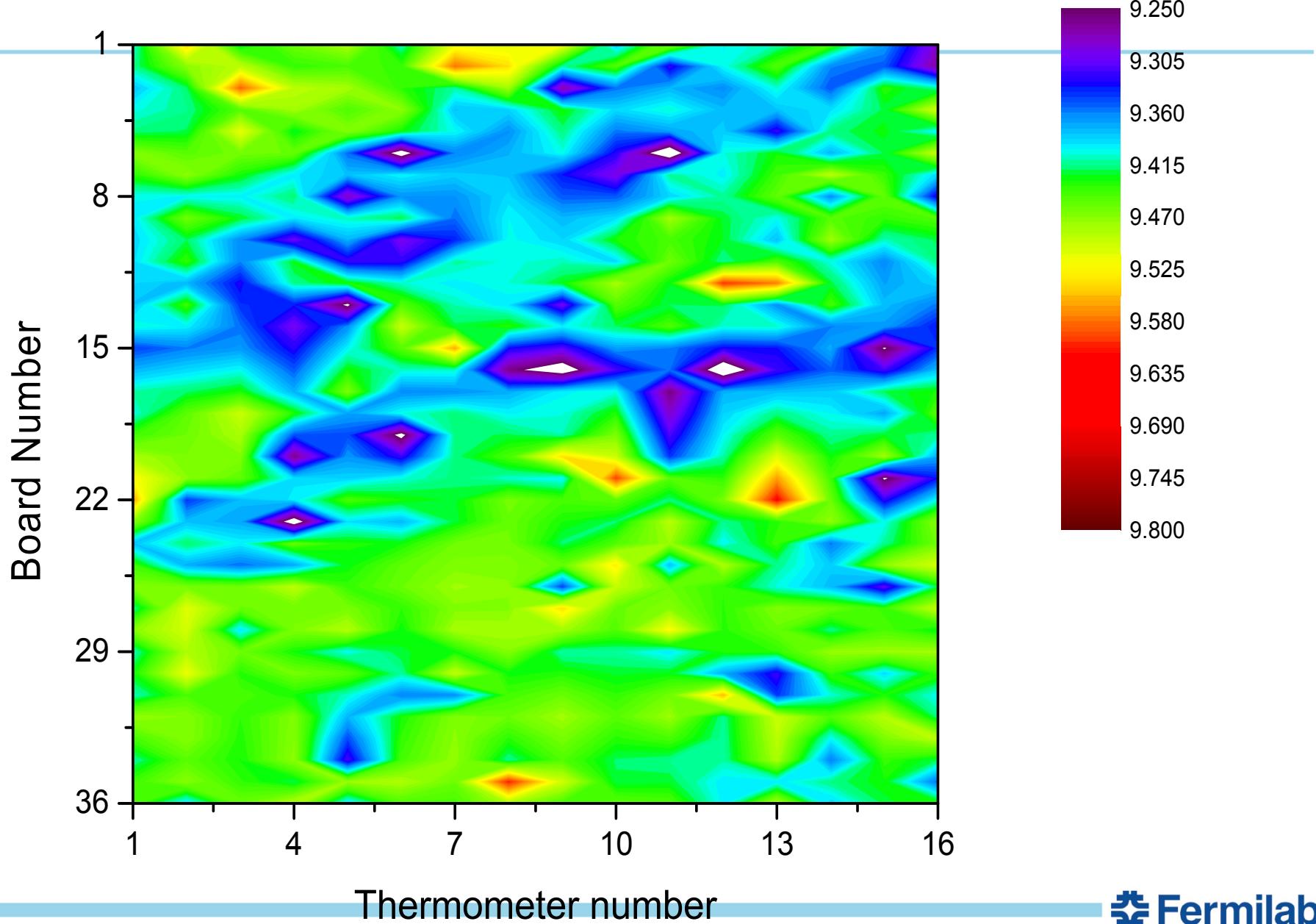
Board Number



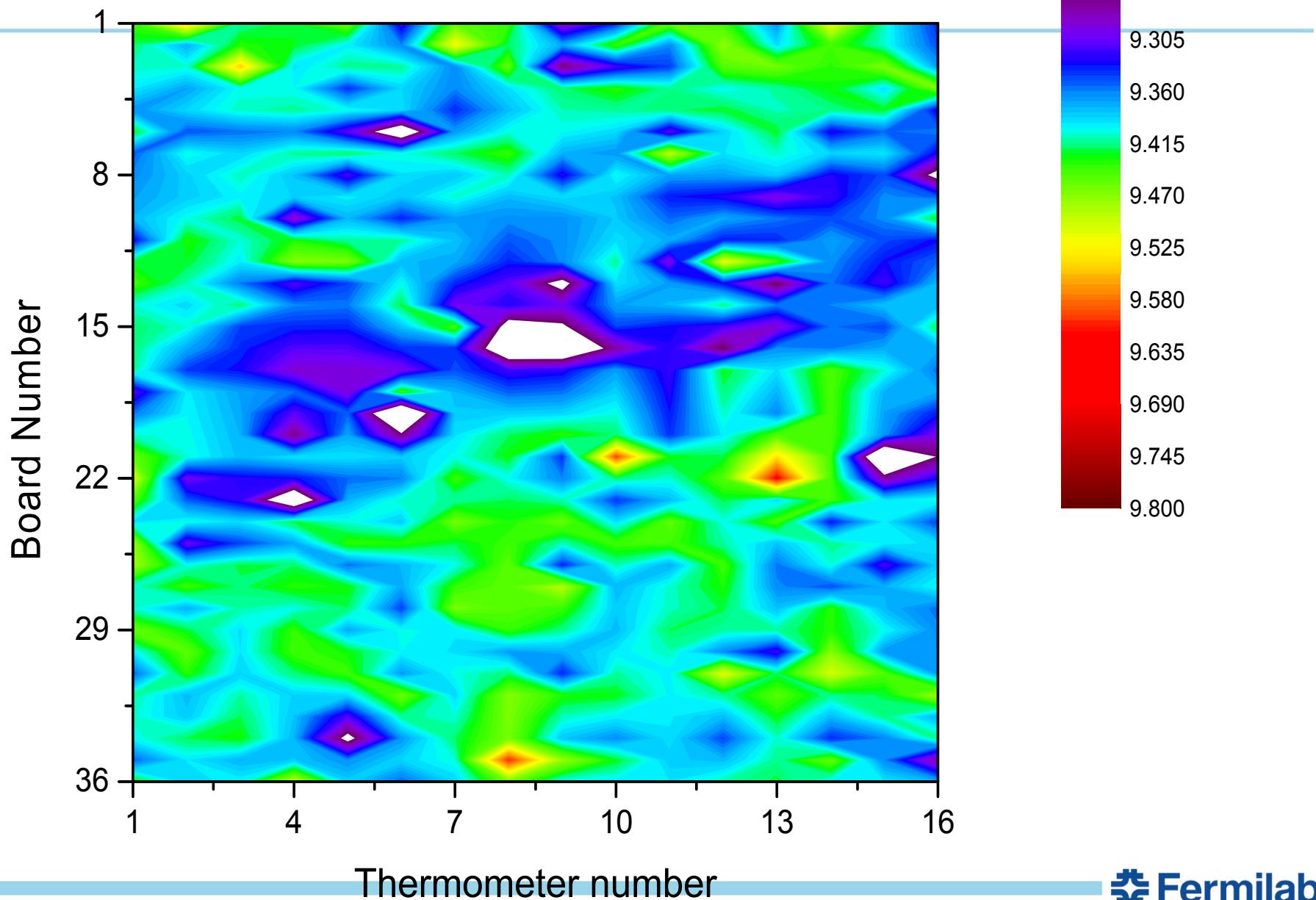
Thermometer number

Fermilab

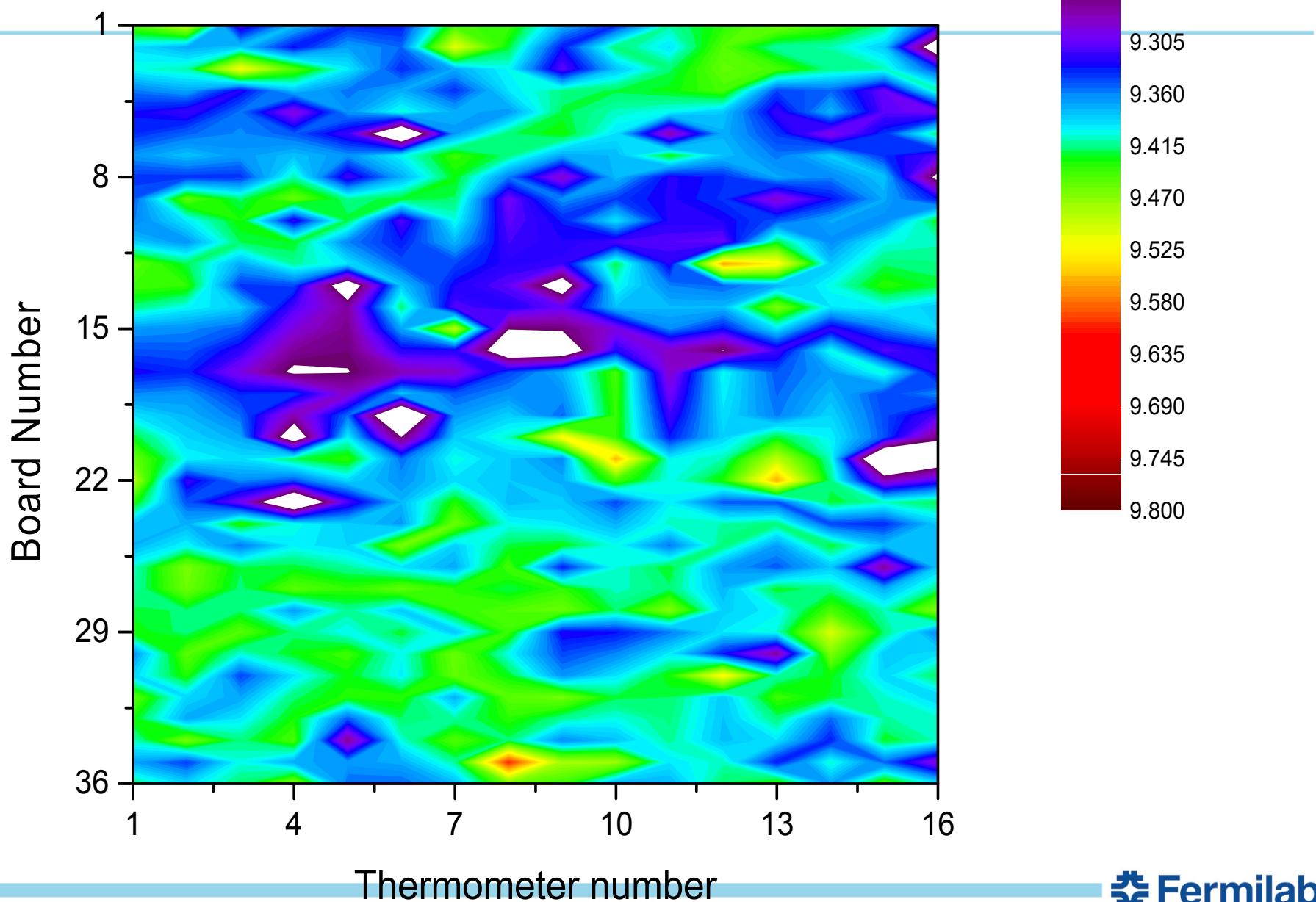
# Slow Cool-down From 12K



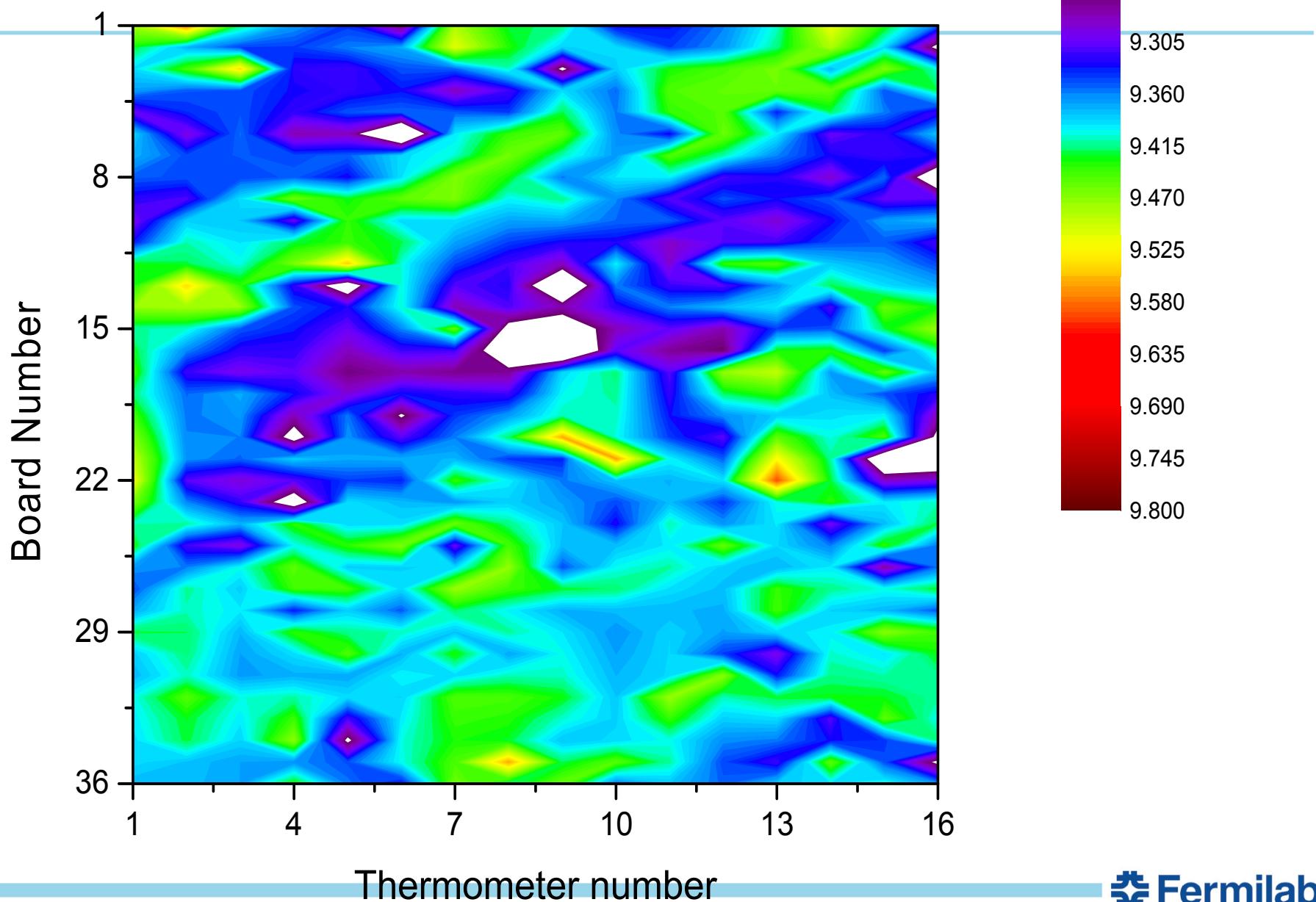
# Slow Cool-down From 12K



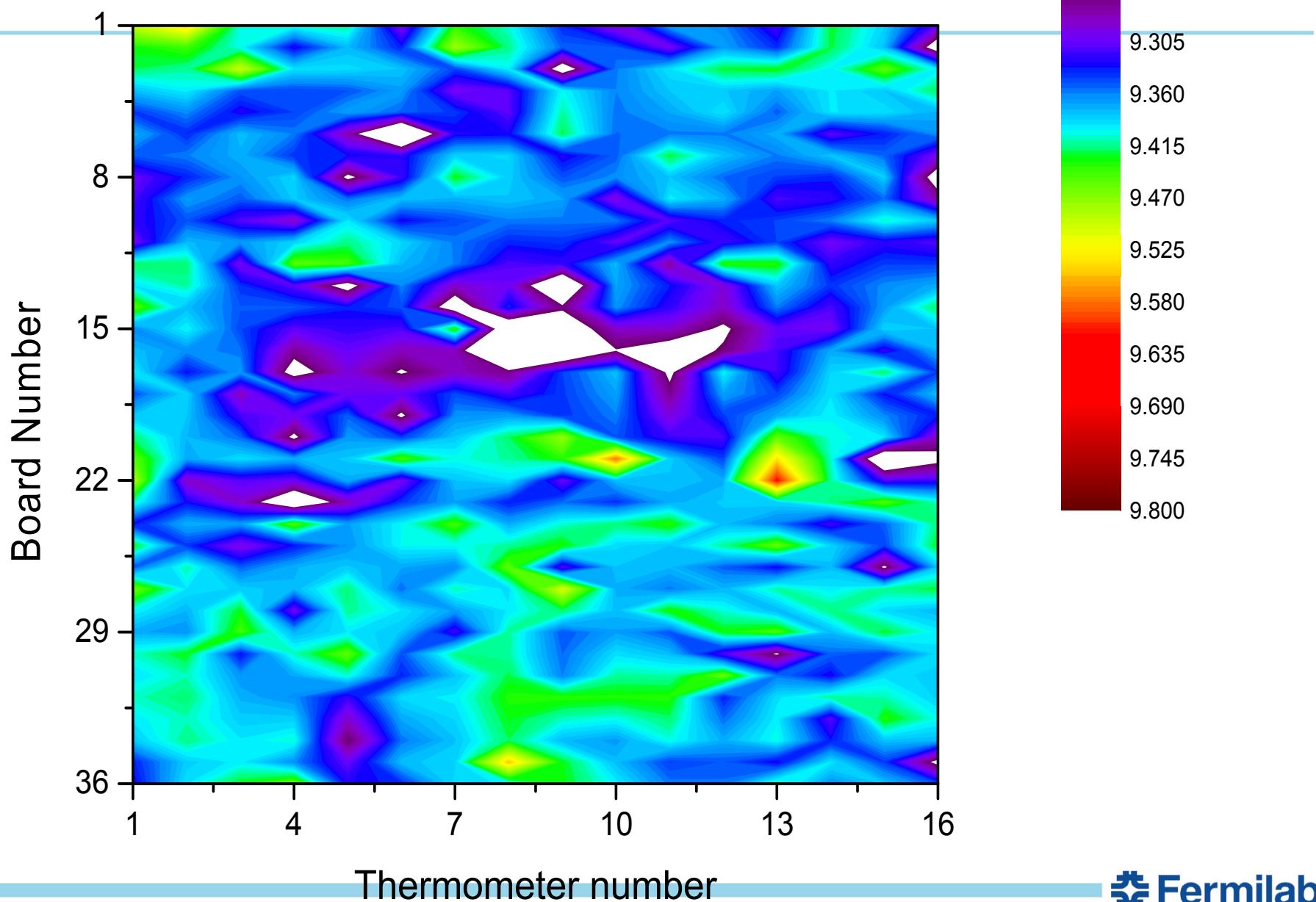
# Slow Cool-down From 12K



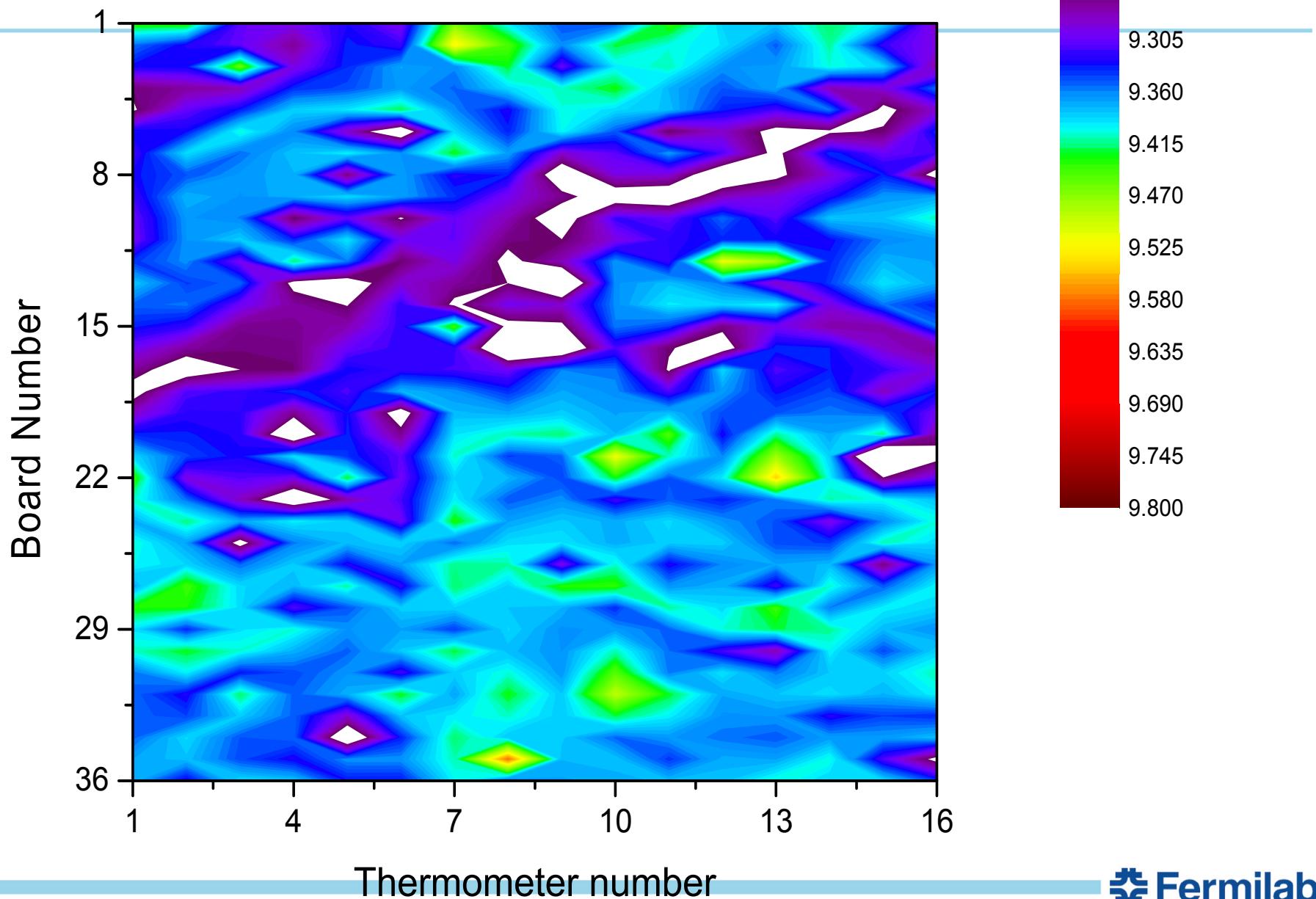
# Slow Cool-down From 12K



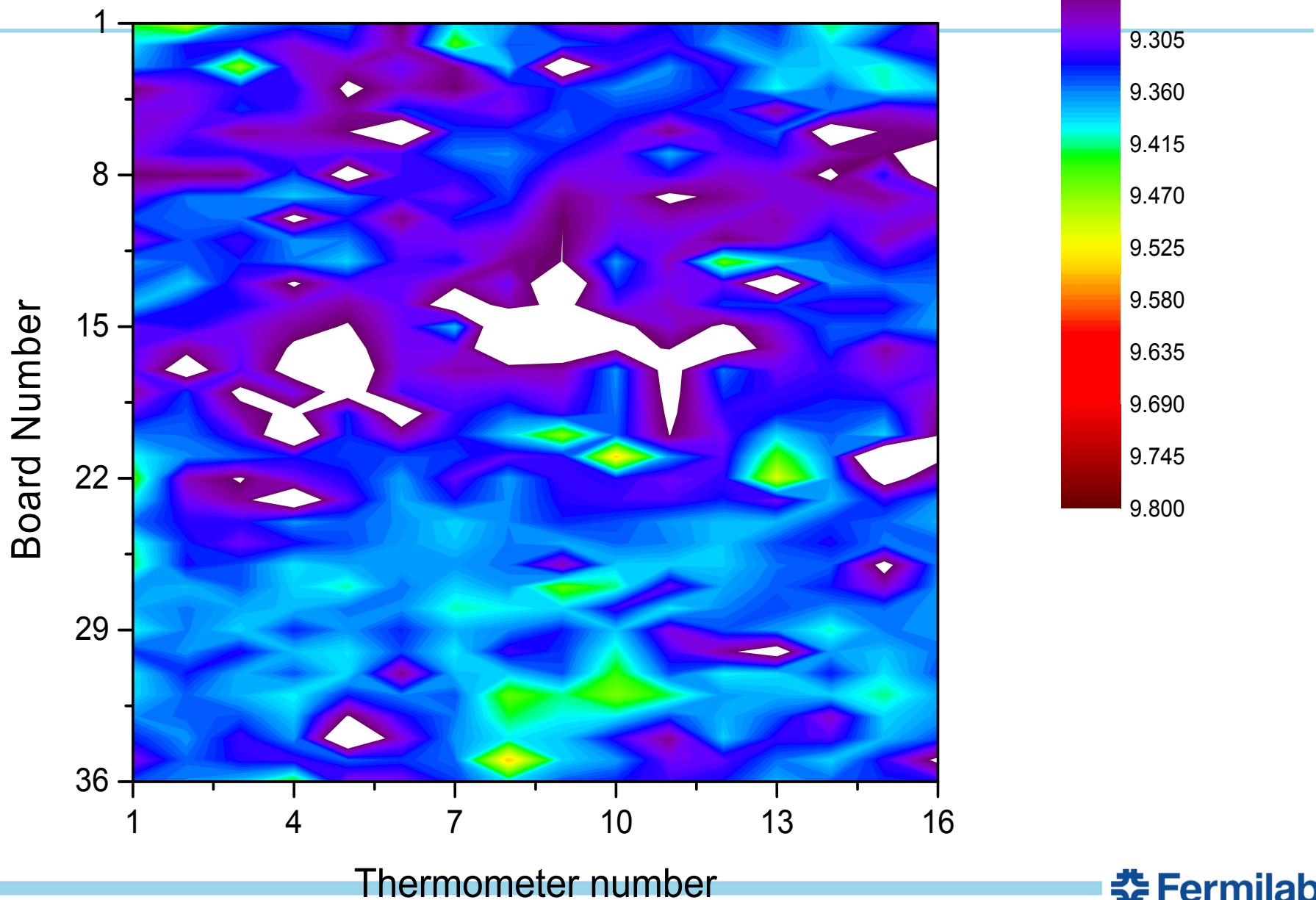
# Slow Cool-down From 12K



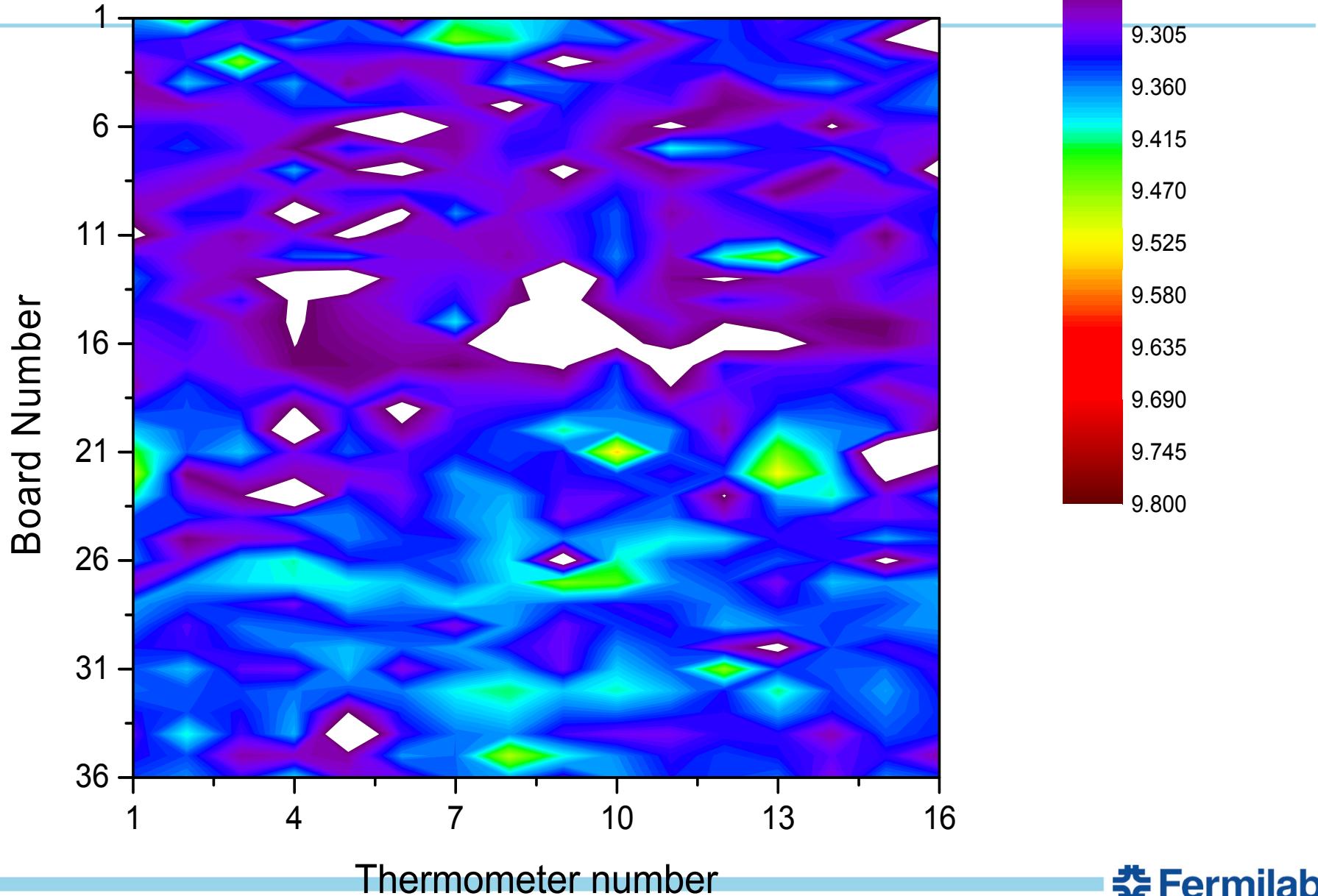
# Slow Cool-down From 12K



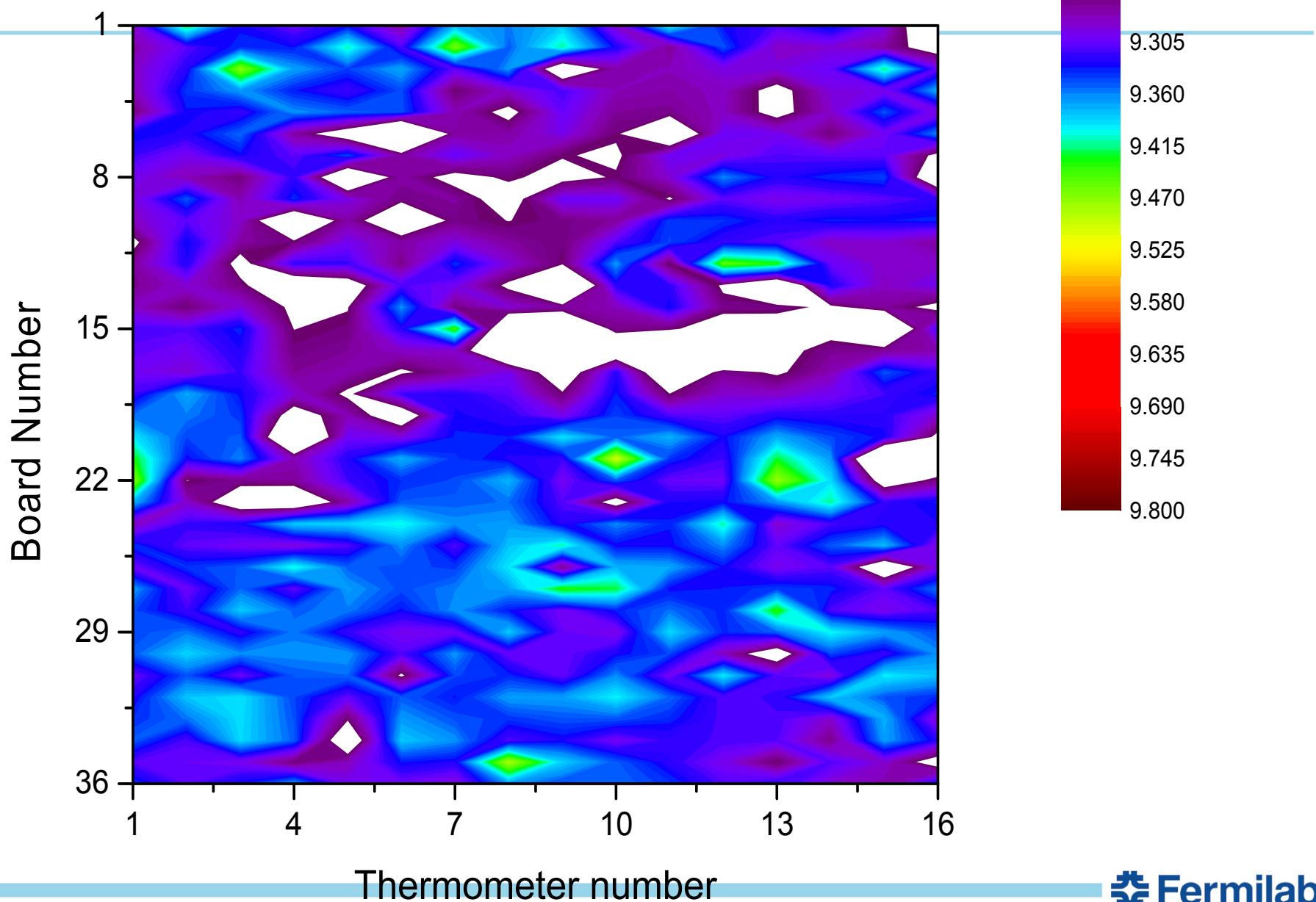
# Slow Cool-down From 12K



# Slow Cool-down From 12K

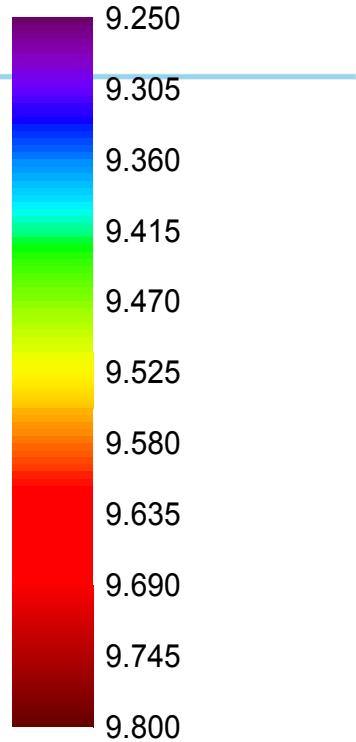
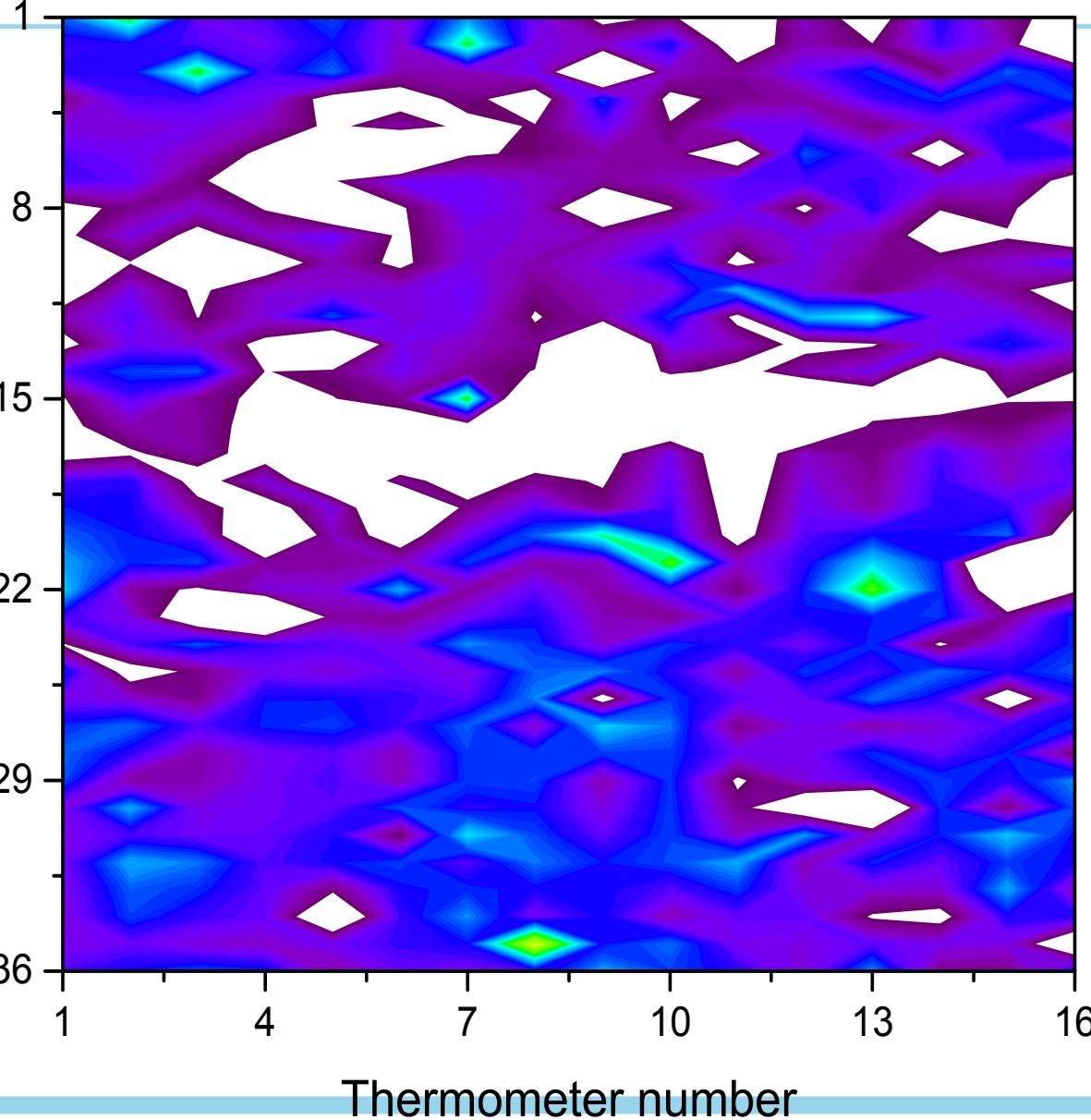


# Slow Cool-down From 12K



# Slow Cool-down From 12K

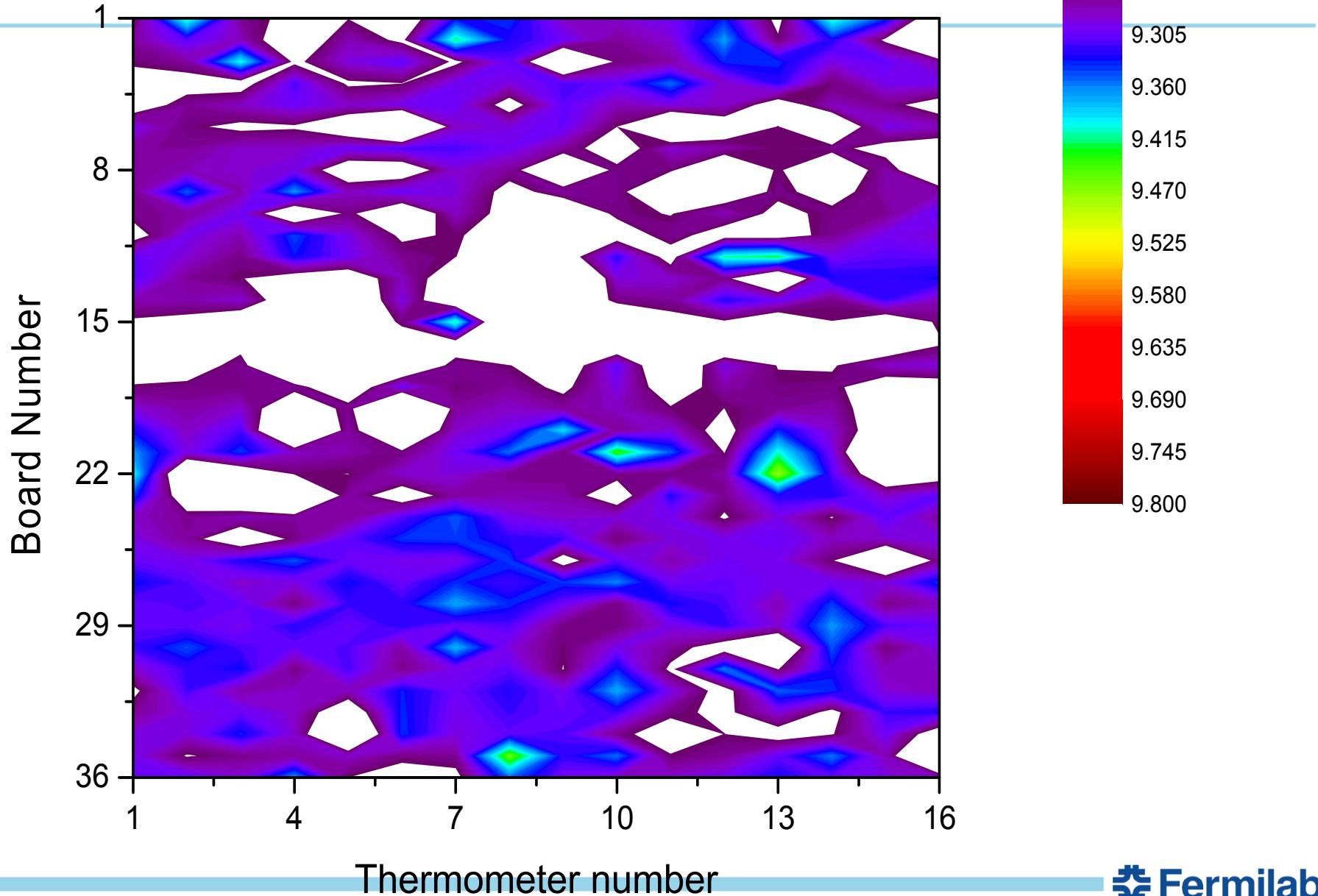
Board Number



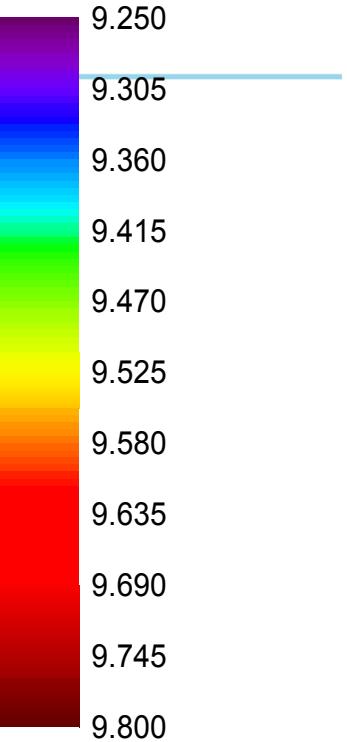
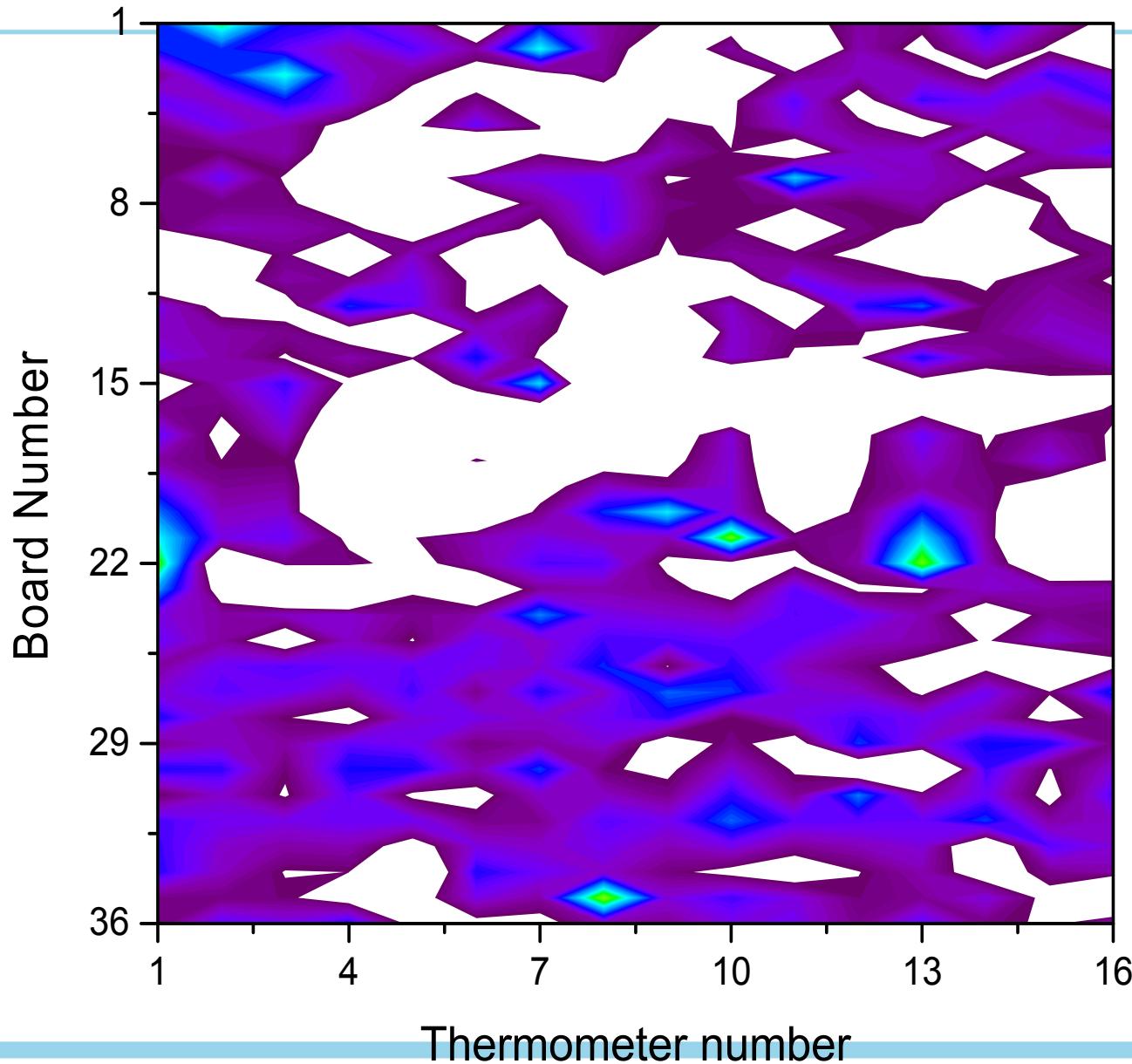
Thermometer number

Fermilab

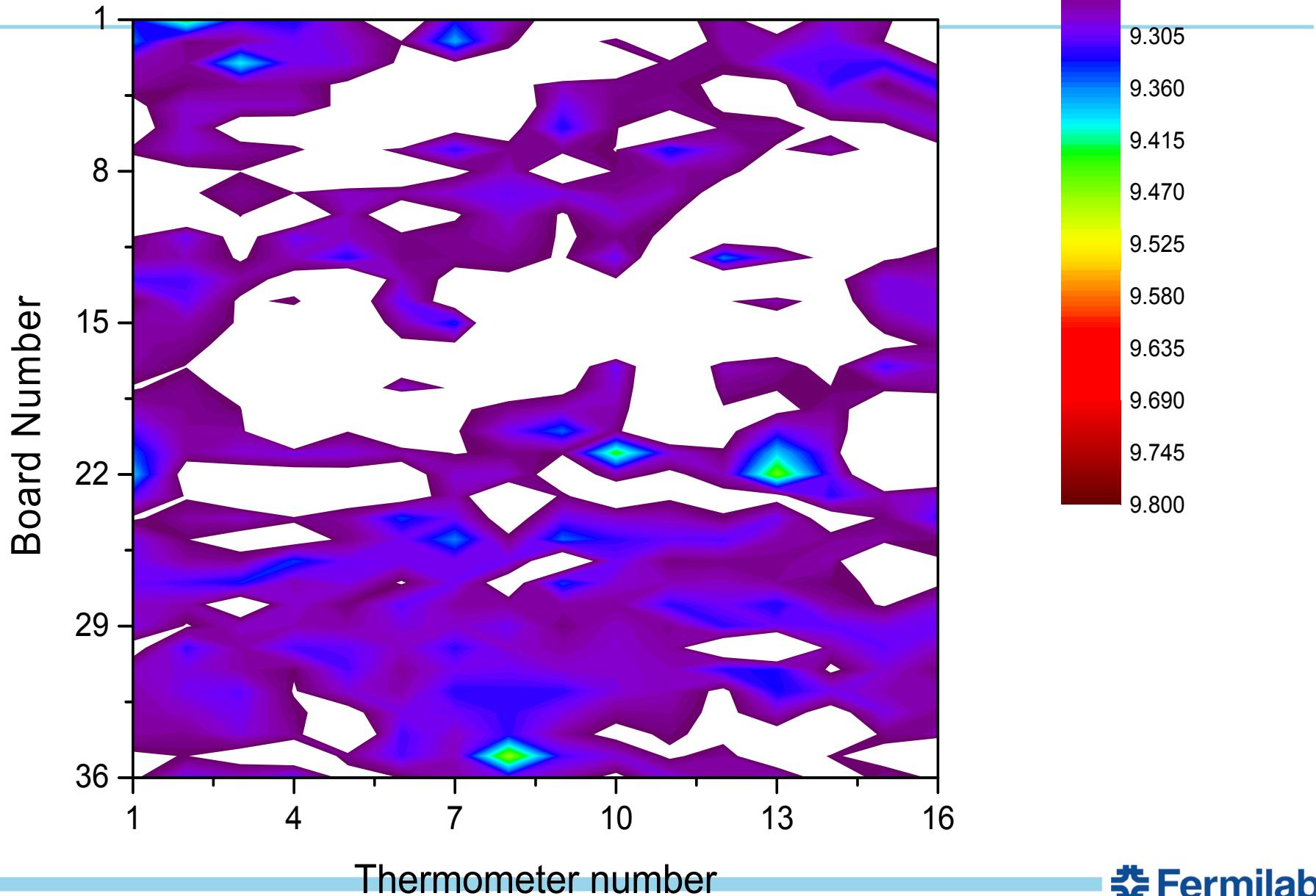
# Slow Cool-down From 12K



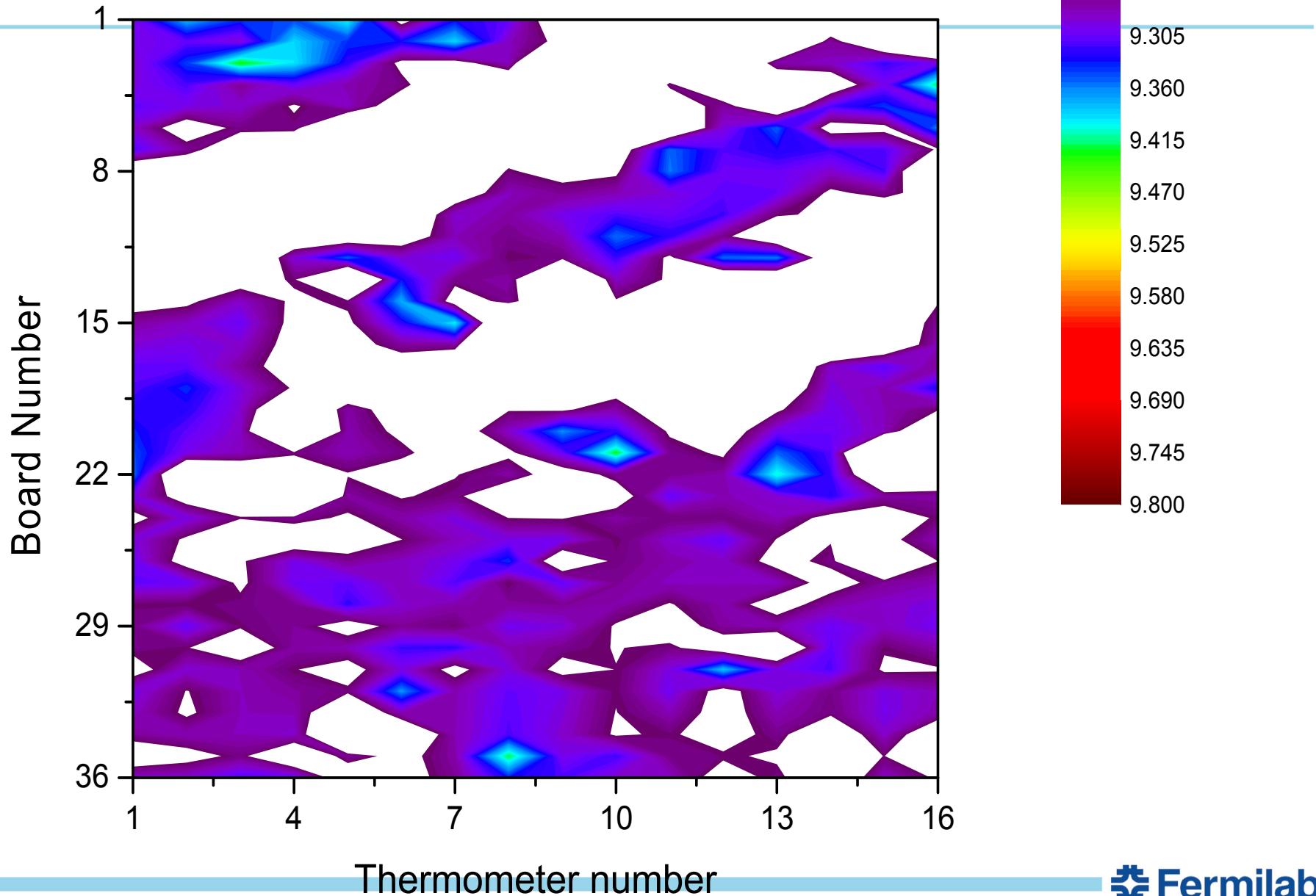
# Slow Cool-down From 12K



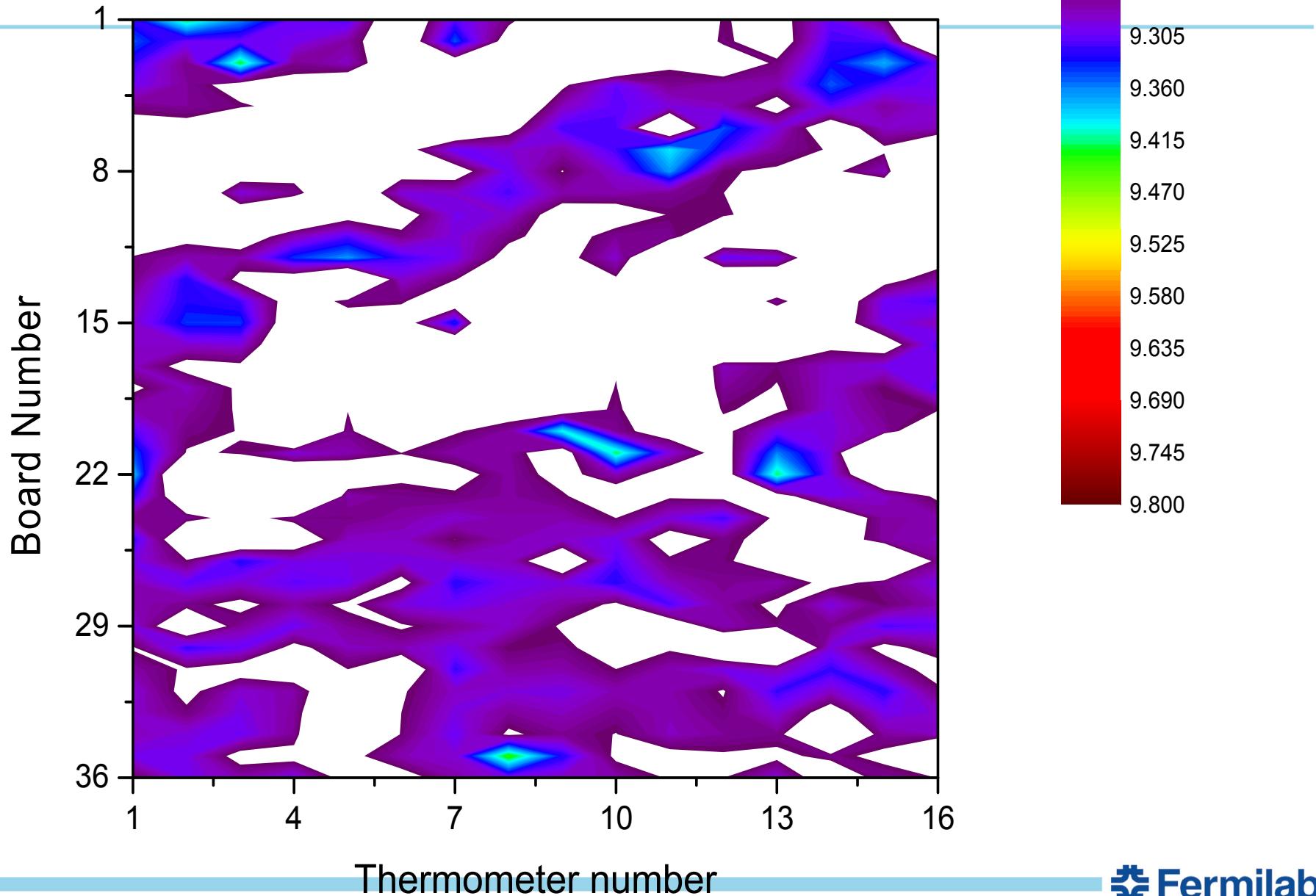
# Slow Cool-down From 12K



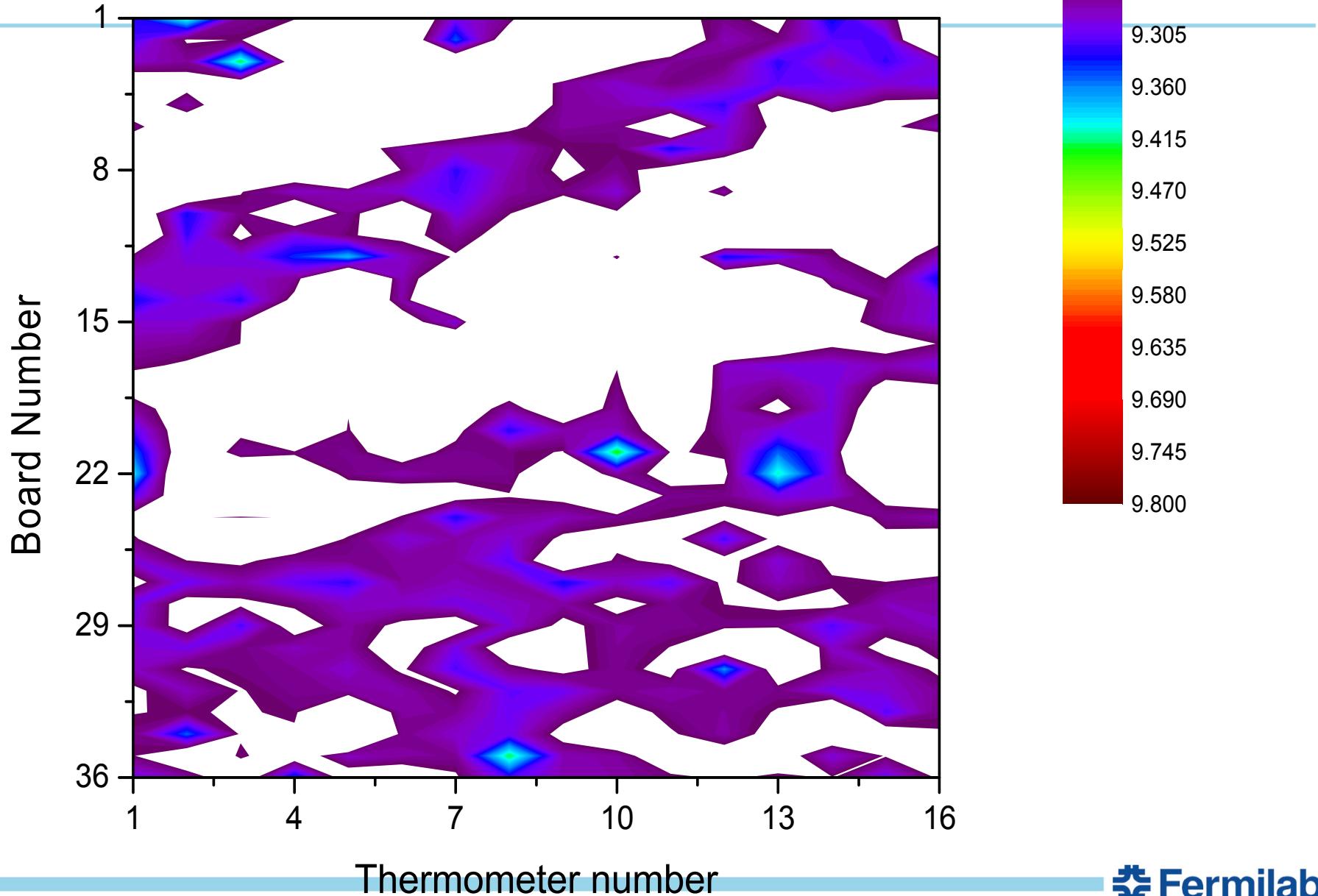
# Slow Cool-down From 12K



# Slow Cool-down From 12K



# Slow Cool-down From 12K



# Slow Cool-down From 12K

Board Number

1

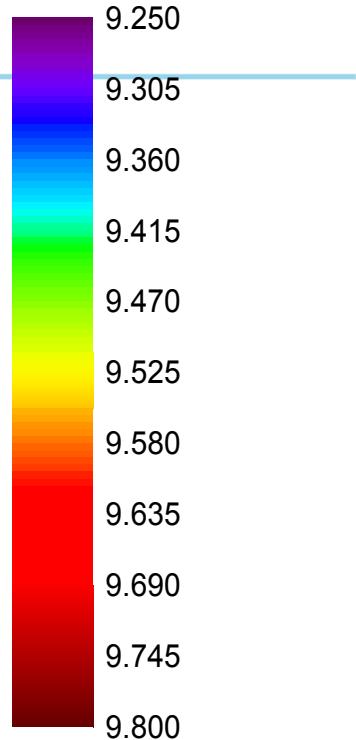
8

15

22

29

36



1

4

7

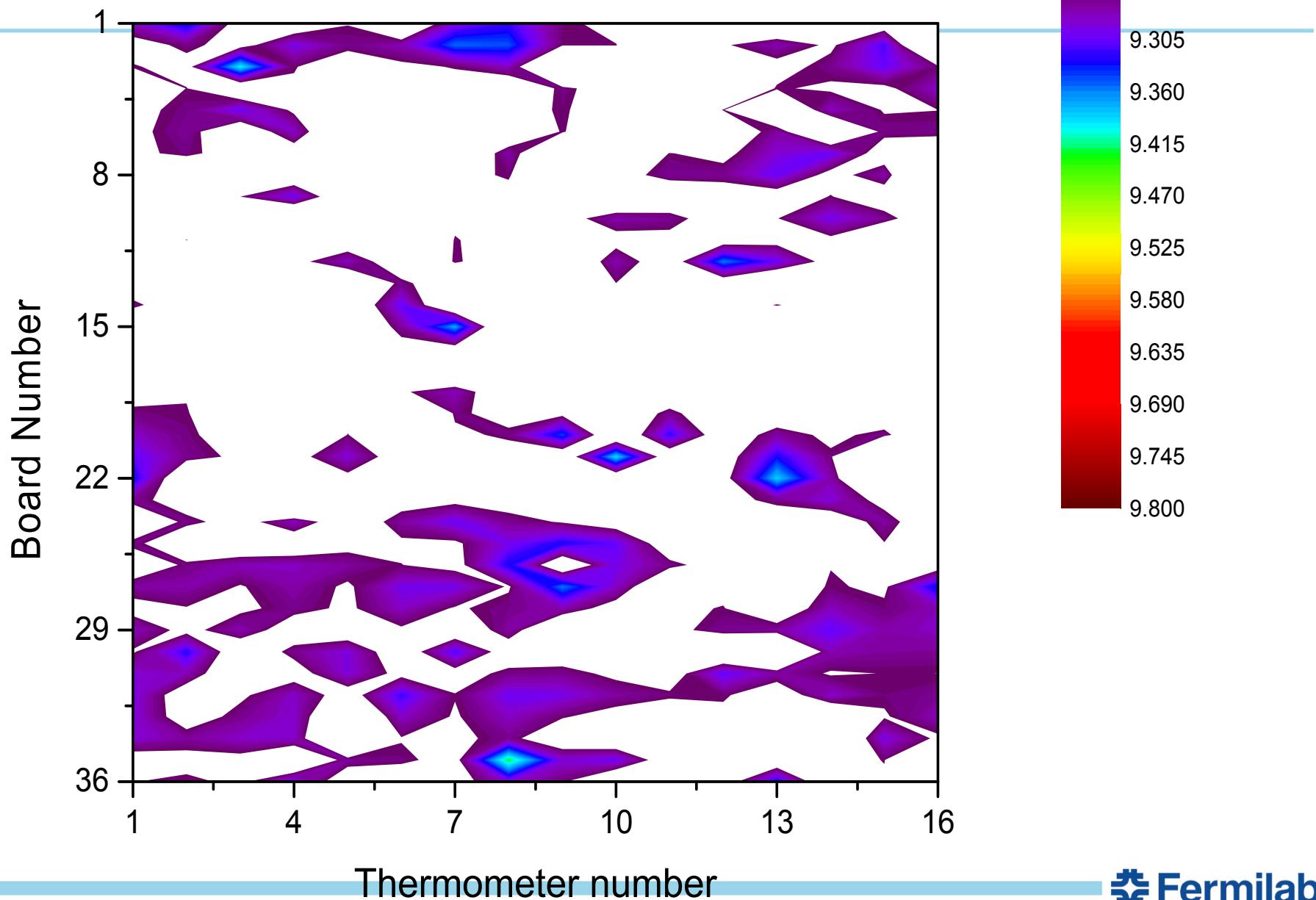
10

13

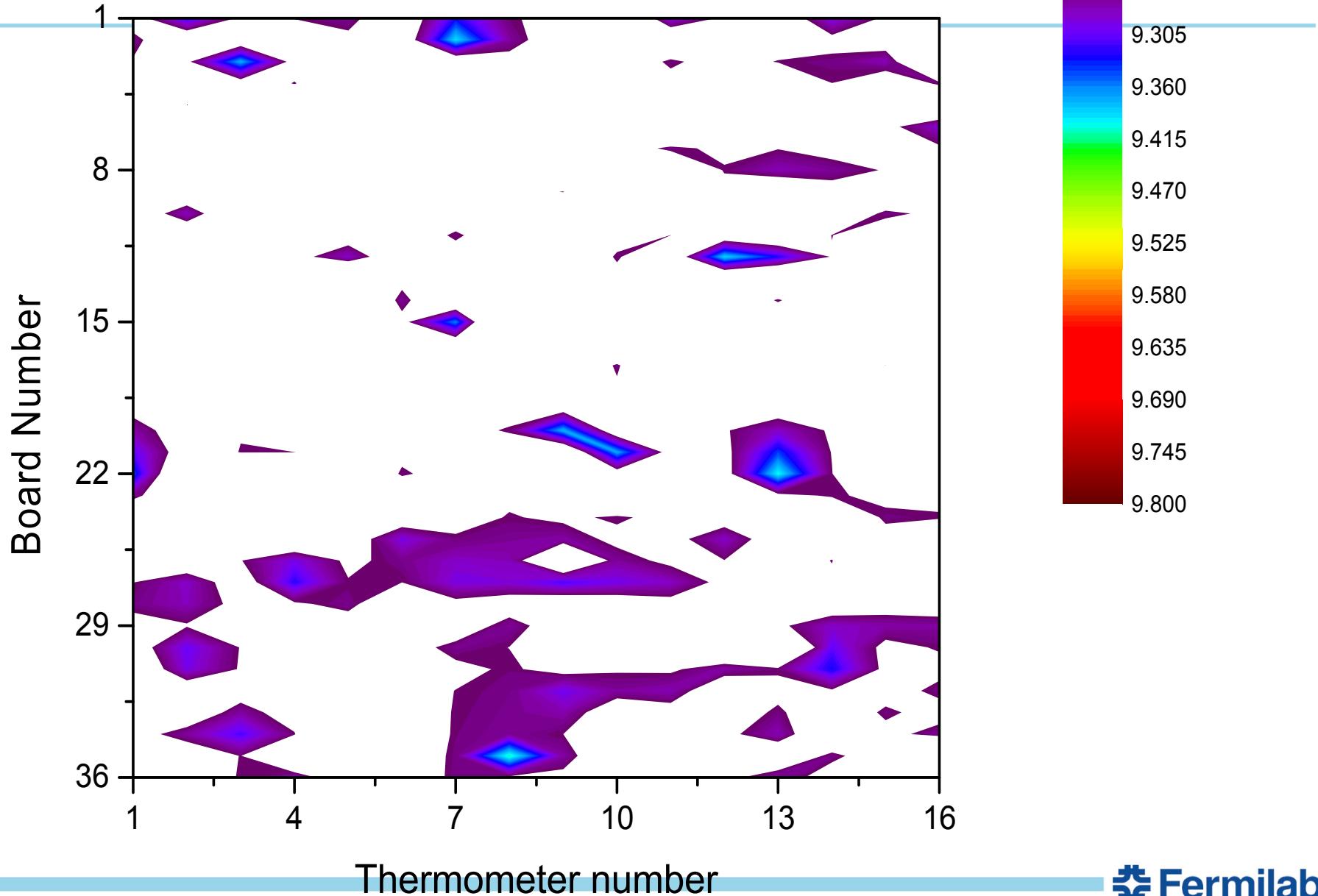
16

Thermometer number

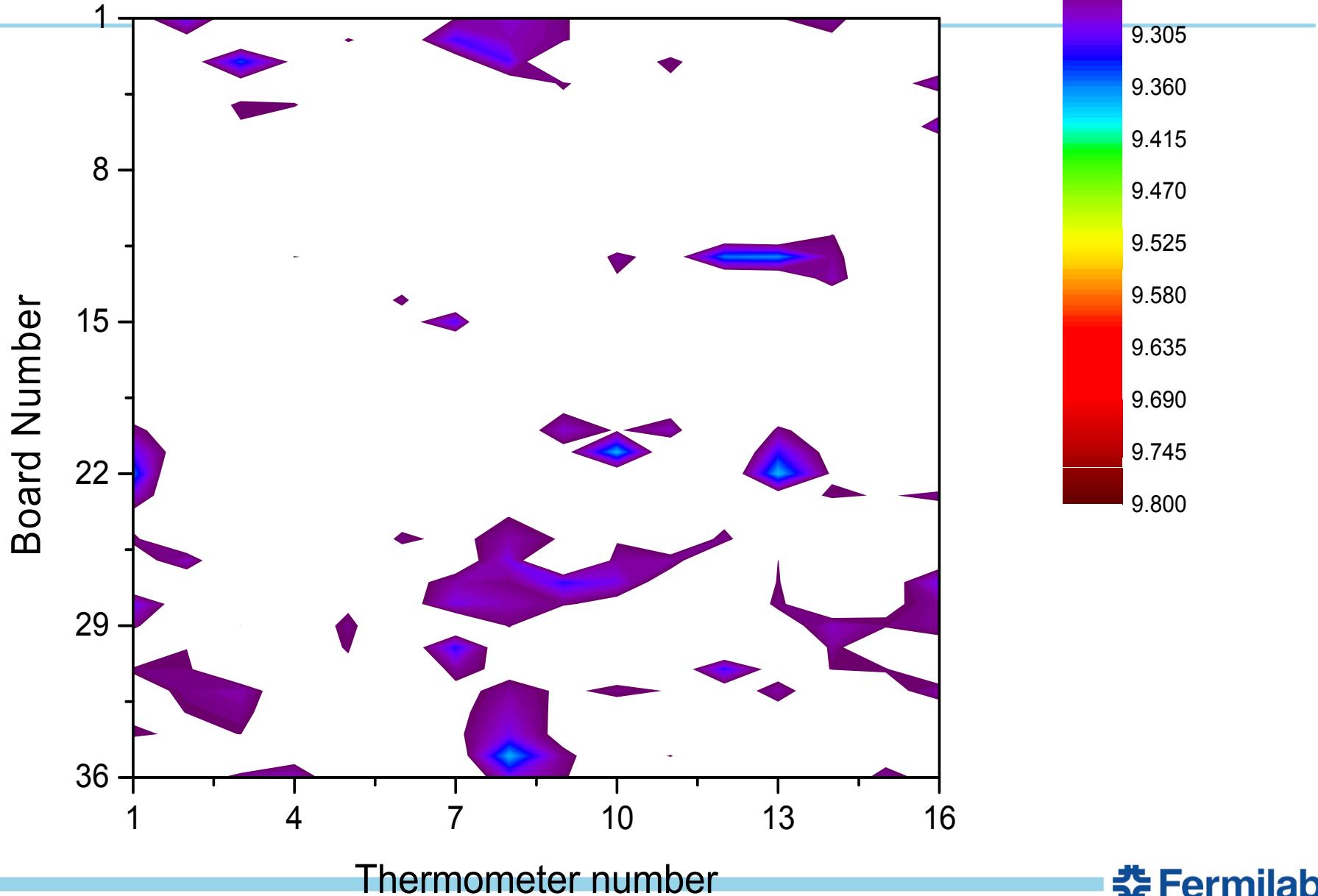
# Slow Cool-down From 12K



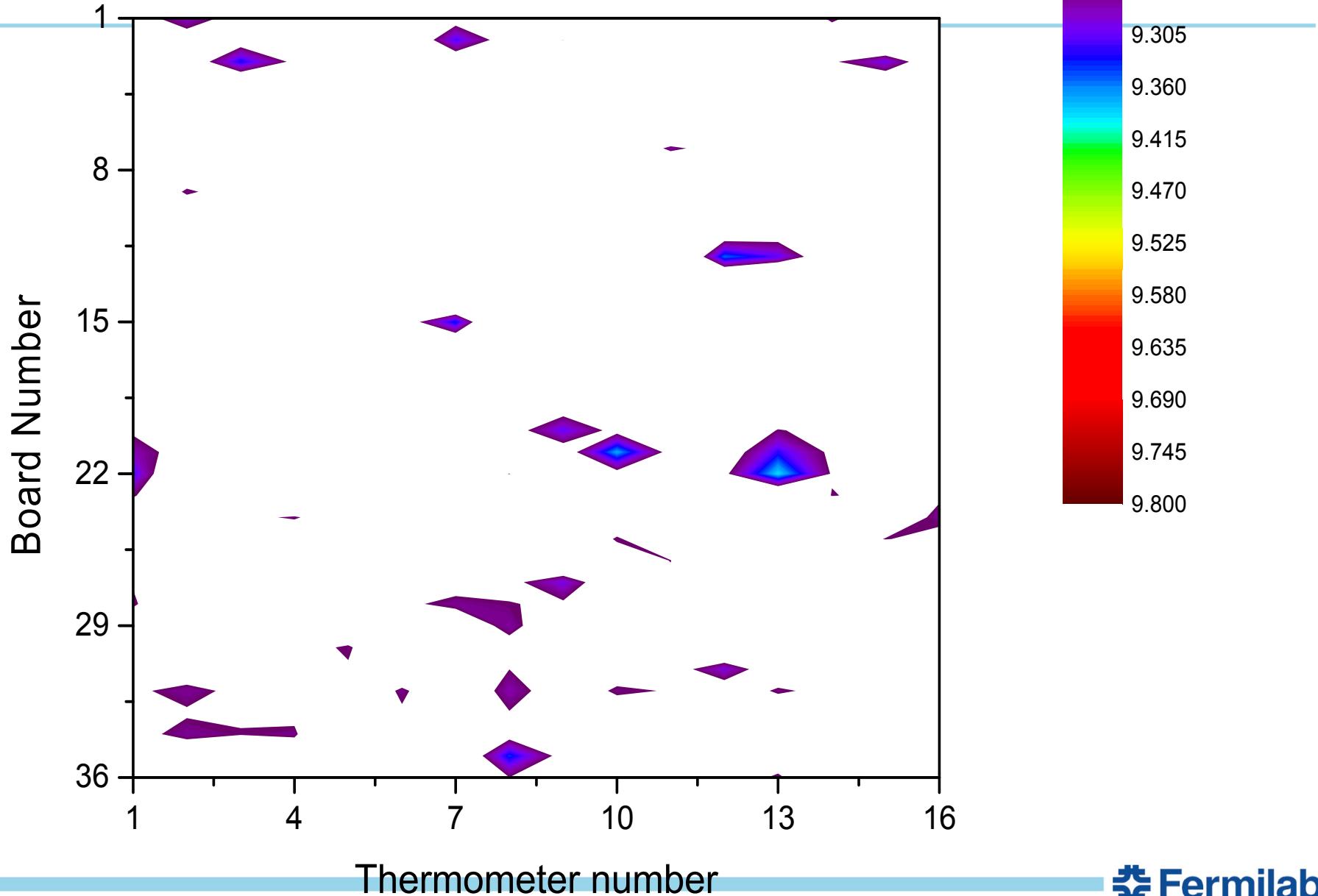
# Slow Cool-down From 12K



# Slow Cool-down From 12K



# Slow Cool-down From 12K



# Slow Cool-down From 12K

Board Number

1

8

15

22

29

36

1

4

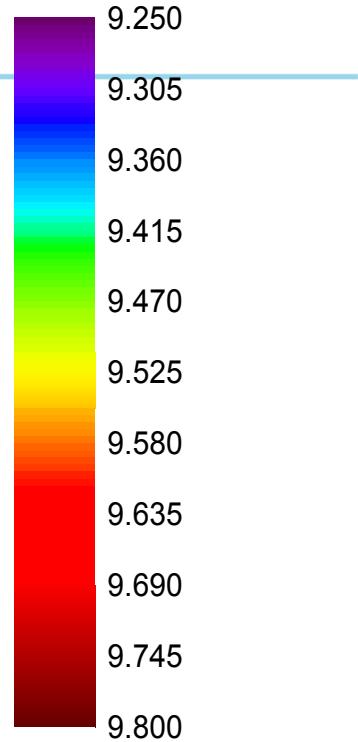
7

10

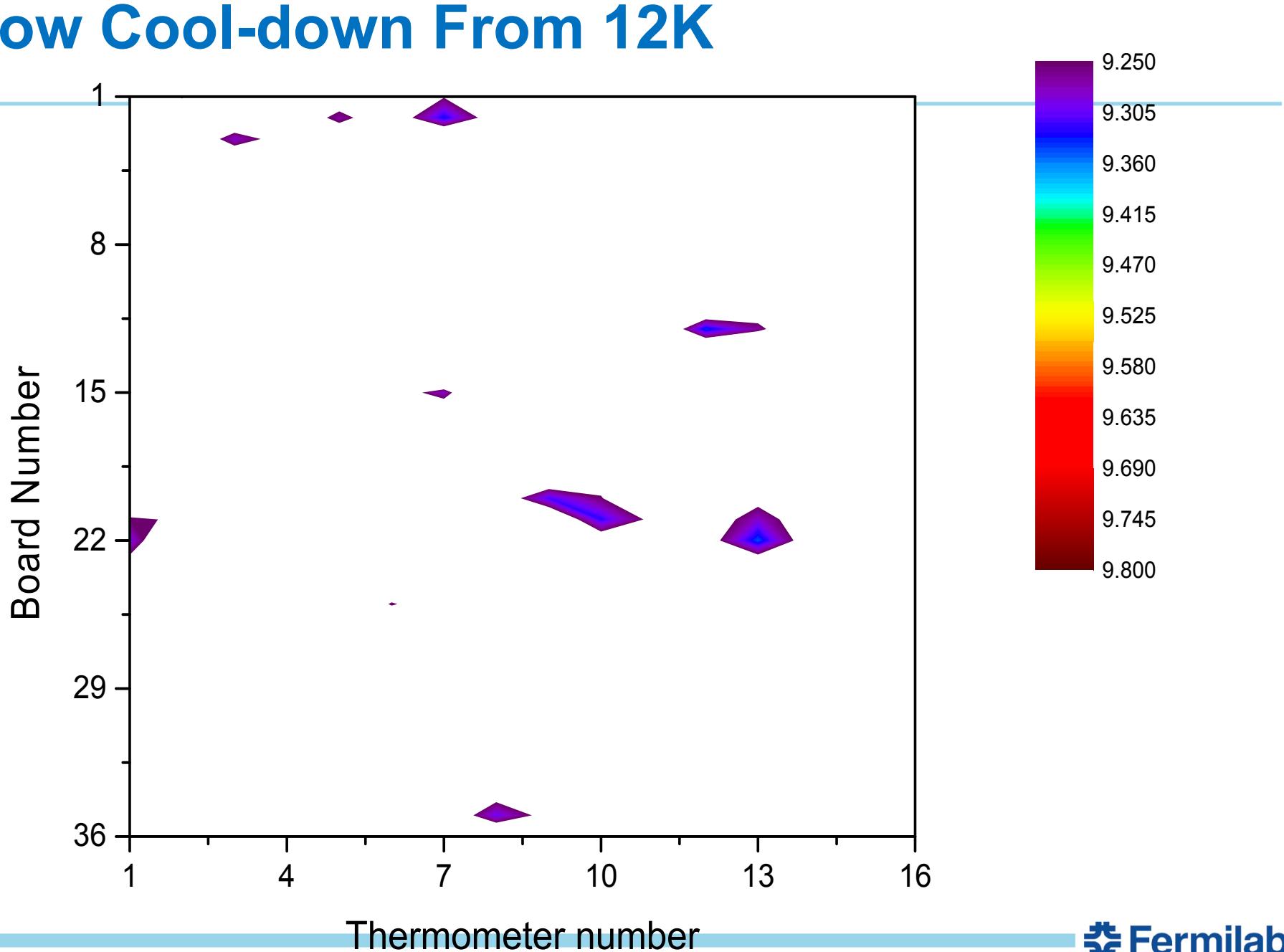
13

16

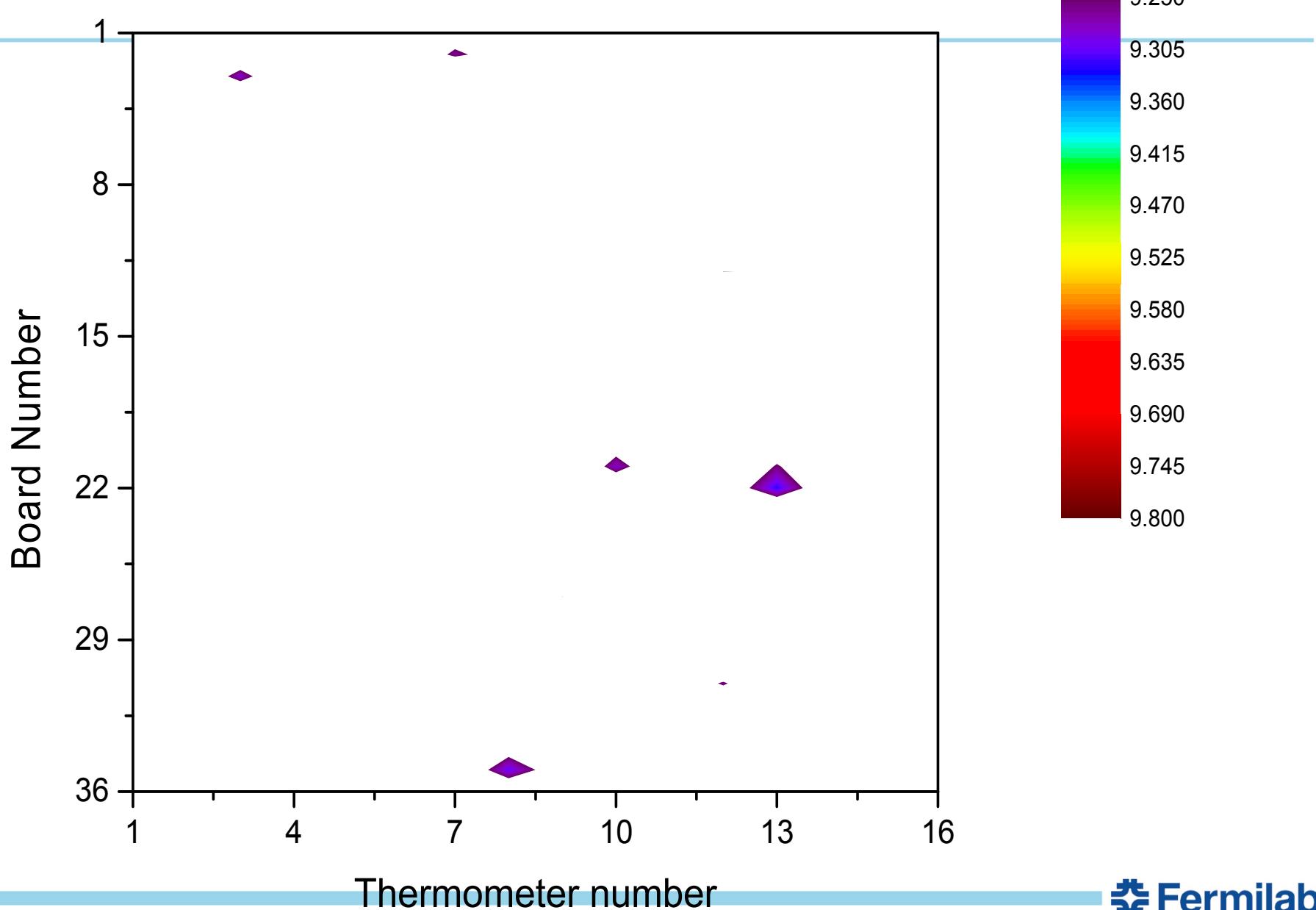
Thermometer number



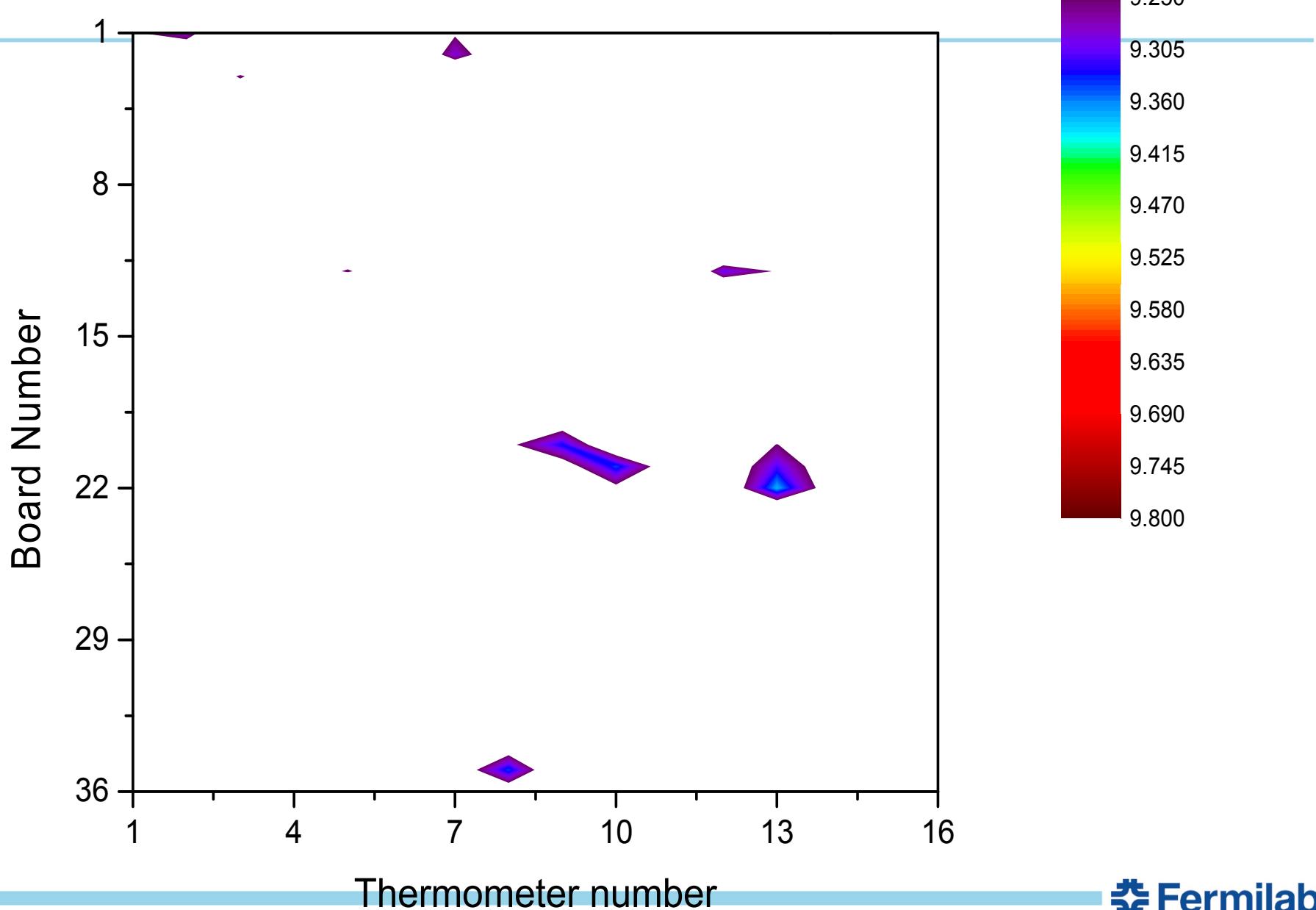
# Slow Cool-down From 12K



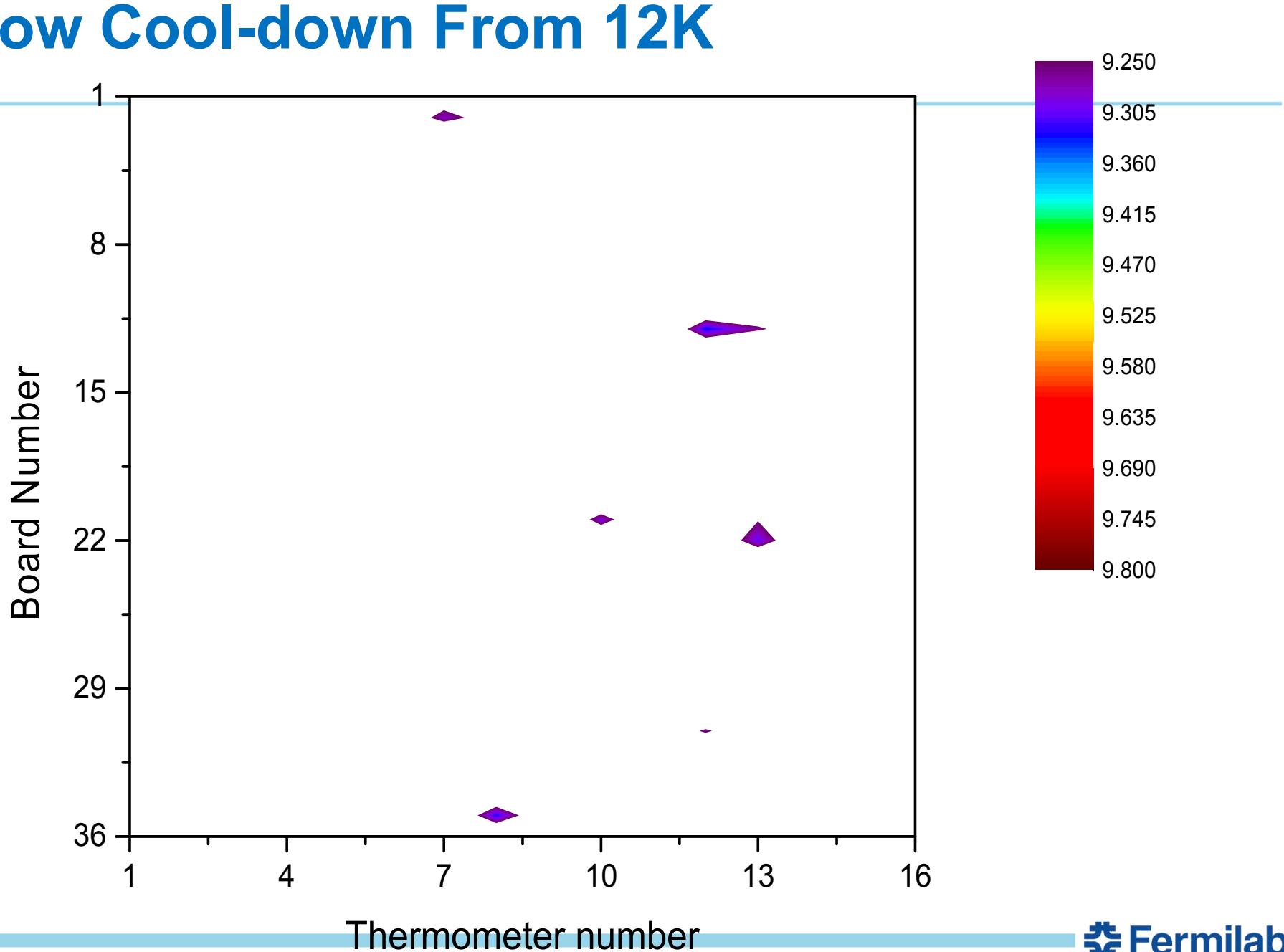
# Slow Cool-down From 12K



# Slow Cool-down From 12K



# Slow Cool-down From 12K



# Slow Cool-down From 12K

Board Number

1

8

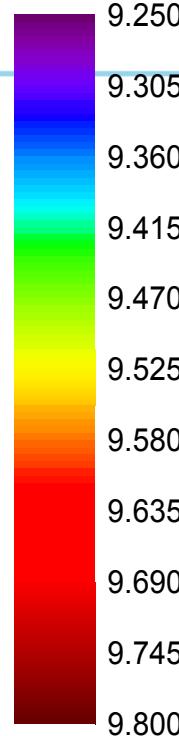
15

22

29

36

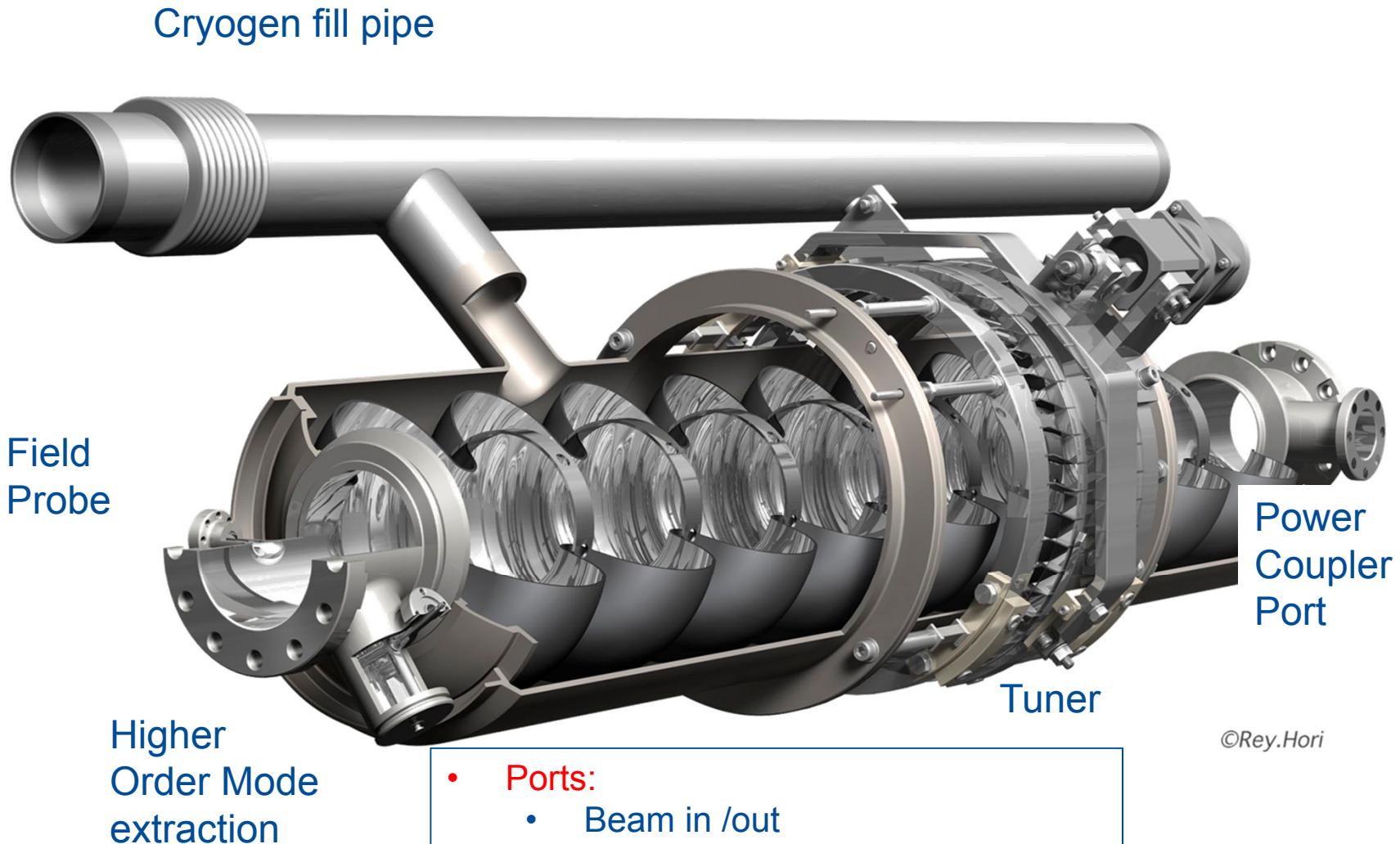
Thermometer number



---

*Bringing these very High Q  
all the way down into the tunnel*

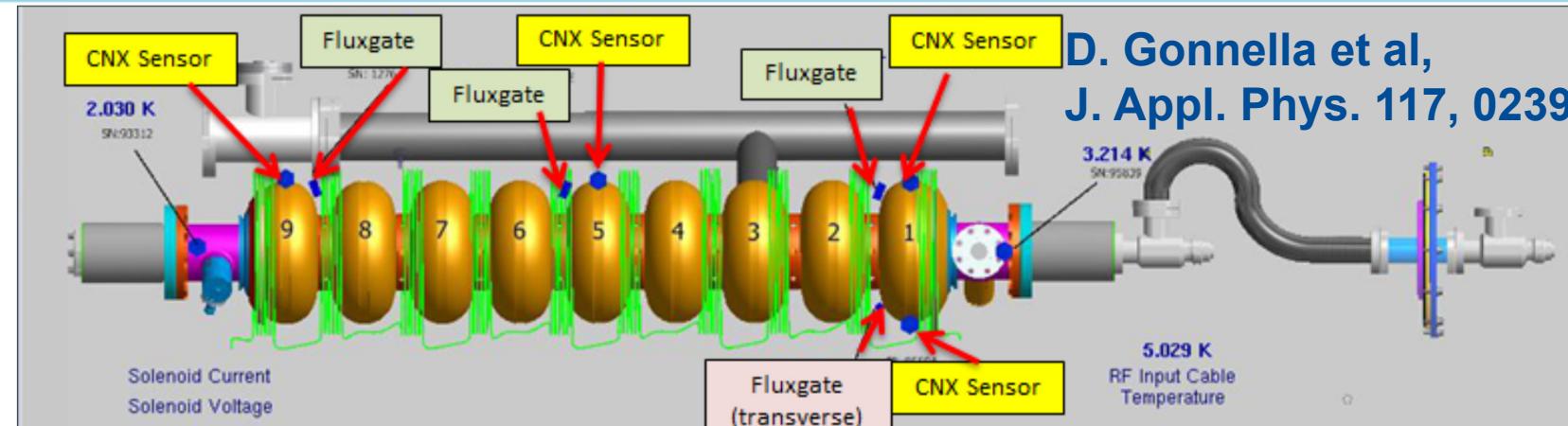
# SRF cavity in its liquid helium filled tank: operating at 2 degrees above absolute zero (-456 deg F)



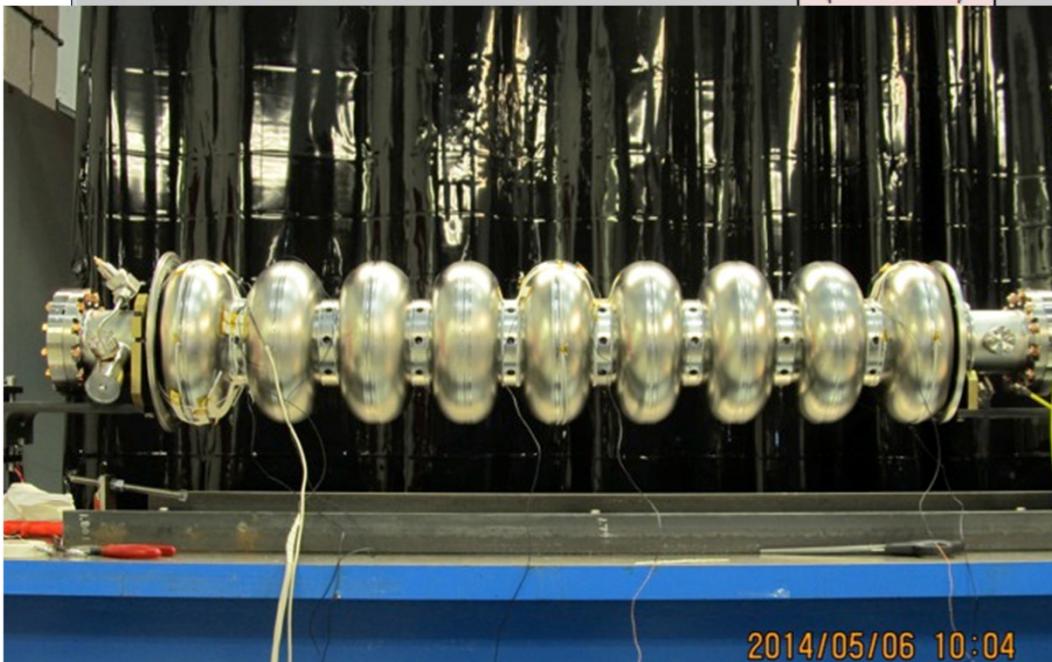
©Rey.Hori

- **Ports:**
  - Beam in /out
  - Bring in power
  - Monitor field
  - Extract un-wanted frequencies

# LCLS-2 cavities dressed with instrumentation inside vessel



D. Gonnella et al,  
J. Appl. Phys. 117, 023908 (2015)



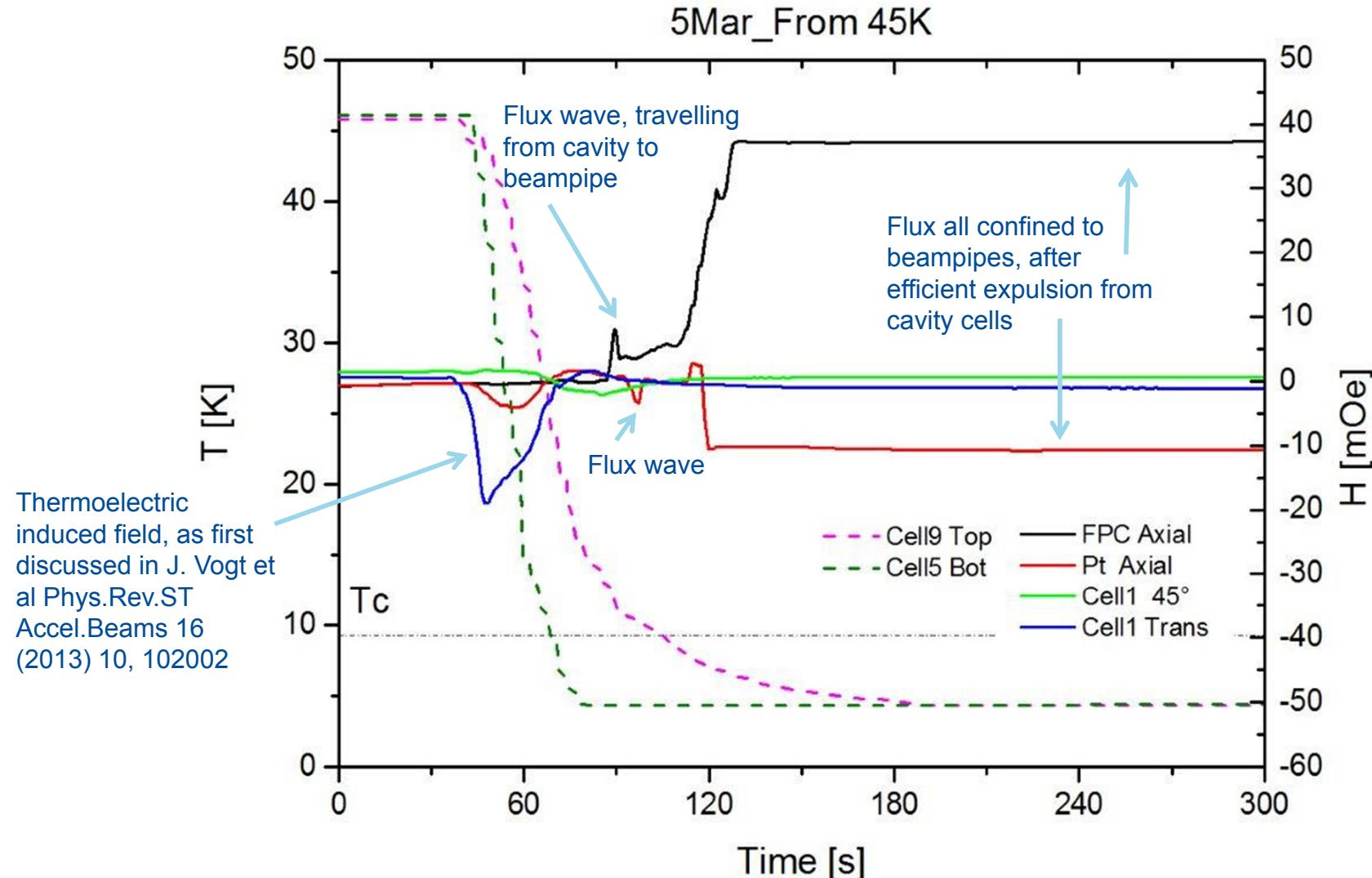
```
9AES021 params      SET   D/A   A/D   Con-U   PTool
#SA# X-A/D  X=TIME   Y=Z:HTTX20,Z:HTTX21,Z:HTTX22,Z:HTTX23
---- Eng-U  I= 0      I= 0   , 0   , 0   , 0
One+ 1_Hz   F= 120    F= 80   , 80   , 80   , 80
hlrf     llrf   cryo  vacuum  DIAG   timing   water

Fluxgates
beampipe - FPC - axial          -5.2828002 mG
SFG1   Fluxgate 1288             -35.256699 mG
beampipe - prb - axial          -2.4957   mG
SFG2   Fluxgate 1289             -59.361901 mG
Cell 1 top - axial/vertical (45 deg)
SFG3   Fluxgate #3               57.36   K
Cell 1 bot - transverse
SFG4   Fluxgate #4               11.25   K

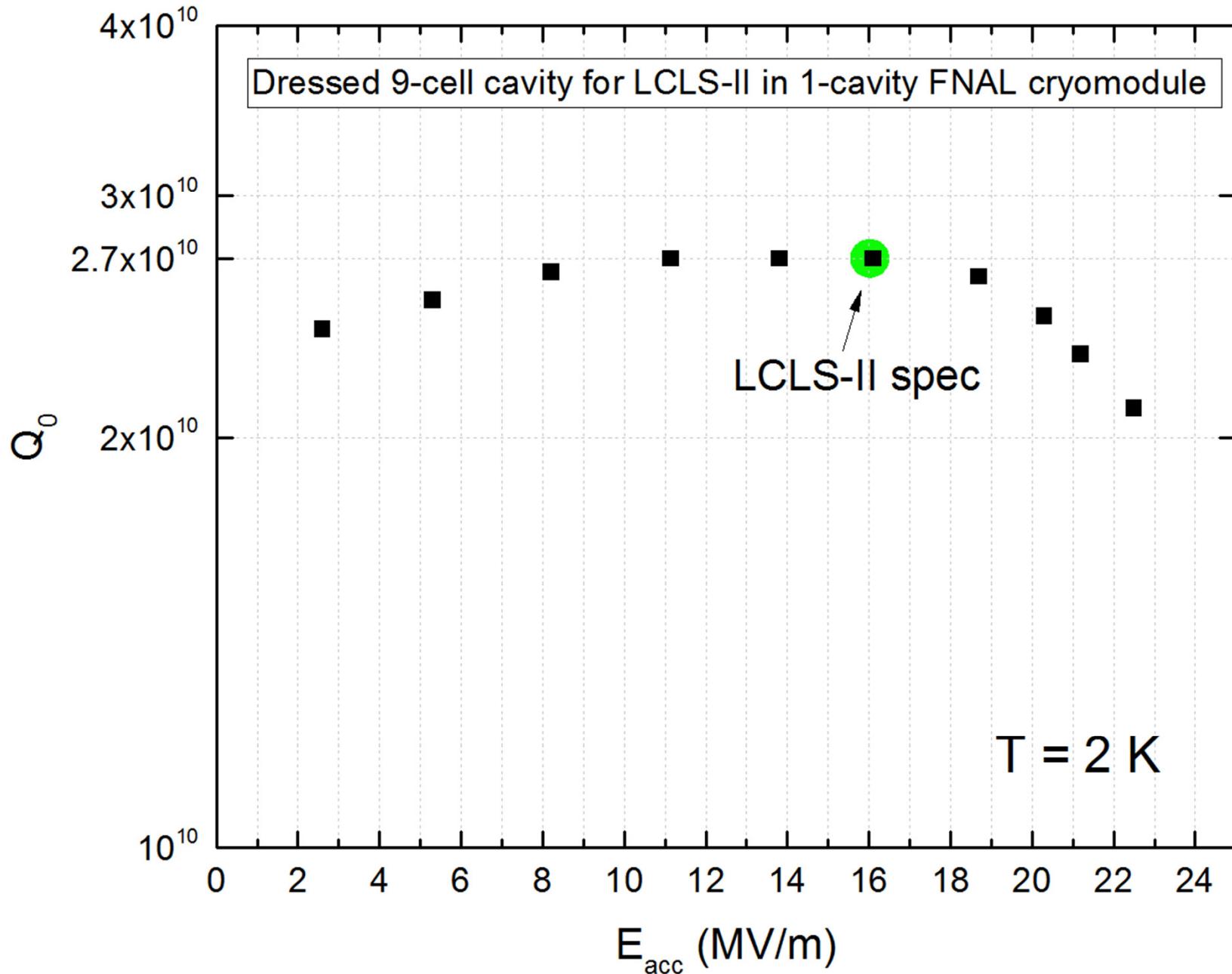
internal cavity RTDs
HTTX21   HTS HEV cell 1 top   51.9   K
HTTX20   HTS HEV cell 1 bot   9.6    K
Cell 3 (top only)
HTTXM2   HOM1 Flange Temp   50.03   K
Cell 5   HTS HEV cell 5 top   62.08   K
HTTX22   HTS HEV cell 5 top   12.85   K
HTTXM1   HOM1 Button Temp   62.08   K
Cell 9   HTS HEV cell 9 top   12.85   K
HTTX23   HTS HEV cell 9 top   9.6    K
HTTXM3   HOM2 Button Temp   51.9   K

Beampipe temps
HTTXM2   HTS coupler flange   57.36   K
```

# Sweeping the flux into the beampipes via fast cooling

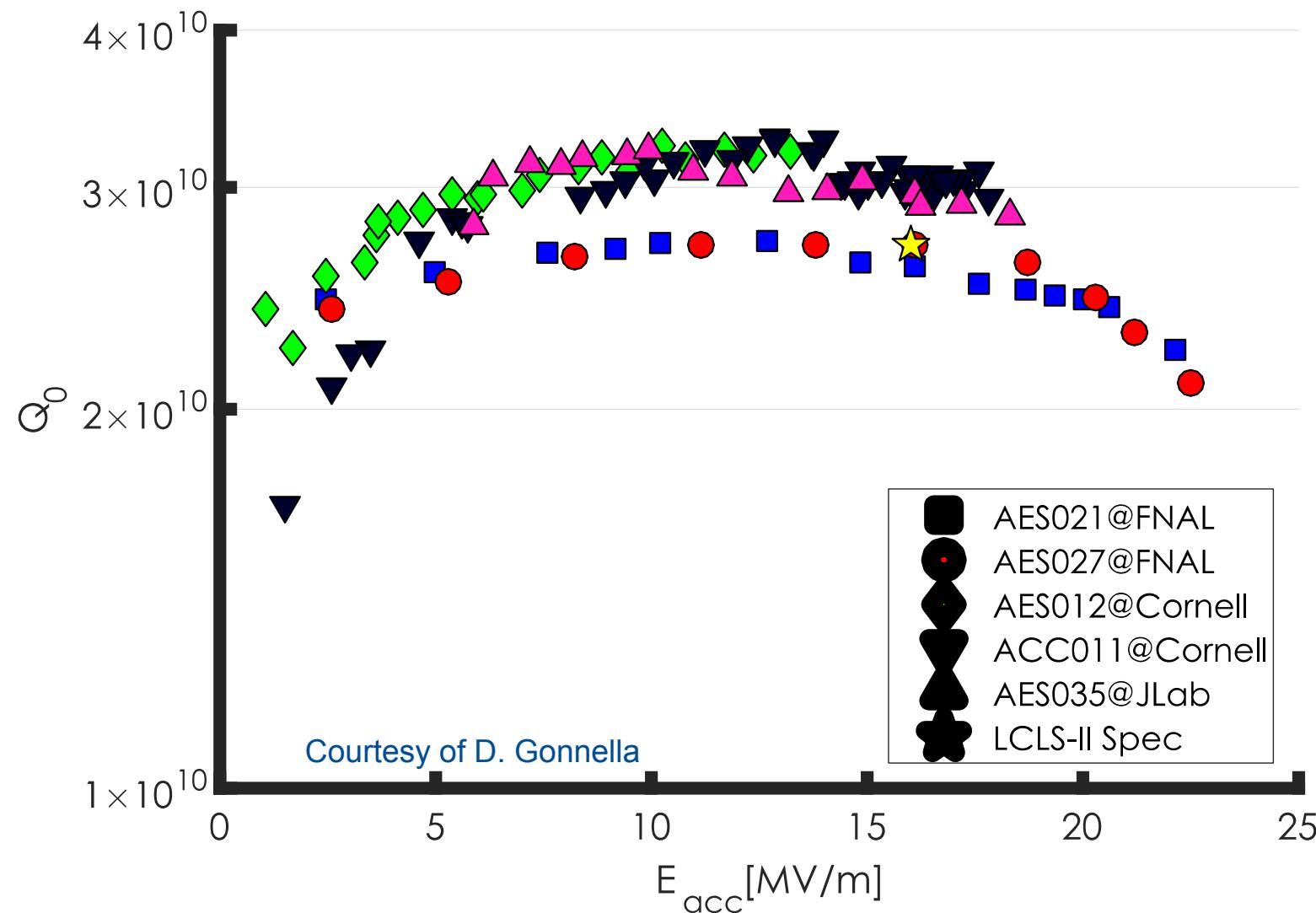


# TB9AES027



# Horizontal dressed cavity tests at FNAL, Cornell, Jlab

## Meeting final LCLS-2 specs in cryomodule environment!



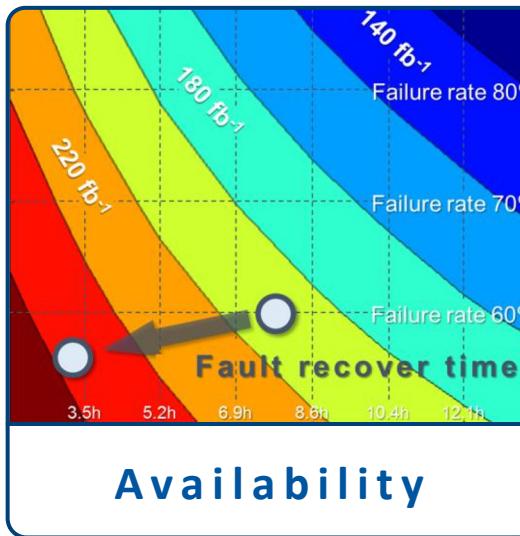
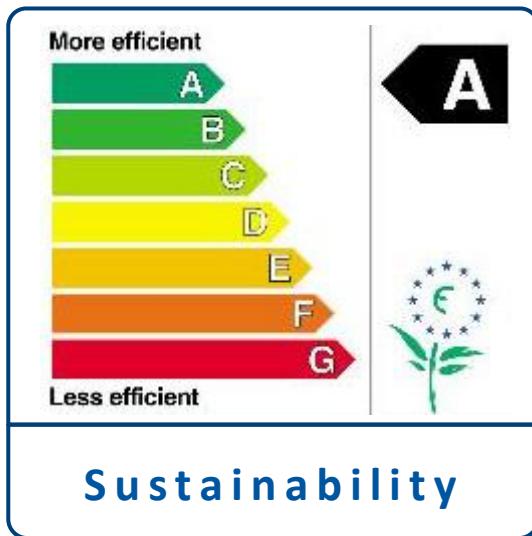
# Conclusions

---

- Tremendous progress in the past two years in understanding of contributors to RF surface resistance
- Record Q achieved from bare cavity tests all the way down to cryomodule environment, by implementing N doping and understanding of flux expulsion via efficient cooling through  $T_c$
- High Q at high gradient via doping is the frontier to be explored, the next battle already ongoing
- LCLS-2 nominal exceeded in vertical and horizontal test at three different institutions
- LCLS-2 has helped nurturing and developing a new high Q technology

# Scale Up versus Scale Out

- Scale-out of available technologies without advancement leads to unsustainable and inadequate performance
- Mandatory to use large projects to develop new technologies



Cost effective operation:  
Personnel and material  
resources  
Energy efficiency

Number of subsystems  
requires breakthrough  
in reliability, availability

Diversify technology  
sources to control risk  
Economic return to  
society is mandatory

---

# Thank you